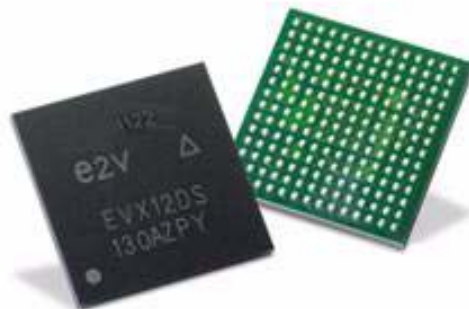


# Low Power 12-bit 3 Gsps Digital to Analog Converter with 4/2:1 Multiplexer

## Datasheet

### Main Features

- 12-bit Resolution
- 3 Gsps Guaranteed Conversion Rate
- 7 GHz Analog Output Bandwidth
- 4:1 or 2:1 integrated Parallel MUX (Selectable)
- Selectable Output Modes for performance optimization:  
Return to Zero, Non Return to Zero, Narrow Return to Zero, RF
- Low Latency Time: 3.5 Clock Cycles
- 1.4 Watt Power Dissipation in MUX 4:1 Mode
- Functions
  - Selectable MUX Ratio 4:1 (Full Speed), 2:1 (Half Speed)
  - Triple Majority Voting
  - User-friendly Functions:
    - Gain Adjustment
    - Input Data Check Bit (FPGA Timing Check)
    - Setup Time and Hold Time Violation Flags (STVF, HTVF)
    - Clock Phase Shift Select for Synchronization with DSP (PSS[2:0])
    - Output Clock Division Selection (Possibility to Change the Division Ratio of the DSP Clock)
    - Input Under Clocking Mode
    - Diode for Die junction Temperature Monitoring
- LVDS Differential Data input and DSP Clock Output
- Analog Output Swing: 1V<sub>pp</sub> Differential (100Ω Differential Impedance)
- External Reset for Synchronization of Multiple MuxDACs
- Power Supplies: 3.3 V (Digital), 3.3V & 5.0V (Analog)
- FpBGA Package (15 × 15 mm Body Size, 1 mm Pitch)



### Performances

Broadband: NPR at -14 dB Loading Factor, (See [Section 7.2.7 "NPR Performance" on page 57](#))

- |                              |               |                                      |
|------------------------------|---------------|--------------------------------------|
| • 1st Nyquist (NRTZ):        | NPR = 51.3 dB | 10.0 Bit Equivalent at Fs = 3 Gsps   |
| • 1st Nyquist (NRTZ):        | NPR = 55.7 dB | 10.8 Bit Equivalent at Fs = 1.5 Gsps |
| • 2nd Nyquist (NRTZ or RTZ): | NPR = 44.6 dB | 8.9 Bit Equivalent at Fs = 3 Gsps    |
| • 3rd Nyquist (RF):          | NPR = 42.5 dB | 8.6 Bit Equivalent at Fs = 3 Gsps    |

Single Tone: (see [Section 5. "Functional Description" on page 16](#))

- Performances Characterized for Fout from 100 MHz to 4500 MHz and from 2 Gsps to 3.2 Gsps
- Performance Industrially Screened Over 3 Nyquist Zones at 3 Gsps for Selected Fout.

Step Response

- Full Scale Rise /Fall Time 50 ps

Visit our website: [www.e2v.com](http://www.e2v.com)  
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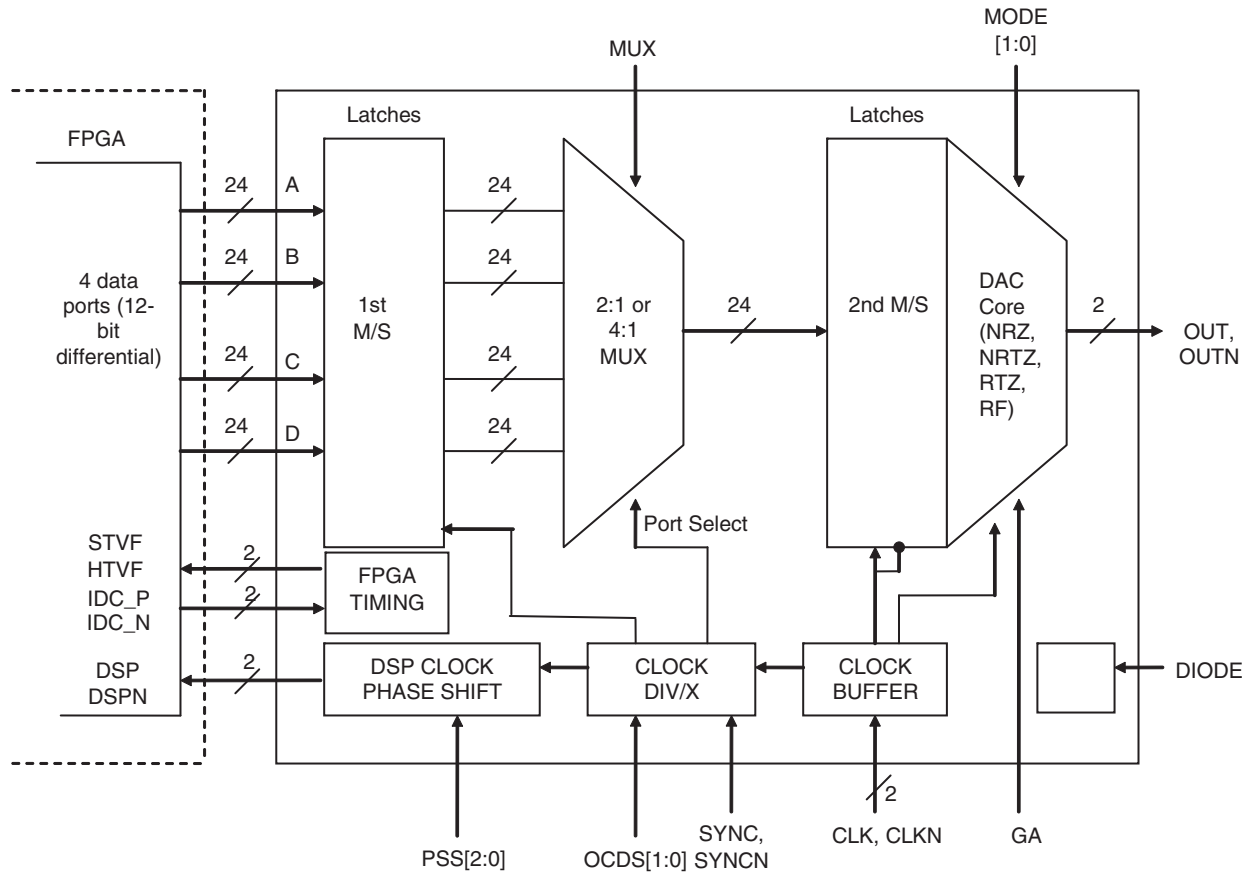
# EV12DS130BZP

## Applications

- Direct Digital Synthesis for Broadband Applications (L-S and Lower C Band)
- Automatic Test Equipment (ATE)
- Arbitrary Waveform Generators
- Radar Waveform Signal Synthesis
- DOCSIS V3.0 Systems

## 1. Block Diagram

Figure 1-1. Simplified Block Diagram



## 2. Description

The EV12DS130A/B is a 12-bit 3 Gsps DAC with an integrated 4:1 or 2:1 multiplexer, allowing easy interface with standard LVDS FPGAs thanks to user friendly features as OCDS, PSS.

It embeds different output modes (RTZ, NRZ, narrow RTZ, RF) that allow performance optimizations depending on the working Nyquist zone.

The Noise Power Ratio (NPR) performance, over more than 900 MHz instantaneous bandwidth, and the high linearity (SFDR, IMD) over full 1<sup>st</sup> Nyquist zone at 3 Gsps (NRZ feature), make this product well suited for high-end applications such as arbitrary waveform generators and broadband DDS systems.

## 3. Electrical Characteristics

### 3.1 Absolute Maximum Ratings

**Table 3-1. Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Positive Analog supply voltage	$V_{CCA5}$	6.0	V
Positive Analog supply voltage	$V_{CCA3}$	4.0	V
Positive Digital supply voltage	$V_{CCD}$	4.0	V
Digital inputs (on each single-ended input) and IDC, SYNC, signal Port P = A, B, C, D $V_{IL}$ $V_{IH}$ Digital Input maximum Differential mode swing	[P0..P11], [P0N.. P11N] IDC_P, IDC_N SYNC, SYNCN	GND–0.3 $V_{CCA3}$ 2.0	V V $V_{pp}$
Master clock input (on each single-ended input) $V_{IL}$ $V_{IH}$ Master Clock Maximum Differential mode swing	CLK, CLKN	1.5 3.5 2.5	V V $V_{pp}$
Control functions inputs $V_{IL}$ $V_{IH}$	MUX, MODE[0..1], PSS[0..2], OCDS[0..1]	–0.4V $V_{CCD} + 0.4$	V V
Gain Adjustment function	GA	–0.3V, $V_{CCA3} + 0.3$	V
Maximum Junction Temperature	$T_j$	170	°C
Storage Temperature	$T_{stg}$	–65 to 150	°C
Electrostatic discharge immunity ESD Classification	ESD HBM	1000 Class 1B	V

- Notes:
1. Absolute maximum ratings are limiting values (referenced to GND = 0V), to be applied individually, while other parameters are within specified operating conditions. Long exposure to maximum rating may affect device reliability.
  2. All integrated circuits have to be handled with appropriate care to avoid damages due to ESD. Damage caused by inappropriate handling or storage could range from performance degradation to complete failure.
  3. Maximum ratings enable active inputs with DAC powered off.
  4. Maximum ratings enable floating inputs with DAC powered on.
  5. DSP clock and STVF, HTVF output buffers must not be shorted to ground nor positive power supply.

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## 3.2 Recommended Conditions of Use

**Table 3-2. Recommended Conditions of Use**

Parameter	Symbol	Comments	Recommended Value	Unit	Note
Positive analog supply voltage	$V_{CCA5}$		5.0	V	(2)(4)
Positive analog supply voltage	$V_{CCA3}$		3.3	V	(1)(2)(4)
Positive digital supply voltage	$V_{CCD}$		3.3	V	(2)(4)
Digital inputs (on each single-ended input) and IDC, SYNC, signal Port P = A, B, C, D $V_{IL}$ $V_{IH}$ Differential mode swing	[P0..P11], [P0N.. P11N] IDC_P, IDC_N SYNC, SYNCN		1.075 1.425 700	V V mV <sub>pp</sub>	(3)
Master clock input power level (Differential mode)	$P_{CLK}$		3	dBm	(3)
Control functions inputs	MUX, OCDS, PSS, MODE, PSS	$V_{IL}$ $V_{IH}$	0 $V_{CCD}$	V V	
Gain Adjustment function	GA	Range	0 $V_{CCA3}$	V	
Operating Temperature Range	$T_c$ $T_j$	Commercial "C" grade Industrial "V" grade	$T_c > 0^\circ\text{C} / T_j < 90^\circ\text{C}$ $T_c > -40^\circ\text{C} / T_j < 110^\circ\text{C}$	$^\circ\text{C}$	

- Notes:
1. For low temperature it is recommended to operate at maximum analog supplies ( $V_{CCA3}$ ) level.
  2. The rise time of any power supplies ( $V_{CCD}$ ,  $V_{CCA5}$ ,  $V_{CCA3}$ ) shall be <10ms.  
For EV12DS130A, in order to obtain the guaranteed performances and functionality, the following rules shall be followed when powering the devices (See [Section 8.9 "Power Up Sequencing" on page 70](#))  
For EV12DS130B, no specific power up sequence nor power supplies relationships are required.
  3. Analog output is in differential. Single-ended operation is not recommended. Guaranteed performance is only in differential configuration.
  4. No power-down sequencing is required.

### 3.3 Electrical Characteristics

Values in the tables below are based on our conditions of measurement in room temperature for typical power supply ( $V_{CCA5} = 5.0V$ ,  $V_{CCA3} = 3.3V$ ,  $V_{CCD} = 3.3V$ ), typical swing and in MUX4:1 otherwise specified.

**Table 3-3.** Electrical Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test Level <sup>(2)</sup>
RESOLUTION			12		bit		
<b>POWER REQUIREMENTS</b>							
Power Supply voltage							
- Analog	$V_{CCA5}$	4.75	5	5.25	V	(7)(8)	1
- Analog	$V_{CCA3}$	3.15	3.3	3.45	V		
- Digital	$V_{CCD}$	3.15	3.3	3.45	V		
Power Supply current (4:1 MUX)							
- Analog	$I_{CCA5}$		84	90	mA		1
- Analog	$I_{CCA3}$		106	122	mA		
- Digital	$I_{CCD}$		187	205	mA		
Power Supply current (2:1 MUX)							
- Analog	$I_{CCA5}$		84	90	mA		1
- Analog	$I_{CCA3}$		106	122	mA		
- Digital	$I_{CCD}$		160	177	mA		
Power dissipation (4:1 MUX)	$P_D$		1.4	1.6	W		1
Power dissipation (2:1 DMUX)	$P_D$		1.3	1.5	W		1
<b>DIGITAL DATA INPUTS, SYNC and IDC INPUTS</b>							
Logic compatibility		LVDS					
Digital input voltages:							
- Differential input voltage	$V_{ID}$	100	350	500	mV <sub>p</sub>		1
- Common mode	$V_{ICM}$		1.25		V		1
Input capacitance from each single input to ground				2	pF		5
Differential Input resistance		80	100	120	$\Omega$		1
<b>CLOCK INPUTS</b>							
Input voltages (Differential operation swing)		0.56	1	2.24	V <sub>pp</sub>		4
Power level (Differential operation)		-4	1	8	dBm	(1)	4
Common mode		2.4	2.5	2.6	V		
Input capacitance from each single input to ground (at die level)				2	pF		5
Differential Input resistance:		80	100	120	$\Omega$		1
<b>DSP CLOCK OUTPUT</b>							
Logic compatibility		LVDS					
Digital output voltages:							
- Differential output voltage	$V_{OD}$	240	350	450	mV <sub>p</sub>		1
- Common mode	$V_{OCM}$		1.3		V		

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**Table 3-3.** Electrical Characteristics (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test Level <sup>(2)</sup>
<b>ANALOG OUTPUT</b>							
Full-scale Differential output voltage (100Ω differentially terminated)		0.92	1	1.08	V <sub>pp</sub>		1
Full-scale output power (differential output)		0.25	1	1.64	dBm		1
Single-ended mid-scale output voltage (50Ω terminated)			V <sub>CCA5</sub> – 0.43		V	(4)	
Output capacitance			1.5		pF		5
Output internal differential resistance		90	100	110	Ω		1
Output VSWR (using e2v evaluation board)							
1.5 GHz			1.17				4
3 GHz			1.54				
4.5 GHz			1.64				
Output bandwidth			7		GHz		4
<b>FUNCTIONS</b>							
Digital functions: MODE, OCDS, PSS, MUX							
- Logic 0	V <sub>IL</sub>		0	0.8	V		1
- Logic 1	V <sub>IH</sub>	1.6	V <sub>CCD</sub>		V		
	I <sub>IN</sub>			150	μA	(6)	
Gain Adjustment function	GA		0				1
			V <sub>CCA3</sub>				
Digital output function (HTVF, STVF)							
Logic 0	V <sub>OL</sub>	–	–	0.8	V	(5)	1
Logic 1	V <sub>OH</sub>	2.3	–		V		
	I <sub>O</sub>			80	μA	(6)	
<b>DC ACCURACY</b>							
Differential Non-Linearity	DNL+		0.5	0.95	LSB		1
Differential Non-Linearity	DNL-	–0.95	–0.5		LSB		1
Integral Non-Linearity	INL+		1	3	LSB		1
Integral Non-Linearity	INL-	–3	–0.8		LSB		1
DC gain:							
- Initial gain error		–8	0	+8	%		1
- DC gain adjustment			±11		%	(3)	1
- DC gain sensitivity to power supplies				+6	%		1
- DC gain drift over temperature			±2		%		4

- Notes:
1. For use in higher Nyquist zone, it is recommended to use higher power clock within the limit.
  2. See [Section 3.6 on page 13](#) for explanation of test levels.
  3. Initial gain error corresponds to the deviation of the DC gain center value from unity gain. The DC gain adjustment (GA function) ensures that the initial gain deviation can be cancelled.  
The DC gain sensitivity to power supplies is given according the rule:  
GainSensVsSupply = IGain@VccMin – Gain@VccMax / Gain@Vccnom
  4. Single-ended operation is not recommended, this line is given for better understanding of what is output by the DAC.
  5. In order to modify the V<sub>OL</sub>/V<sub>OH</sub> value, potential divider could be used.
  6. Sink or source.

7. Only for EV12DS130A dependency between power supplies:  
Within the applicable power supplies range, the following relationship shall always be satisfied  $V_{CCA3} \geq V_{CCD}$ , taking into account AGND and DGND planes are merged and power supplies accuracy.
8. Please refer [Section 8.9 "Power Up Sequencing" on page 70](#).

### 3.4 AC Electrical Characteristics

Values in the tables below are based on our conditions of measurement in room temperature for typical power supply ( $V_{CCA5} = 5.0V$ ,  $V_{CCA3} = 3.3V$ ,  $V_{CCD} = 3.3V$ ), typical swing and in MUX4:1 otherwise specified.

**Table 3-4.** AC Electrical Characteristics NRZ Mode (First Nyquist Zone)

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test level <sup>(1)</sup>
Single-tone Spurious Free Dynamic Range First Nyquist MUX 4:1	ISFDRI	59					
Fs = 3 Gsps @ Fout = 100 MHz 0 dBFS			68		dBc		1
Fs = 3 Gsps @ Fout = 400 MHz 0 dBFS			63				4
Fs = 3 Gsps @ Fout = 100 MHz -3 dBFS			70				4
Highest spur level First Nyquist MUX 4:1							
Fs = 3 Gsps @ Fout = 100 MHz 0 dBFS			-68	-58	dBm		1
Fs = 3 Gsps @ Fout = 400 MHz 0 dBFS			-59				4
Fs = 3 Gsps @ Fout = 100 MHz -3 dBFS			-72				4
SFDR sensitivity & high spur level variation over temperature			±2		dB		4
SFDR sensitivity & high spur level variation over power supplies			±2		dB		4
Signal independent Spur (clock-related spur)							
Fc/2			-82		dBm		4
Fc/4			-85		dBm		4
Noise Power Ratio -14 dBFS peak to rms loading factor Fs = 3 Gsps 20 MHz to 900 MHz broadband pattern 25 MHz notch centered on 450 MHz	NPR		46		dB	(2)	4
Equivalent ENOB Computed from NPR figure at 3 GSps	ENOB		9.2		Bit		4
Signal to Noise Ratio Computed from NPR figure at 3 GSps	SNR		57		dB		4
DAC self noise density at constant code 0 or 4095			-163		dBm/Hz		4

- Notes:
1. See [Section 3.6 on page 13](#) for explanation of test levels.
  2. Figures in tables are derived from industrial screening; for practical reasons (necessity to cover also 2nd and 3rd Nyquist Zones) the balun used for industrial test is not optimum for first Nyquist performances, and results when Fout or folded low order hamonics are between DC to 400 MHz are very pessimistic. For further details please refer to [Section 7.2 on page 38](#) for effect of the balun on performances.

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**Table 3-5.** AC Electrical Characteristics NRTZ Mode (First & Second Nyquist Zone)

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test level <sup>(1)</sup>
Single-tone Spurious Free Dynamic Range MUX4:1 Fs = 3 Gsps @ Fout = 100 MHz 0 dBFS Fs = 3 Gsps @ Fout = 700 MHz 0 dBFS Fs = 3 Gsps @ Fout = 1800 MHz 0 dBFS	ISFDR1	54	68		dBc		4
			62				4
			61				1
Fs = 3 Gsps @ Fout = 700 MHz –3 dBFS			66				4
MUX2:1 Fs = 1.5 Gsps @ Fout = 700 MHz 0 dBFS		53	65				1
Highest spur level MUX4:1 Fs = 3 Gsps @ Fout = 100 MHz 0 dBFS Fs = 3 Gsps @ Fout = 700 MHz 0 dBFS Fs = 3 Gsps @ Fout = 1800 MHz 0 dBFS			–70 –64 –67	–59	dBm		4 4 1
Fs = 3 Gsps @ Fout = 700 MHz –3 dBFS			–70				4
MUX2:1 Fs = 1.5 Gsps @ Fout = 700 MHz 0 dBFS			–68	–55			1
SFDR sensitivity & high spur level variation over temperature			±2		dB		4
SFDR sensitivity & high spur level variation over power supplies			±2		dB		4
Signal independent Spur (clock-related spur) Fc Fc/2 Fc/4			–29 –80 < –80		dBm dBm dBm		4 4 4
DAC self noise density at constant code 0 or 4095			–149	–144	dBm/Hz		1
Noise Power Ratio –14 dBFS peak to rms loading factor Fs = 3 Gsps 20 MHz to 900 MHz broadband pattern, 25 MHz notch centered on 450 MHz	NPR	46	50.2		dB	(2)	1
Equivalent ENOB Computed from NPR figure at 3 GSps	ENOB	9.2	9.9		Bit	(2)	1
Signal to Noise Ratio Computed from NPR figure at 3 GSps	SNR	57	61.2		dB	(2)	1
Noise Power Ratio –14 dBFS peak to rms loading factor Fs = 1.5 Gsps 10 MHz to 450 MHz broadband pattern, 12.5 MHz notch centered on 225 MHz	NPR		55.7		dB	(2)	4
Equivalent ENOB Computed from NPR figure at 1.5 GSps	ENOB		10.8		Bit	(2)	4
Signal to Noise Ratio Computed from NPR figure at 1.5 GSps	SNR		66.7		dB	(2)	4



- Notes: 1. See [Section 3.6 on page 13](#) for explanation of test levels.  
2. Figures in tables are derived from industrial screening; for practical reasons (necessity to cover also 2nd and 3rd Nyquist Zones) the balun used for industrial test is not optimum for first Nyquist performances, and results when Fout or folded low order hamonics are between DC to 400 MHz are very pessimistic. For further details please refer to [Section 7.2 on page 38](#) for effect of the balun on performances.

**Table 3-6.** AC Electrical Characteristics RTZ Mode (Second Nyquist Zone)

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test level <sup>(1)</sup>
Single-tone Spurious Free Dynamic Range MUX4:1 Fs = 3 Gsps @ Fout = 1600 MHz 0 dBFS Fs = 3 Gsps @ Fout = 2900 MHz 0 dBFS	ISFDR	50	60 57		dBc		1 4
Highest spur level MUX4:1 Fs = 3 Gsps @ Fout = 1600 MHz 0 dBFS Fs = 3 Gsps @ Fout = 2900 MHz 0 dBFS			-67 -66	-58	dBm		1 4
SFDR sensitivity & high spur level variation over temperature			±2		dB		4
SFDR sensitivity & high spur level variation over power supplies			±2		dB		4
Signal independent Spur (clock-related spur) Fc Fc/2 Fc/4			-25 -80 < -80		dBm dBm dBm		4 4 4
DAC self noise density at constant code 0 or 4095			-143		dBm/Hz		4
Noise Power Ratio -14 dBFS peak to rms loading factor Fs = 3 Gsps 1520 MHz to 2200 MHz broadband pattern, 25 MHz notch centered on 1850 MHz	NPR	40	44.0		dB	(2)	1
Equivalent ENOB Computed from NPR figure at 3 GSps	ENOB	8.2	8.8		Bit	(2)	1
Signal to Noise Ratio Computed from NPR figure at 3 GSps	SNR	51	55.0		dB	(2)	1

- Notes: 1. See [Section 3.6 on page 13](#) for explanation of test levels.  
2. Please refer to [Section 7.2 "AC Performances" on page 38](#) to have detailed characterization results.

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**Table 3-7.** AC Electrical Characteristics RF Mode (Second and Third Nyquist Zones)

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test level <sup>(1)</sup>
Single-tone Spurious Free Dynamic Range 2 <sup>nd</sup> Nyquist Fs = 3 Gsps @ Fout = 1600 MHz 0 dBFS Fs = 3 Gsps @ Fout = 2900 MHz 0 dBFS	ISFDR1		52 60		dBc		4 4
3 <sup>rd</sup> Nyquist Fs = 3 Gsps @ Fout = 3800 MHz 0 dBFS Fs = 3 Gsps @ Fout = 4400 MHz 0 dBFS		47	53 54			(2)	4 1
Highest spur level 2 <sup>nd</sup> Nyquist Fs = 3 Gsps @ Fout = 1600 MHz 0 dBFS Fs = 3 Gsps @ Fout = 2900 MHz 0 dBFS			–58 –58		dBm		4 4
3 <sup>rd</sup> Nyquist Fs = 3 Gsps @ Fout = 4400 MHz 0 dBFS			–62	–57			1
SFDR sensitivity & high spur level variation over temperature			±2		dB		4
SFDR sensitivity & high spur level variation over power supplies			±2		dB		4
Signal independent Spur (clock-related spur) Fc Fc/2 Fc/4			–28 –80 < –80		dBm dBm dBm		4 4 4
DAC self noise density at constant code 0 or 4095			–141		dBm/Hz		4
Noise Power Ratio (2 <sup>nd</sup> Nyquist) –14 dBFS peak to rms loading factor Fs = 3 Gsps 1520 MHz to 2200 MHz broadband pattern, 25 MHz notch centered on 1850 MHz	NPR		42		dB	(2)	4
Equivalent ENOB Computed from NPR figure at 3 GSps	ENOB		8.5		Bit	(2)	4
Signal to Noise Ratio Computed from NPR figure at 3 GSps	SNR		53		dB	(2)	4
Noise Power Ratio –14 dBFS peak to rms loading factor Fs = 3 Gsps 2200 MHz to 2880 MHz broadband pattern, 25 MHz notch centered on 2550 MHz	NPR		42		dB	(2)	4
Equivalent ENOB Computed from NPR figure at 3 GSps	ENOB		8.5		Bit	(2)	4
Signal to Noise Ratio Computed from NPR figure at 3 GSps	SNR		53		dB	(2)	4

**Table 3-7.** AC Electrical Characteristics RF Mode (Second and Third Nyquist Zones) (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test level <sup>(1)</sup>
Noise Power Ratio –14 dBFS peak to rms loading factor Fs = 3 Gsps 3050 MHz to 3700 MHz broadband pattern, 25 MHz notch centered on 3375 MHz	NPR	39	40		dB	(2)	1
Equivalent ENOB Computed from NPR figure at 3 GSps	ENOB	8	8.2		Bit	(2)	1
Signal to Noise Ratio Computed from NPR figure at 3 GSps	SNR	50	51		dB	(2)	1

- Notes: 1. See [Section 3.6 on page 13](#) for explanation of test levels.  
2. Figures in tables are derived from industrial screening without any correction to take in account the balun effect, but for practical reasons (necessity to cover also 2nd and 3rd Nyquist Zones) the balun used for industrial test is not optimum for first Nyquist performances, and results when Fout or folded low order hamonics are between DC to 400 MHz are very pessimistic.

### 3.5 Timing Characteristics and Switching Performances

**Table 3-8.** Timing Characteristics and Switching Performances

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test level <sup>(1)</sup>
<b>SWITCHING PERFORMANCE AND CHARACTERISTICS</b>							
Operating clock frequency 4:1 MUX mode 2:1 MUX mode		300 300		3000 1500	MHz		4
<b>TIMING CHARACTERISTICS</b>							
Analog output rise/fall time	T <sub>OR</sub> T <sub>OF</sub>			60	ps	(2)	4
Data Tsetup (Fc = 3 Gsps)		250			ps	(3)	4
Data Thold (Fc = 3 Gsps)		100			ps	(3)	4
Max Input data rate (Mux 4:1)		75		750	MSps		4
Max Input data rate (Mux 2:1)		150		750	MSps		4
Master clock input jitter				100	fs rms	(4)	5
DSP clock phase tuning steps			0.5		Clock period		5
Master clock to DSP, DSPN delay	TDSP		1.6		ns		4
SYNC forbidden area lower bound (Fc = 3 Gsps)	T <sub>1</sub>		200		ps	(5)(6)	4
SYNC forbidden area upper bound (Fc = 3 Gsps)	T <sub>2</sub>		180		ps	(5)(6)	4

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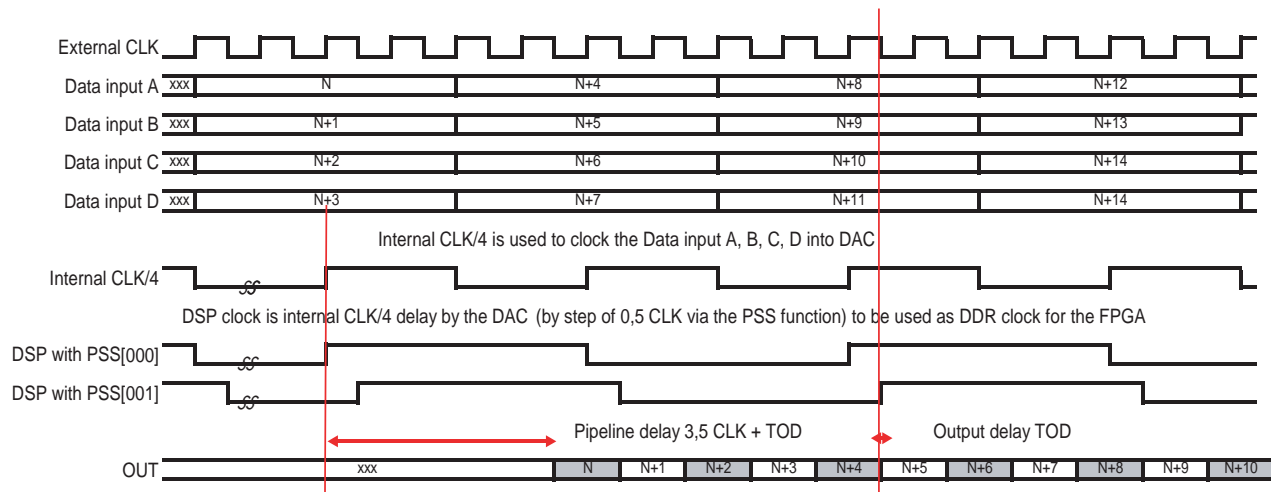
## EV12DS130BZP

**Table 3-8.** Timing Characteristics and Switching Performances (Continued)

Parameter	Symbol	Min	Typ	Max	Unit	Note	Test level <sup>(1)</sup>
SYNC to DSP, DSPN MUX 2:1 MUX4:1			880 1600		ps		4
Data Pipeline Delay MUX4:1 MUX2:1	TPD		3.5 3.5		Clock period		4
Data Output Delay	TOD		160		ps		4

- Notes:
1. See [Section 3.6 on page 13](#) for explanation of the test level.
  2. Analog output rise/fall time measured from 20% to 80% of a full scale jump, after probe de-embedding.
  3. Exclusive of period (pp) jitter on Data. Setup and hold time for DATA at input relative to DSP clock at output of the component, at PSS = 000; also applicable for IDC signal.
  4. Master clock input jitter defined over 5 GHz bandwidth.
  5.  $T_C$  represents the master clock period. See [Figure 3-3](#).
  6. For EV12DS130A, please refer to erratasheet 1125

**Figure 3-1.** Timing Diagram for 4:1 MUX Principle of Operation OCDS[00]



**Figure 3-2.** Timing Diagram for 2:1 MUX Principle of Operation OCDS[00]

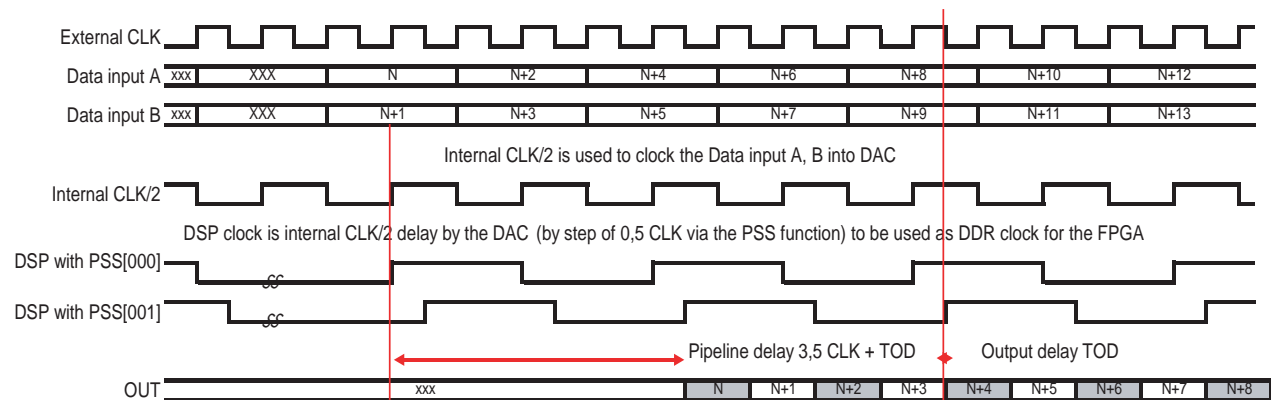
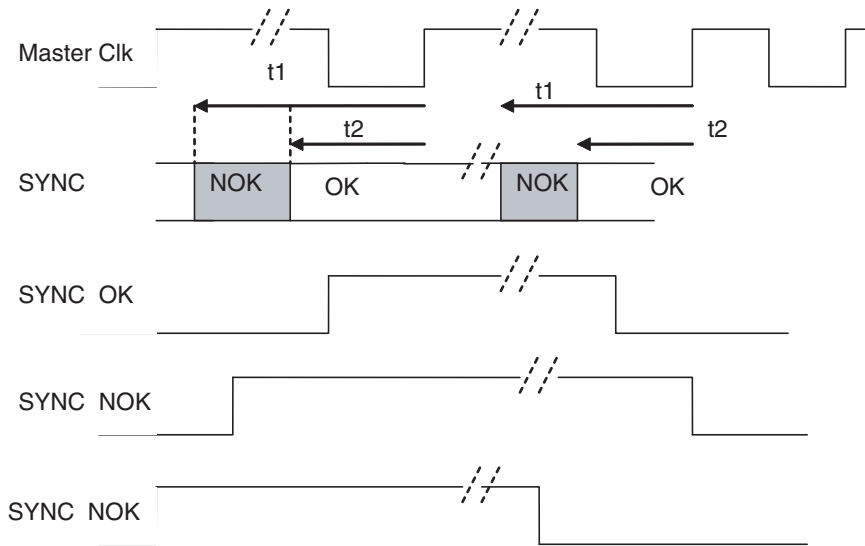


Figure 3-3. SYNC Timing Diagram



Please refer to [Section 5.8 "Synchronization functions for multi-DAC operation"](#) on page 26.

3.6 Explanation of Test Levels

1	100% production tested at +25°C <sup>(1)</sup>
2	100% production tested at +25°C <sup>(1)</sup> , and sample tested at specified temperatures.
3	Sample tested only at specified temperatures
4	Parameter is guaranteed by design and/or characterization testing (thermal steady-state conditions at specified temperature)
5	Parameter value is guaranteed by design
6	100% production tested over specified temperature range (for Space/Mil grade <sup>(2)</sup> )

Only MIN and MAX values are guaranteed.

- Notes:
- 1. Unless otherwise specified.
  - 2. If applicable, please refer to "Ordering Information"

EV12DS130AZP  
EV12DS130BZP

3.7 Digital Input Coding Table

Table 3-9. Coding Table (Theoretical values)

Digital output msb.....lsb	Differential analog output
000000000000	−500 mV
010000000000	−250 mV
011000000000	−125 mV
011111111111	−0.122 mV
100000000000	0.122 mV
101000000000	+125 mV
110000000000	+250 mV
111111111111	+500 mV

## 4. Definition of Terms

Abbreviation	Term	Definition
(Fs max)	<i>Maximum conversion Frequency</i>	Maximum conversion frequency
(Fs min)	<i>Minimum conversion frequency</i>	Minimum conversion Frequency
(SFDR)	<i>Spurious free dynamic range</i>	Ratio expressed in dB of the RMS signal amplitude, set at Full Scale, to the RMS value of the highest spectral component (peak spurious spectral component). The peak spurious component may or may not be a harmonic. It may be reported in dB (i.e., related to converter 0 dB Full Scale), or in dBc (i.e, related to input signal level).
(HSL)	<i>High Spur Level</i>	Power of highest spurious spectral component expressed in dBm.
(ENOB)	<i>Effective Number Of Bits</i>	ENOB is determined from NPR measurement with the formula: $\text{ENOB} = (\text{NPR}_{[\text{dB}]} + \text{ILF}_{[\text{dB}]} - 3 - 1.76) / 6.02$ Where LF "Loading factor" is the ratio between the Gaussian noise standard deviation versus amplitude full scale.
(SNR)	<i>Signal to noise ratio</i>	SNR is determined from NPR measurement with the formula: $\text{SNR}_{[\text{dB}]} = \text{NPR}_{[\text{dB}]} + \text{ILF}_{[\text{dB}]} - 3$ Where LF "Loading factor" is the ratio between the Gaussian noise standard deviation versus amplitude full scale.
(DNL)	<i>Differential non linearity</i>	The Differential Non Linearity for an given code i is the difference between the measured step size of code i and the ideal LSB step size. DNL (i) is expressed in LSBs. DNL is the maximum value of all DNL (i). DNL error specification of less than 1 LSB guarantees that there are no missing point and that the transfer function is monotonic.
(INL)	<i>Integral non linearity</i>	The Integral Non Linearity for a given code i is the difference between the measured voltage at which the transition occurs and the ideal value of this transition. INL (i) is expressed in LSBs, and is the maximum value of all  INL (i)
(TPD/TOD)	<i>Output delay</i>	The analog output propagation delay measured between the rising edge of the differential CLK, CLK <sub>N</sub> clock input (zero crossing point) and the zero crossing point of a full-scale analog output voltage step. TPD corresponds to the pipeline delay plus an internal propagation delay (TOD) including package access propagation delay and internal (on-chip) delays such as clock input buffers and DAC conversion time.
(NPR)	<i>Noise Power Ratio</i>	The NPR is measured to characterize the DAC performance in response to broad bandwidth signals. When applying a notch-filtered broadband white-noise pattern at the input to the DAC under test, the Noise Power Ratio is defined as the ratio of the average noise measured on the shoulder of the notch and inside the notch on the same integration bandwidth.
(VSWR)	<i>Voltage Standing Wave Ratio</i>	The VSWR corresponds to the insertion loss linked to power reflection. For example a VSWR of 1:2 corresponds to a 20dB return loss (ie. 99% power transmitted and 1% reflected).
(IUCM)	<i>Input under clocking mode</i>	The IUCM principle is to apply a selectable division ratio between DAC section clock and the MUX section clock.
(PSS)	<i>Phase Shift Select</i>	The Phase Shift Select function allow to tune the phase of the DSPclock.
(OCDS)	<i>Output Clock Division Selectt</i>	It allows to divide the DSPclock frequency by the OCDS coded value factor
(NRZ)	<i>Non Return to Zero mode</i>	Non Return to Zero mode on analog output
(RF)	<i>Radio Frequency mode</i>	RF mode on analog output
(RTZ)	<i>Return to zero</i>	Return to zero mode on analog output
(NRTZ)	<i>Narrow return to zero</i>	Narrow return to zero mode on analog output

5. Functional Description

Figure 5-1. DAC Functional Diagram

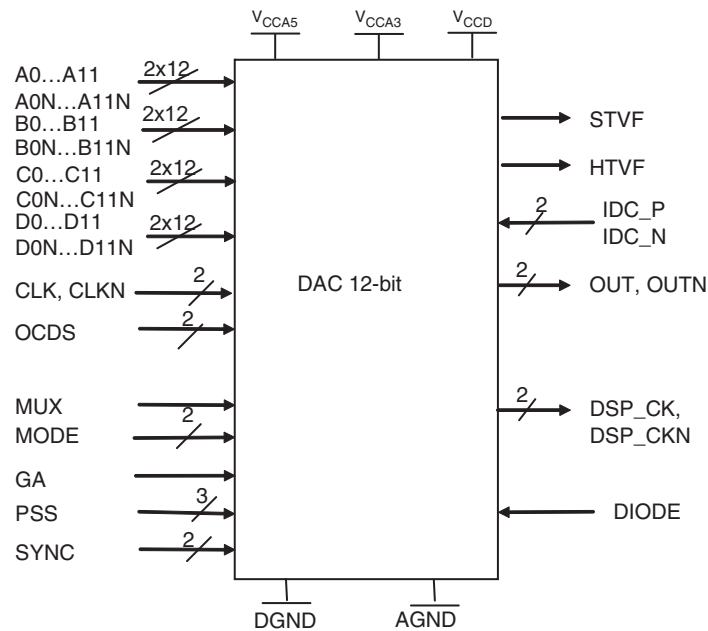


Table 5-1. Functions Description

Name	Function	Name	Function
V <sub>CCD</sub>	3.3V Digital Power Supply	CLK	In-phase Master clock
V <sub>CCA5</sub>	5.0V Analog Power Supply	CLKN	Inverted phase Master clock
V <sub>CCA3</sub>	3.3V Analog Power Supply	DSP_CK	In-phase Output clock
DGND	Digital Ground	DSP_CKN	Inverted phase Output clock
AGND	Analog ground (for analog supply reference)	PSS[0..2]	Phase shift select
A[11...0]	In-phase digital input Port A	GA	Gain Adjust
A[11..0]N	Inverted phase digital input Port A	MUX	Multiplexer Selection
B[11...0]	In-phase digital input Port B	MODE[0..1]	DAC Mode: NRZ, RTZ, NRTZ, RF
B[11..0]N	Inverted phase digital input Port B	STVF	Setup time Violation flag
C[11...0]	In-phase digital input Port C	HTVF	Hold time Violation flag
C[11..0]N	Inverted phase digital input Port C	IDC_P, IDC_N	Input data check
D[11...0]	In-phase digital input Port D	OCDS[0..1]	Output Clock Division factor Selection (by 4 or 8)
D[11..0]N	Inverted phase digital input Port D	Diode	Diode for temperature monitoring
OUT	In-phase analog output	SYNC/SYNCN	Synchronization signal (Active High)
OUTN	Inverted phase analog output		



## 5.1 DSP Output Clock

The DSP output clock DSP, DSPN is an LVDS signal which is used to synchronize the FPGA generating the digital patterns with the DAC sampling clock.

The DSP clock frequency is a fraction of the sampling clock frequency. The division factor depends on OCDS settings. The DSP clock frequency is equal to (sampling frequency / [2N\*X]) where N is the MUX ratio and X is the output clock division factor, determined by OCDS[0..1] bits.

For example, in a 4:1 MUX ratio application with a sampling clock of 3 GHz and OCDS set to "00" (ie. Factor of 1), the input data rate is 750 MSps and the DSP clock frequency is 375 MHz.

This DSP clock is used in the FPGA to control the digital data sequencing. Its phase can be adjusted using the PSS[2:0] bits (refer to [Section 5.4 on page 22](#)) in order to ensure a proper synchronization between the data coming to the DAC and the sampling clock.

The HTVF and STVF bits should be used to check whether the timing between the FPGA and the DAC is correct. HTVF and STVF bits will indicate whether the DAC and FPGA are aligned or not. PSS bits should then be used to shift the DSP clock and thus the input data of the DAC, so that a correct timing is achieved between the FPGA and the DAC.

**Important note: Maximum supported sampling frequency when using DSP to clock digital data is 2.1 Gsps on EV12DS130B. Please refer to application note AN1141 to use EV12DS130B at sampling frequency beyond 2.1 GHz.**

## 5.2 Multiplexer

Two multiplexer ratio are allowed:

- 4:1 which allows operation at full sampling rate (ie. 3 GHz)
- 2:1 which can only be used up to 1.5 GHz sampling rate

Label	Value	Description
MUX	0	4:1 mode
	1	2:1 mode

In 2:1 MUX ratio, the unused data ports (ports C and D) can be left open.

## 5.3 MODE Function

Label	Value	Description	Default Setting (Not Connected)
MODE[1:0]	00	NRZ mode	11 RF mode
	01	Narrow RTZ (a.k.a. NRTZ) mode	
	10	RTZ Mode (50%)	
	11	RF mode	

The MODE function allows choosing between NRZ, NRTZ, RTZ and RF functions. NRZ and narrow RTZ should be chosen for use in 1<sup>st</sup> Nyquist zone while RTZ should be chosen for use in 2<sup>nd</sup> and RF for 3<sup>rd</sup> Nyquist zones.

Theory of operation: see following subsections for time domain waveform of the different modes.

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Ideal equations describing max available Pout for frequency domain in the four modes are given hereafter, with X = normalized output frequency (that is Fout/Fclock, edges of Nyquist zones are then at X = 0 1/2 1 3/2 2 ...). Due to limited bandwidth, an extra term must be added to take in account a first order low pass filter.

## NRZ mode:

$$P_{out}(X) = 20 \cdot \log_{10} \cdot \left[ \frac{|k \cdot \text{sinc}(k \cdot \pi \cdot X)|}{0.893} \right]$$

where sinc(x) = sin(x)/x, and k = 1

## NRTZ mode:

$$P_{out}(X) = 20 \cdot \log_{10} \cdot \left[ \frac{|k \cdot \text{sinc}(k \cdot \pi \cdot X)|}{0.893} \right] \quad k = \frac{T_{clk} - T_{\tau}}{T_{clk}}$$

where T<sub>τ</sub> is width of reshaping pulse, T<sub>τ</sub> is about 75ps.

## RTZ mode:

$$P_{out}(X) = 20 \cdot \log_{10} \cdot \left[ \frac{|k \cdot \text{sinc}(k \cdot \pi \cdot X)|}{0.893} \right]$$

where k is the duty cycle of the clock presented at the DAC input, please note that due to phase mismatch in balun used to convert single ended clock to differential clock the first zero may move around the limit of the 4<sup>th</sup> and the 5<sup>th</sup> Nyquist zones. Ideally k = 1/2.

## RF mode:

$$P_{out}(X) = 20 \cdot \log_{10} \cdot \left[ \frac{\left| k \cdot \text{sinc}\left(\frac{k \cdot \pi \cdot X}{2}\right) \cdot \sin\left(\frac{k \cdot \pi \cdot X}{2}\right) \right|}{0.893} \right]$$

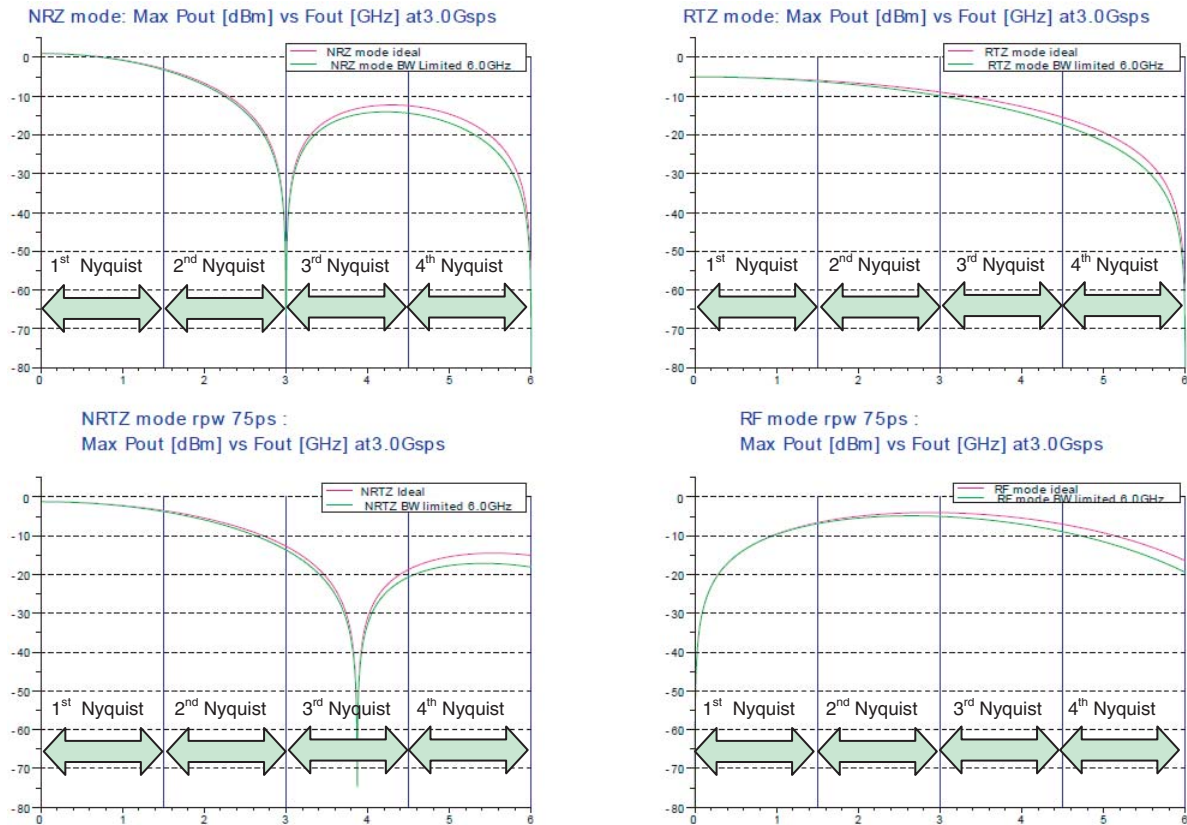
where k is as per in NRTZ mode.

As a consequence:

- NRZ mode offers max power for 1<sup>st</sup> Nyquist operation
- RTZ mode offers slow roll off for 2<sup>nd</sup> Nyquist or 3<sup>rd</sup> Nyquist operation
- RF mode offers maximum power over 2<sup>nd</sup> and 3<sup>rd</sup> Nyquist operation
- NRTZ mode offers optimum power over full 1<sup>st</sup> and first half of 2<sup>nd</sup> Nyquist zones. This is the most relevant in term of performance for operation over 1<sup>st</sup> and beginning of 2<sup>nd</sup> Nyquist zone. Depending on the sampling rate the zero of transmission moves in the 3<sup>rd</sup> Nyquist zone from begin to end when sampling rate increases.

Note in the two following figures: Pink line is ideal equation's result, and green line includes a first order 6 GHz cut-off low pass filter to take into account finite bandwidth effect due to die and package.

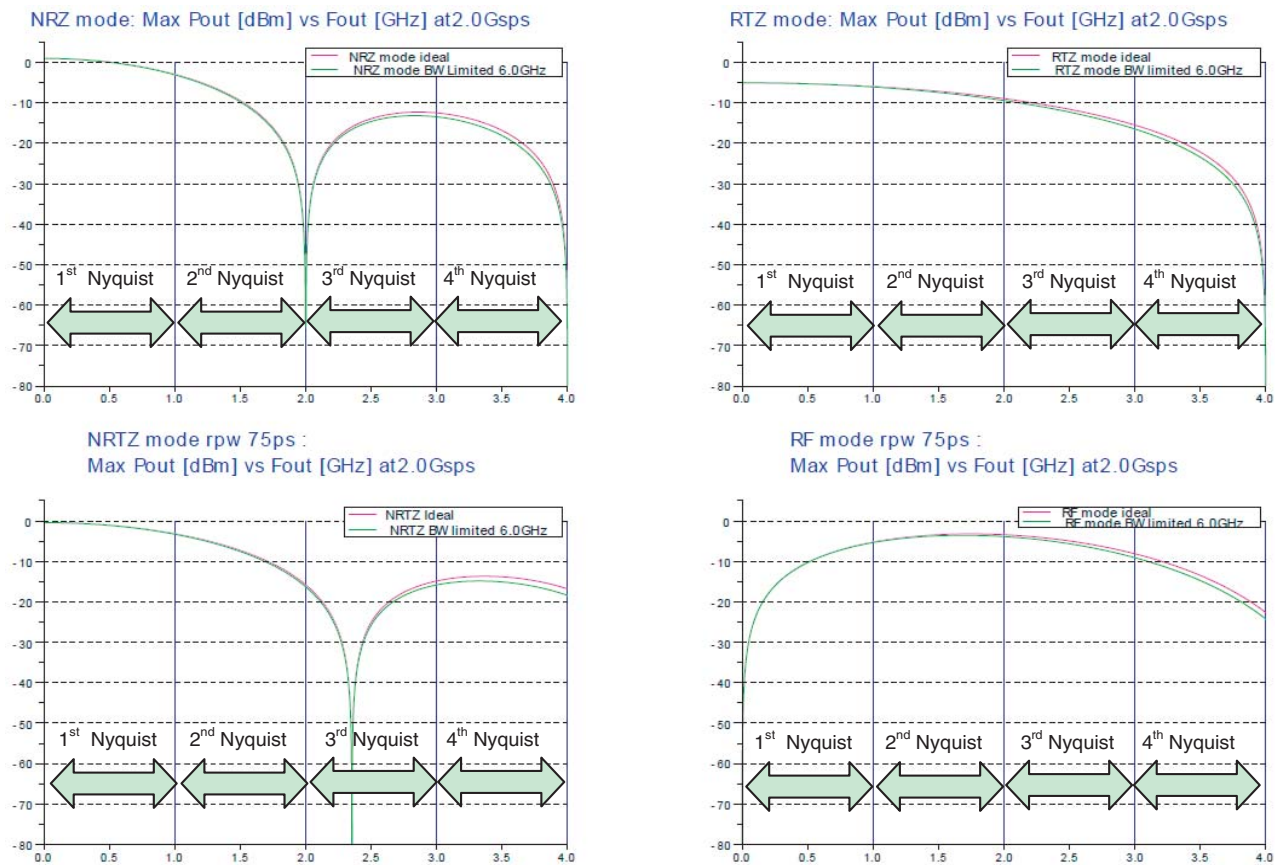
**Figure 5-2.** Max Available Pout[dBm] at Nominal Gain vs Fout[GHz] in the Four Output Modes at 3 Gsps, over four Nyquist Zones, Computed for  $T\tau = 75$  ps.



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**Figure 5-3.** Max available Pout[dBm] at Nominal Gain vs Fout[GHz] in the Four Output Modes at 2 Gsps, over four Nyquist Zones, Computed for  $T_{\tau} = 75$  ps

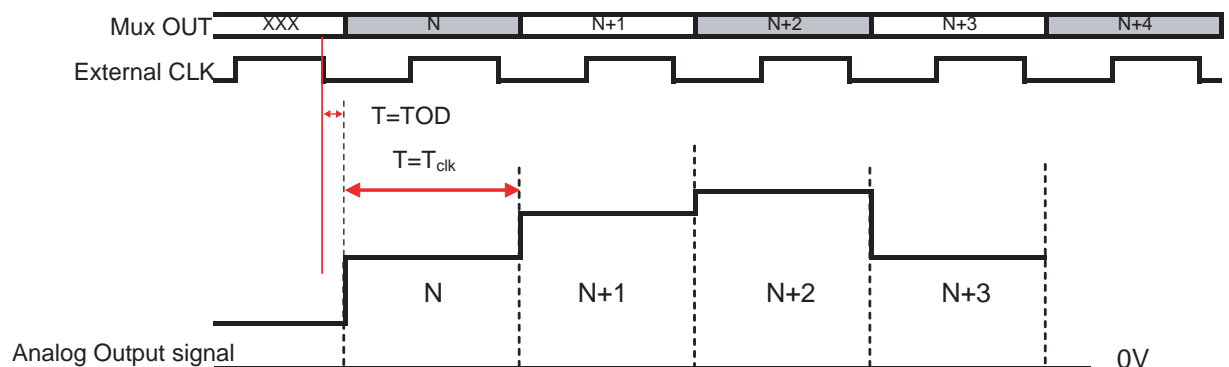


## 5.3.1 NRZ Output Mode

This mode does not allow for operation in the 2<sup>nd</sup> Nyquist zone because of the  $\text{Sinx}/x$  notch.

The advantage is that it gives good results at the beginning of the 1<sup>st</sup> Nyquist zone (less attenuation than in RTZ architecture), it removes the parasitic spur at the clock frequency (in differential).

**Figure 5-4.** NRZ Timing Diagram

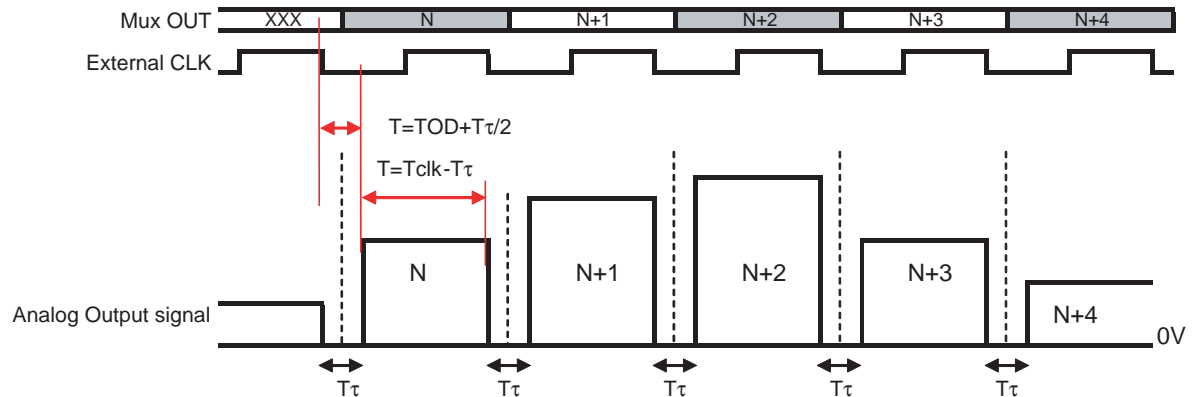


### 5.3.2 Narrow RTZ Mode (NRTZ Mode)

This mode has the following advantages:

- Optimized power in 1<sup>st</sup> Nyquist zone
- Extended dynamic through elimination of noise on transition edges
- Improved spectral purity (see [Section 7.2.3 on page 45](#))
- Trade off between NRZ and RTZ

**Figure 5-5.** Narrow RTZ Timing Diagram



Note:  $T_\tau$  is independent of  $F_{clock}$ .

### 5.3.3 RTZ Mode

The advantage of the RTZ mode is to enable the operation in the 2<sup>nd</sup> zone but the drawback is clearly to attenuate more the signal in the first Nyquist zone.

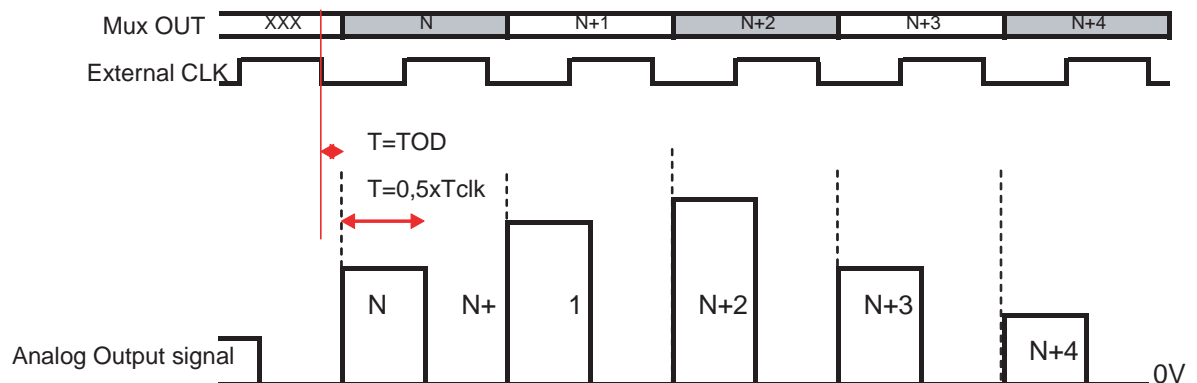
Advantages:

- Extended roll off of sinc
- Extended dynamic through elimination of hazardous transitions

Weakness:

- By construction clock spur at  $F_s$ .

**Figure 5-6.** RTZ Timing Diagram



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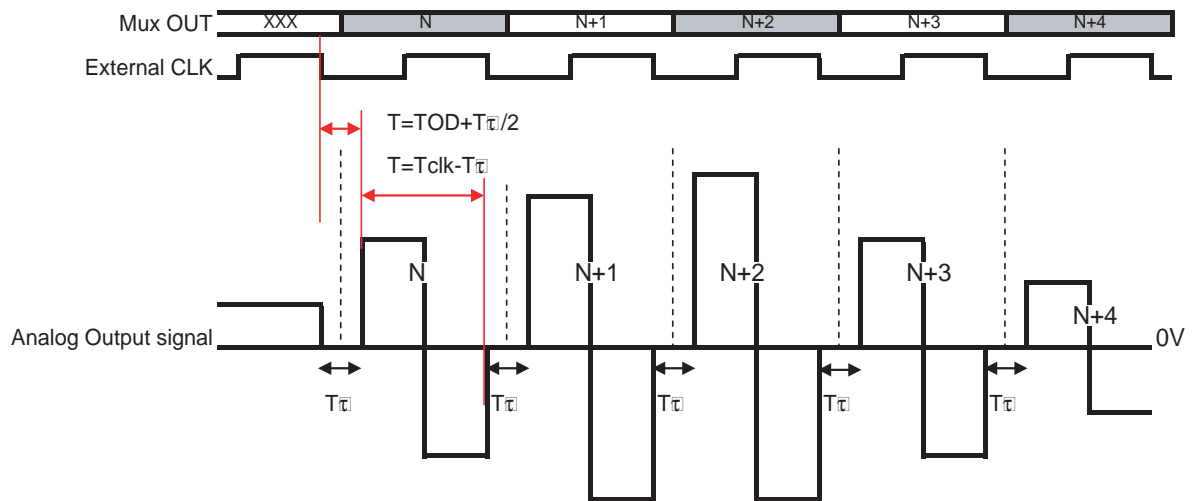
## 5.3.4 RF Mode

RF mode is optimal for operation at high output frequency, since the decay with frequency occurs at higher frequency than for RTZ. Unlike NRZ or RTZ modes, RF mode presents a notch at DC and  $2N \cdot F_s$ , and minimum attenuation for  $F_{out} = F_s$ .

Advantages:

- Optimized for 2<sup>nd</sup> and 3<sup>rd</sup> Nyquist operation
- Extended dynamic range through elimination of hazardous transitions.
- Clock spur pushed to  $2 \cdot F_s$

**Figure 5-7.** RF Timing Diagram



Note: The central transition is not hazardous but its elimination allows to push clock spur to  $2 \cdot F_s$   
 $T_{\tau}$  is independent of  $F_{clock}$ .

## 5.4 PSS (Phase Shift Select Function)

It is possible to adjust the timings between the sampling clock and the DSP output clock (which frequency is given by the following formula: Sampling clock /  $2NX$  where N is the MUX ratio, X the output clock division factor).

The DSP clock output phase can be tuned over a range of 3.5 input clock cycles (7 steps of half a clock cycle) in addition to the intrinsic propagation delay between the DSP clock (DSP, DSPN) and the sampling clock (CLK, CLKN).

Three bits are provided for the phase shift function: PSS[2:0].

By setting these 3 bits to 0 or 1, one can add a delay on the DSP clock in order to properly synchronize the input data of the DAC and the sampling clock (the DSP clock should be applied to the FPGA and should be used to clock the DAC digital input data).

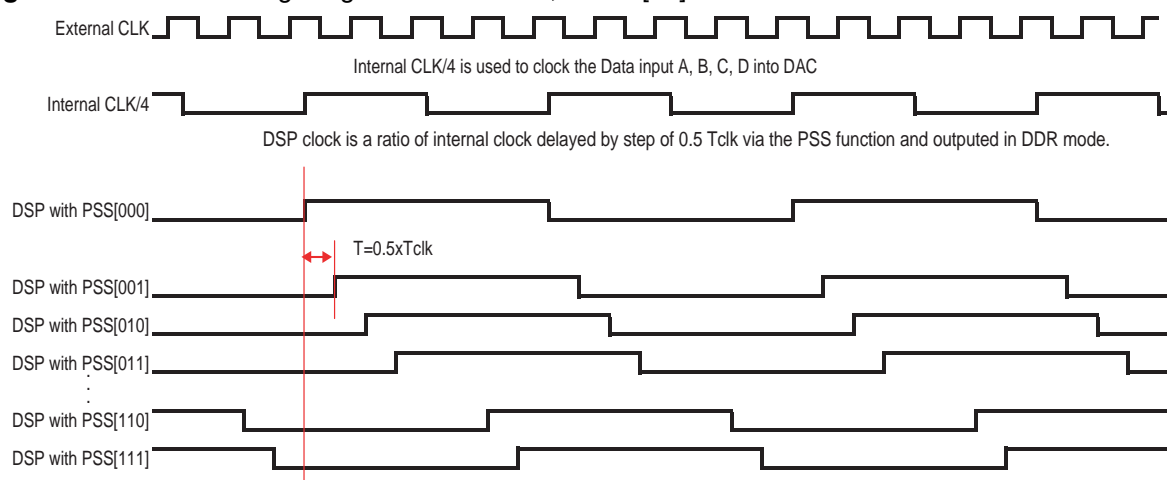
**Table 5-2.** PSS Coding Table

Label	Value	Description
PSS[2:0]	000	No additional delay on DSP clock
	001	0.5 input clock cycle delay on DSP clock
	010	1 input clock cycle delay on DSP clock
	011	1.5 input clock cycle delay on DSP clock
	100	2 input clock cycle delay on DSP clock
	101	2.5 input clock cycle delay on DSP clock
	110	3 input clock cycle delay on DSP clock
	111	3.5 input clock cycle delay on DSP clock

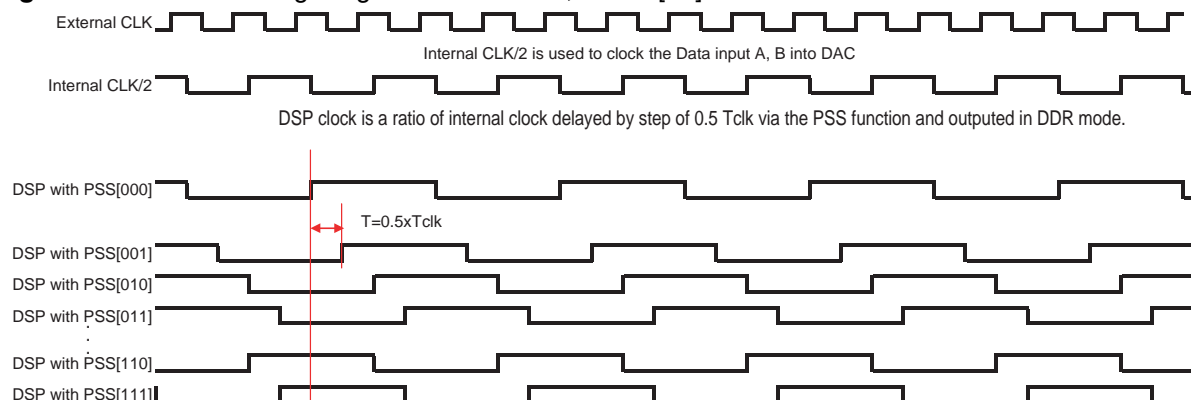
In order to determine how much delay needs to be added on the DSP clock to ensure the synchronization between the input data and the sampling clock within the DAC, the HTVF and STVF bits should be monitored. Refer to [Section 5.6 on page 25](#).

**Note:** In MUX 4:1 mode the 8 settings are relevant, in MUX 2:1 only the four first settings are relevant since the four last ones will yield exactly the same results.

**Figure 5-8.** PSS Timing Diagram for 4:1 MUX, OCDS[00]



**Figure 5-9.** PSS Timing Diagram for 2:1 MUX, OCDS[00]



5.5 Output Clock Division Select Function

It is possible to change the DSP clock internal division factor from 1 to 2 with respect to the sampling clock/2N where N is the MUX ratio. This is possible via the OCDS "Output Clock Division Select" bits.

OCDS is used to obtain a synchronization clock for the FPGA slow enough to allow the FPGA to operate with no further internal division of this clock, thus its internal phase is determined by the DSP clock phase. This is useful in a system with multiple DACs and multiple FPGAs to guarantee deterministic phase relationship between the FPGAs after a synchronization of all the DACs.

Table 5-3. OCDS[1:0] Coding Table

Label	Value	Description
OCDS [1:0]	00	DSP clock frequency is equal to the sampling clock divided by 2N
	01	DSP clock frequency is equal to the sampling clock divided by 2N*2
	10	Not allowed
	11	Not allowed

Figure 5-10. OCDS Timing Diagram for 4:1 MUX

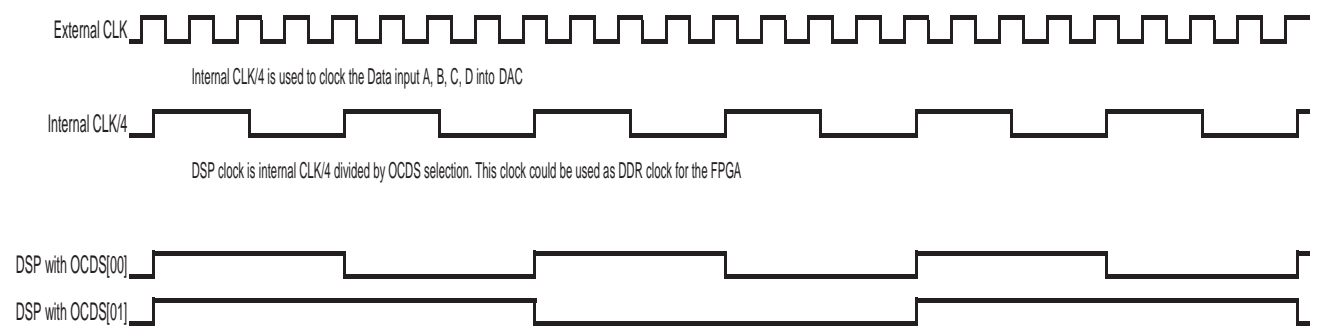
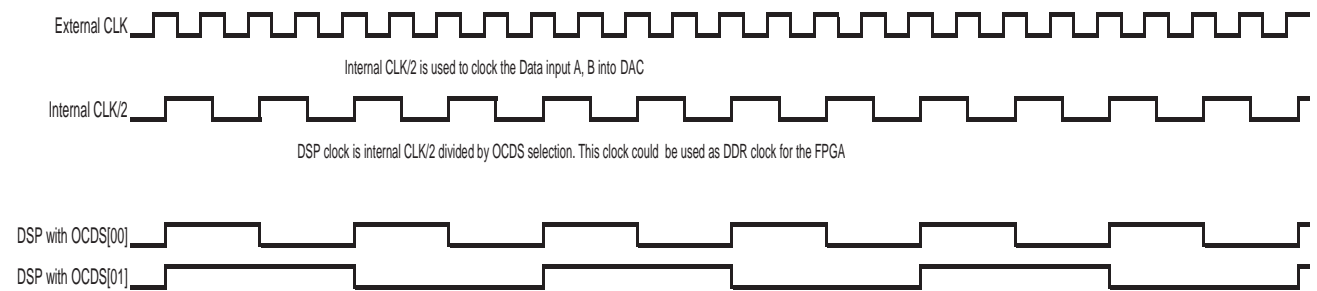


Figure 5-11. OCDS Timing Diagram for 2:1 MUX





## 5.6 Synchronization FPGA-DAC: IDC\_P, IDC\_N, HTVF and STVF Functions

IDC\_P, IDC\_N: Input Data check function (LVDS signal).

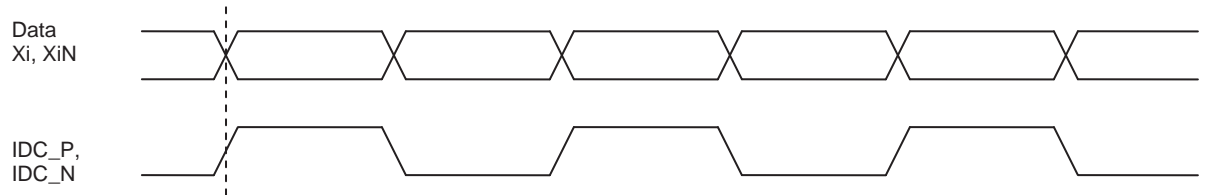
HTVF: Hold Time Violation Flag. (cmos3.3V signal)

STVF: Setup Time Violation Flag. (cmos3.3V signal)

IDC signal is toggling at each cycle synchronously with other data bits. It should be considered as a DAC input data that toggles at each cycle.

This signal should be generated by the FPGA in order for the DAC to check in real-time if the timings between the FPGA and the DAC are correct.

**Figure 5-12.** IDC Timing vs Data Input



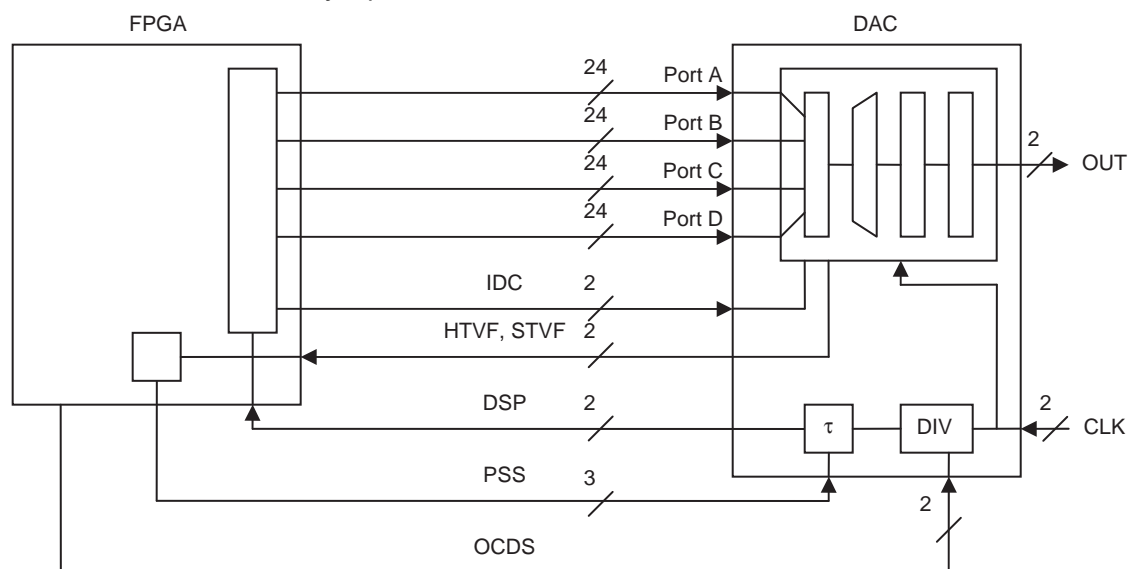
The information on the timings is then given by HTVF, STVF signals (flags).

**Table 5-4.** HTVF, STVF Coding Table

Label	Value	Description
HTVF	0	SYNCHRO OK
	1	Data Hold time violation detected
STVF	0	SYNCHRO OK
	1	Data Setup time violation detected

During monitoring STVF indicates setup time of data violation (Low -> OK, High -> Violation), HTVF indicates hold time of data violation (Low -> OK, High -> Violation).

**Figure 5-13.** FPGA to DAC Synoptic



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## Principle of Operation:

The Input Data Check pair (IDC\_P, IDC\_N) will be sampled three times with half a master clock period shift (the second sample being synchronous with all the data sampling instant), these three samples will be compared, and depending on the results of the comparison a violation may be signalled.

- Violation of setup time -> STVF is high level
- Violation of hold time -> HTVF is high level

In case of violation of timing (setup or hold) the user has two solutions:

- Shift phase in the FPGA PLL (if this functionality is available in FPGA) for changing the internal timing of DATA and Data Check signal inside FPGA.
- Shift the DSP clock timing (Output clock of the DAC which can be used for FPGA synchronization – refer to [Section 5.4 on page 22](#)), in this case this shift also shift the internal timing of FPGA clock.

Note: When used, it should be routed as the data signals (same layout rules and same length). if not used, it should be driven to an LVDS low or high level.

For further details, refer to application note AN1087.

## 5.7 OCDS, MUX Combinations Summary

**Table 5-5.** OCDS, MUX, PSS Combinations Summary

MUX		OCDS		PSS Range	Data Rate	Comments
0	4:1	00	DSP clock division factor 8	0 to 7/(2Fs) by 1/(2Fs) steps	Fs/4	Refer to <a href="#">Section 5.5</a>
0		01	DSP clock division factor 16			
0		10	Not allowed			
0		11	Not allowed			
1	2:1	00	DSP clock division factor 4	0 to 7/(2Fs) by 1/(2Fs) steps	Fs/2	Refer to <a href="#">Section 5.5</a>
1		01	DSP clock division factor 8			
1		10	Not allowed			
1		11	Not allowed			

Note: Behaviour according to MUX, OCDS and PSS combination is independent of output mode (MODE).

## 5.8 Synchronization functions for multi-DAC operation

In order to synchronize the timings, a SYNC operation can be generated.

After the application of the SYNC signal the DSP clock from the DAC will stop for a period and after a constant and known time the DSP clock will start up again.

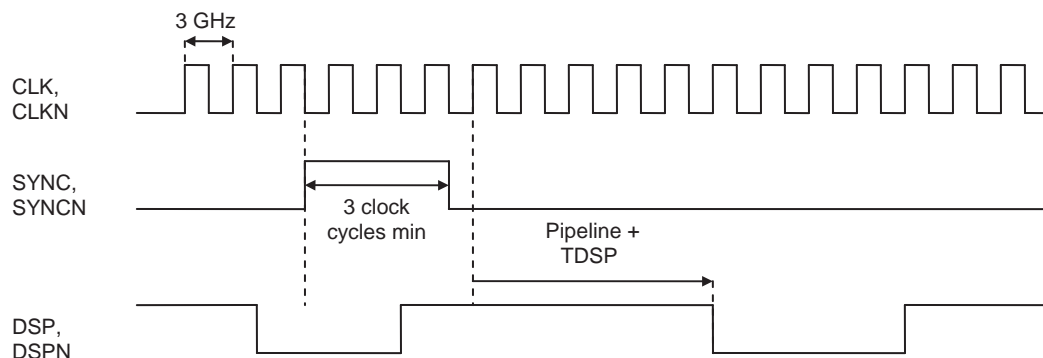
There are two SYNC functions integrated in this DAC:

- a power up reset, which is triggered by the power supplies if the dedicated power up sequence is applied  $V_{CCD} \Rightarrow V_{CCA3} \Rightarrow V_{CCA5}$ ;
- External SYNC pulse applied on (SYNC, SYNCN).

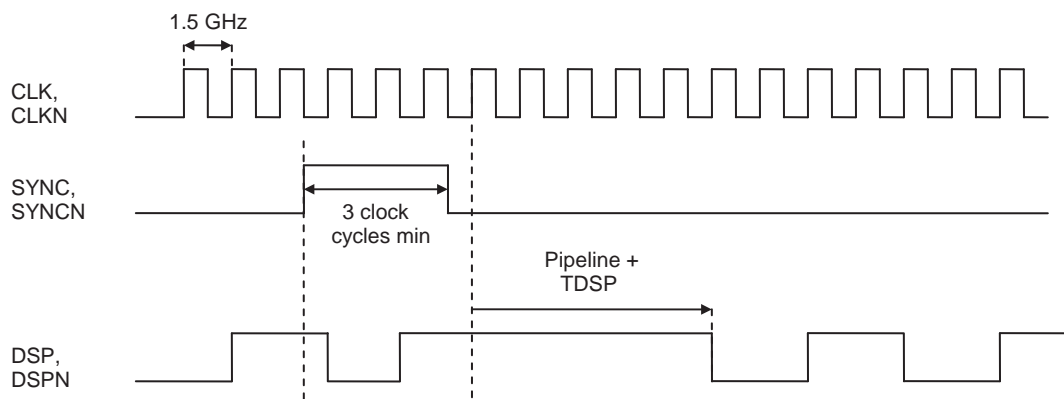
The external SYNC is LVDS compatible (same buffer as for the digital input data). It is active high.

Depending on the settings for OCDS, PSS and also the MUX ratio the width of the SYNC pulse must be greater than a certain number of external clock pulses. It is also necessary that the sync pulse be synchronized with the system clock and is an integer number of clock pulses. See application note (ref 1087) for further details.

**Figure 5-14.** Reset Timing Diagram (4:1 MUX)



**Figure 5-15.** Reset Timing Diagram (2:1 MUX)



**Important note:**

**For EV12DS130A:**

- See erratasheet (ref 1125) for SYNC condition of use.
- SYNC, SYNCN pins have to be driven.

**For EV12DS130B:**

- SYNC, SYNCN pins can be left floating if unused.
- No specific timing constraints (other than T1 and T2) are required.

## 5.9 Gain Adjust GA Function

This function allows to adjust the internal gain of the DAC to cancel the initial gain deviation.

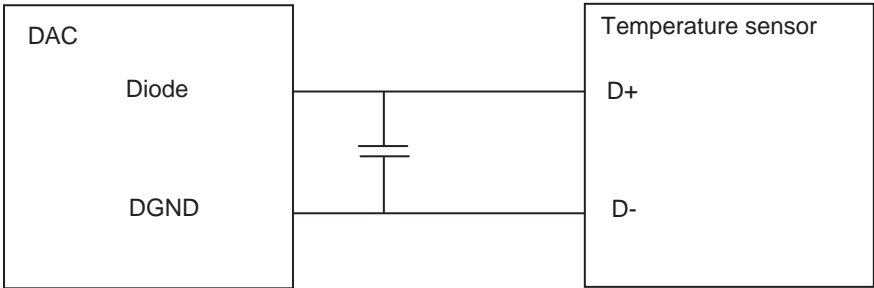
The gain of the DAC can be adjusted by  $\pm 11\%$  by tuning the voltage applied on GA by varying GA potential from 0 to  $V_{CCA3}$ .

GA max is given for GA = 0 and GA min for GA =  $V_{CCA3}$

5.10 Diode Function

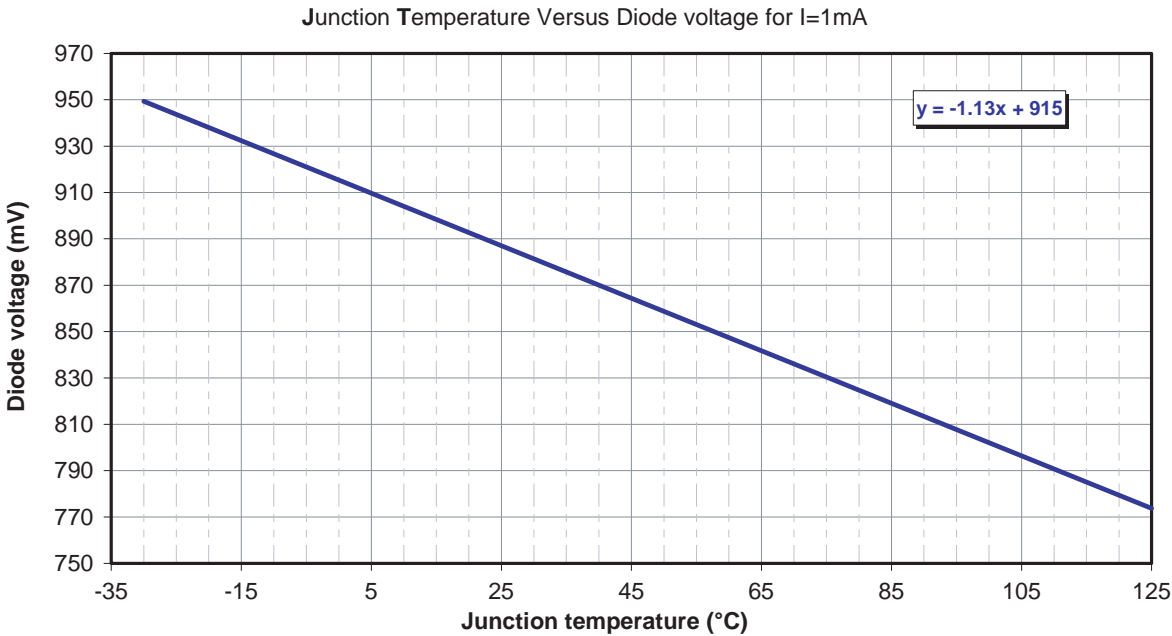
A diode is available to monitor the die junction temperature of the DAC.  
For the measurement of die junction temperature, you may use a temperature sensor.

Figure 5-16. Temperature DIODE Implementation



In characterization measurement a current of 1 mA is applied on the DIODE pin. The voltage across the DIODE pin and the DGND pin gives the junction temperature using the intrinsic diode characteristics below [Figure 5-17](#).

Figure 5-17. Diode Characteristics for Die Junction Monitoring



## 6. PIN Description

**Figure 6-1.** Pinout View fpBGA196 (Top View)

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	
A	DGND	B5	B6	B6N	B9	B9N	B11	C11	C9N	C9	C6N	C6	C5	DGND	A
B	B3	B4	B5N	B7	B8	B10	B11N	C11N	C10	C8	C7	C5N	C4	C3	B
C	B1N	B3N	B4N	B7N	B8N	B10N	DGND	DGND	C10N	C8N	C7N	C4N	C3N	C1N	C
D	B1	B2	B2N	DGND	DGND	VCCD	VCCD	VCCD	VCCD	DGND	DGND	C2N	C2	C1	D
E	A10N	B0	B0N	DGND	DGND	VCCD	VCCD	VCCD	VCCD	DGND	DGND	C0N	C0	D10N	E
F	A10	A11	A11N	VCCD	VCCD	AGND	AGND	AGND	AGND	VCCD	VCCD	D11N	D11	D10	F
G	A8	A8N	A9	A9N	DGND	AGND	AGND	AGND	AGND	DGND	D9N	D9	D8N	D8	G
H	A6	A6N	A7	A7N	DGND	AGND	AGND	AGND	AGND	DGND	D7N	D7	D6N	D6	H
J	A3N	A5	A5N	VCCA3	VCCA3	AGND	AGND	AGND	AGND	VCCA3	VCCA3	D5N	D5	D3N	J
K	A3	A4	A4N	DGND	DGND	AGND	VCCA5	VCCA5	AGND	DGND	DGND	D4N	D4	D3	K
L	A1N	A2	A2N	DGND	Diode	VCCA5	VCCA5	VCCA5	VCCA5	DGND	MUX	D2N	D2	D1N	L
M	A1	A0N	GA	HTVF	STVF	VCCA5	VCCA5	AGND	AGND	MODE0	MODE1	PSS2	D0N	D1	M
N	A0	DSPN	IDC_P	SYNCP	CLKN	AGND	AGND	AGND	AGND	AGND	AGND	OCDS1	OCDS0	D0	N
P	DGND	DSP	IDC_N	SYNC	CLK	AGND	AGND	AGND	OUT	OUTN	AGND	PSS0	PSS1	DGND	P
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	

**Table 6-1.** Pinout Table fpBGA196

Signal name	Pin number	Description	Direction	Equivalent Simplified schematics
<b>Power Supplies</b>				
V <sub>CCA5</sub>	K7, K8, L6, L7, L8, L9, M6, M7	5V analogue power supplies Referenced to AGND	N/A	
V <sub>CCA3</sub>	J4, J5, J10, J11	3.3V analogue power supply Referenced to AGND	N/A	
V <sub>CCD</sub>	D6, D7, D8, D9, E6, E7, E8, E9, F4, F5, F10, F11	3.3V digital power supply Referenced to DGND	N/A	
AGND	F6, F7, F8, F9, G6, G7, G8, G9, H6, H7, H8, H9, J6, J7, J8, J9, K6, K9, M8, M9, N6, N7, N8, N9, N10, N11, P6, P7, P8, P11	Analog Ground	N/A	

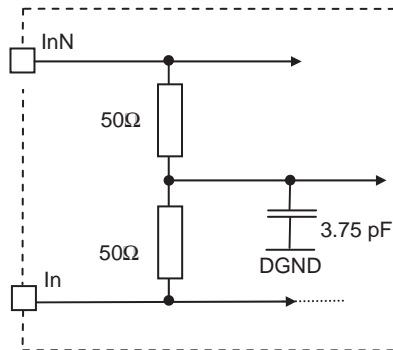
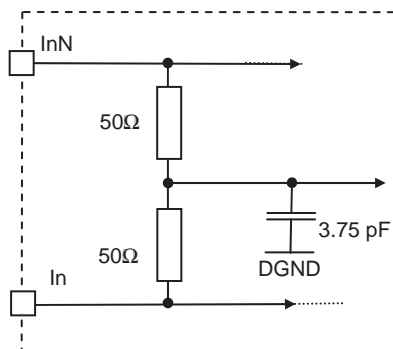
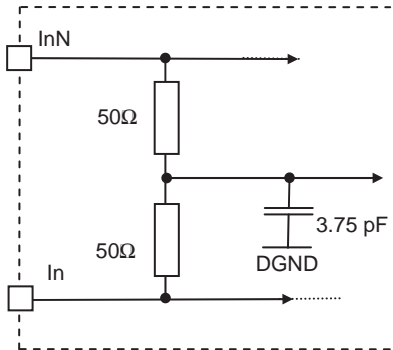
# EV12DS130AZP

## EV12DS130BZP

**Table 6-1.** Pinout Table fpBGA196 (Continued)

Signal name	Pin number	Description	Direction	Equivalent Simplified schematics
DGND	A1, A14, C7, C8, D4, D5, D10, D11, E4, E5, E10, E11, G5, G10, H5, H10, K4, K5, K10, K11, L4, L10, P1, P14	Digital Ground	N/A	
<b>Clock Signals</b>				
CLK, CLKN	P5, N5	<p>Master sampling clock input (differential) with internal common mode</p> <p>It should be driven in AC coupling.</p> <p>Equivalent internal differential 100Ω input resistor.</p>	I	
DSP, DSPN	P2, N2	Output clock (in-phase and inverted phase)	O	
<b>Analog Output Signal</b>				
OUT, OUTN	P9, P10	In phase and Inverted phase analogue output signal (differential termination required)	O	

**Table 6-1.** Pinout Table fpBGA196 (Continued)

Signal name	Pin number	Description	Direction	Equivalent Simplified schematics
<b>Digital Input Signals</b>				
A0, A0N A1, A1N A2, A2N A3, A3N A4, A4N A5, A5N A6, A6N A7, A7N A8, A8N A9, A9N A10, A10N A11, A11N	N1, M2 M1, L1 L2, L3 K1, J1 K2, K3 J2, J3 H1, H2 H3, H4 G1, G2 G3, G4 F1, E1 F2, F3	In-phase Digital input Port A Data A0, A0N is the LSB Data A11, A11N is the LSB	I	
B0, B0N B1, B1N B2, B2N B3, B3N B4, B4N B5, B5N B6, B6N B7, B7N B8, B8N B9, B9N B10, B10N B11, B11N	E2, E3 D1, C1 D2, D3 B1, C2 B2, C3 A2, B3 A3, A4 B4, C4 B5, C5 A5, A6 B6, C6 A7, B7	Inverted phase Digital input Port B Data B0, B0N is the LSB Data B11, B11N is the LSB	I	
C0, C0N C1, C1N C2, C2N C3, C3N C4, C4N C5, C5N C6, C6N C7, C7N C8, C8N C9, C9N C10, C10N C11, C11N	E13, E12 D14, C14 D13, D12 B14, C13 B13, C12 A13, B12 A12, A11 B11, C11 B10, C10 A10, A9 B9, C9 A8, B8	In-phase Digital input Port B Data 1	I	

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Table 6-1. Pinout Table fpBGA196 (Continued)

Signal name	Pin number	Description	Direction	Equivalent Simplified schematics
D0, D0N D1, D1N D2, D2N D3, D3N D4, D4N D5, D5N D6, D6N D7, D7N D8, D8N D9, D9N D10, D10N D11, D11N	N14, M13 M14, L14 L13, L12 K14, J14 K13, K12 J13, J12 H14, H13 H12, H11 G14, G13 G12, G11 F14, E14 F13, F12	Inverted phase Digital input Port B Data 1	I	
Control Signals				
HTVF	M4	Setup time violation flag	O	
STVF	M5	Hold time violation flag	O	



**Table 6-1.** Pinout Table fpBGA196 (Continued)

Signal name	Pin number	Description	Direction	Equivalent Simplified schematics
IDC_P, IDC_N	N3, P3	Input data check	I	
PSS0 PSS1 PSS2	P12 P13 M12	Phase Shift Select (PSS2 is the MSB)	I	
MODE0 MODE1	M10 M11	DAC Mode selection bits	I	

# EV12DS130AZP

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**Table 6-1.** Pinout Table fpBGA196 (Continued)

Signal name	Pin number	Description	Direction	Equivalent Simplified schematics
MUX	L11	MUX selection	I	
OCDS0 OCDS1	N13 N12	Output Clock Division Select = these bits allow to select the clock division factor applied on the DSP, DSPN signal.	I	

**Table 6-1.** Pinout Table fpBGA196 (Continued)

Signal name	Pin number	Description	Direction	Equivalent Simplified schematics
SYNC, SYNCH	P4, N4	In phase and Inverted phase reset signal	I	
GA	M3	Gain adjust	I	
Diode	L5	Diode for die junction temperature monitoring	I	

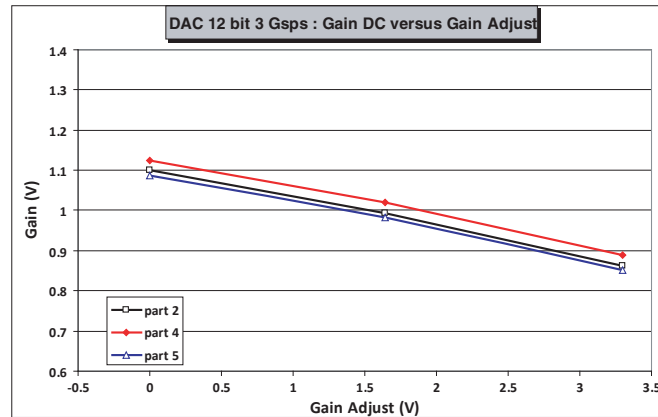
## 7. Characterization Results

Unless otherwise specified results are given at room temperature ( $T_j \sim 60^\circ\text{C}$ ), nominal power supply, in 4:1 MUX mode, gain at nominal setting.

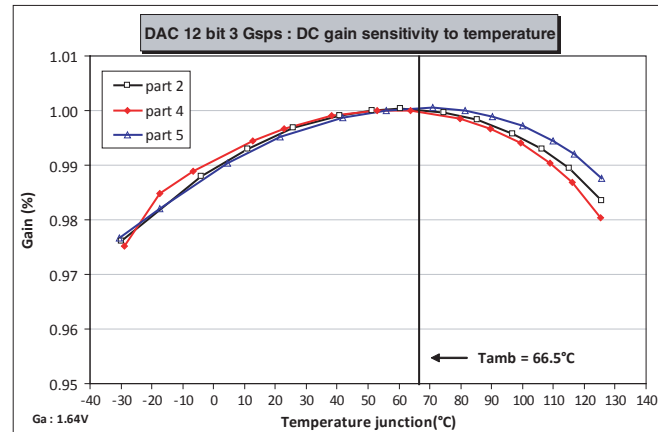
### 7.1 Static Performances

#### 7.1.1 DC Gain Characterization

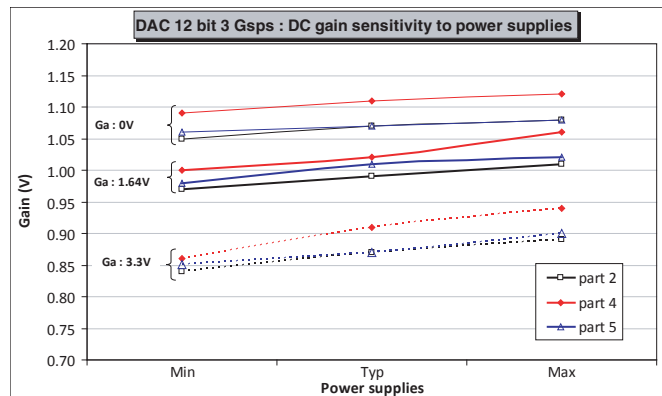
**Figure 7-1.** DAC DC Gain vs Gain Adjust (Measured in NRZ Mode)



**Figure 7-2.** DAC DC Gain Drift from Unity Gain vs Temperature (Measured in NRZ Mode)



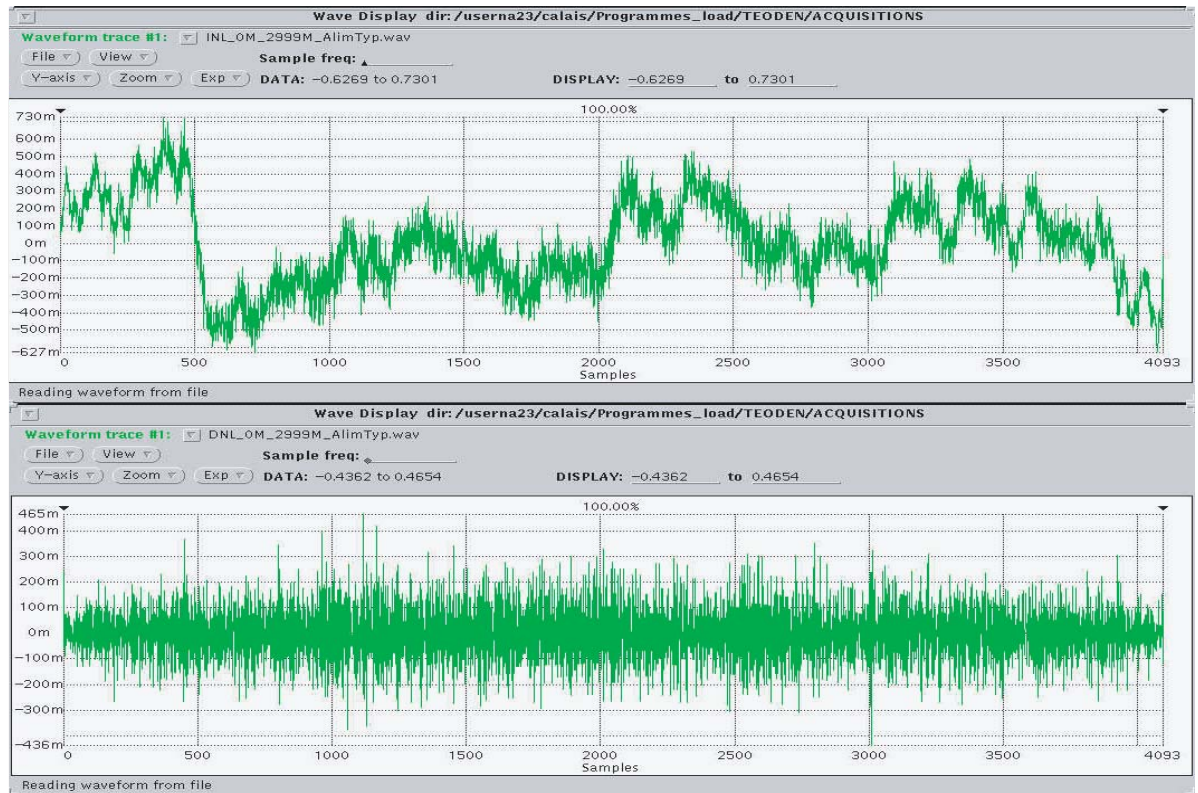
**Figure 7-3.** DC Gain Sensitivity to Power Supply (Measured in NRZ Output Mode)



Conditions: room temperature, supply levels:  
 - Min:  $V_{CCA}$ : 4.75V //  $V_{CCA3} = V_{CCD} = 3.15\text{V}$   
 - Typ:  $V_{CCA}$ : 5V //  $V_{CCA3} = V_{CCD} = 3.3\text{V}$   
 - Max:  $V_{CCA}$ : 5.25V //  $V_{CCA3} = V_{CCD} = 3.45\text{V}$

## 7.1.2 Static Linearity

**Figure 7-4.** INL/DNL Measurement at  $f_{out} = 100\text{ kHz}$  and 3 Gsps



INL reflects a true 12 bit DAC.

Low DNL values reflect a strictly monotonous 12 bit DAC.

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# EV12DS130BZP

## 7.2 AC Performances

### 7.2.1 Available Output Power vs Fout.

The following plots summarize characterization results, for a Fout sweep from 98 MHz to 4498 MHz (step 100 MHz).

Figure 7-5. Available Pout vs Fout from 98 MHz to 4498 MHz in the 4 Output Modes at 3 Gsps

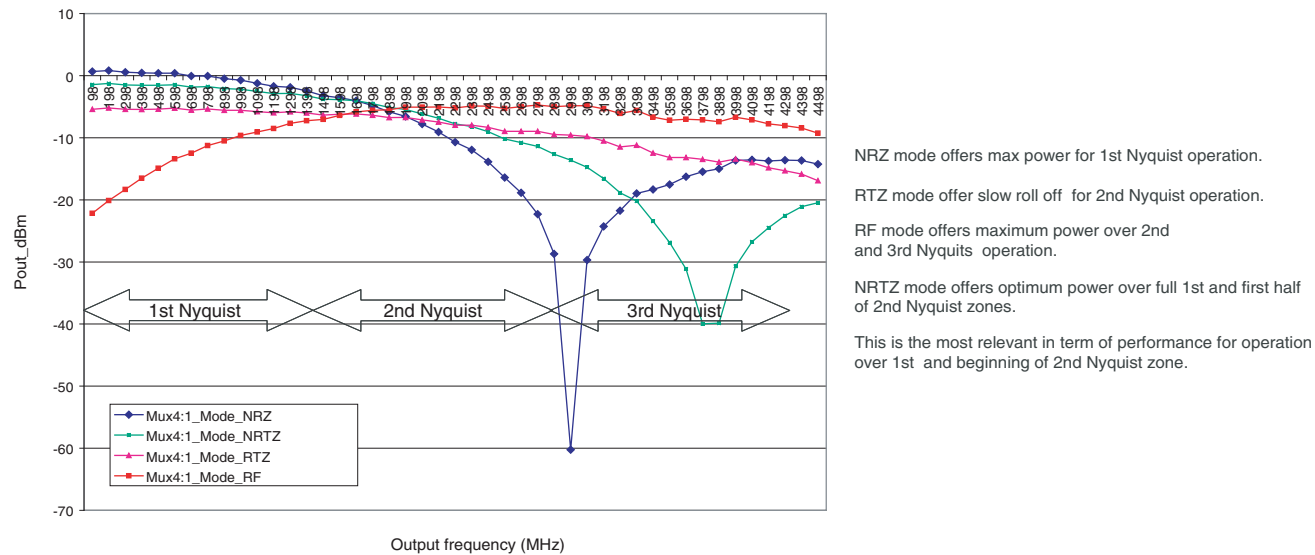
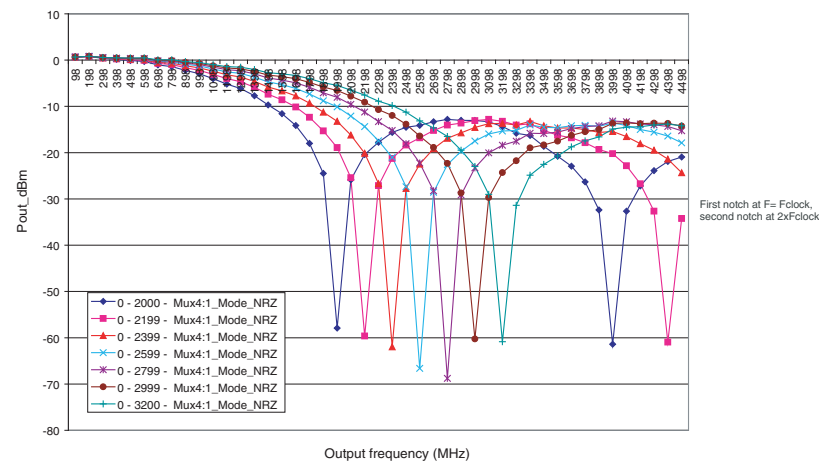
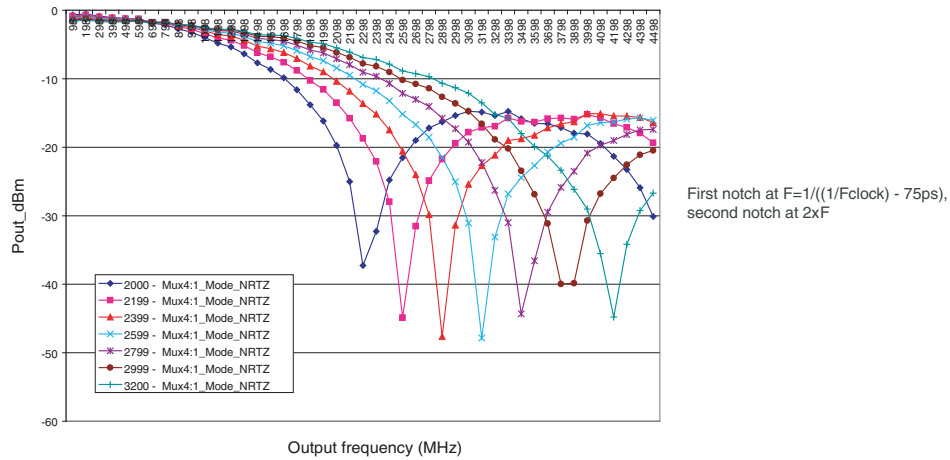


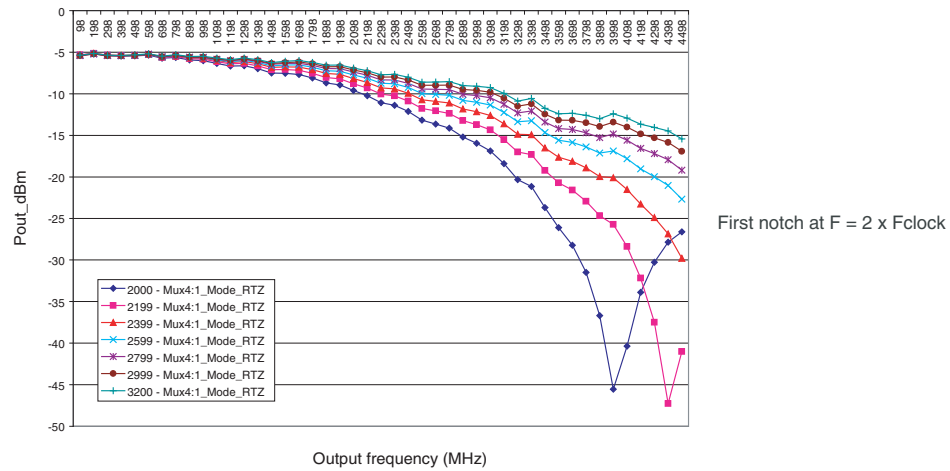
Figure 7-6. Available Pout vs Fout from 98 MHz to 4498 MHz and from 2 Gsps to 3.2 Gsps in NRZ Mode



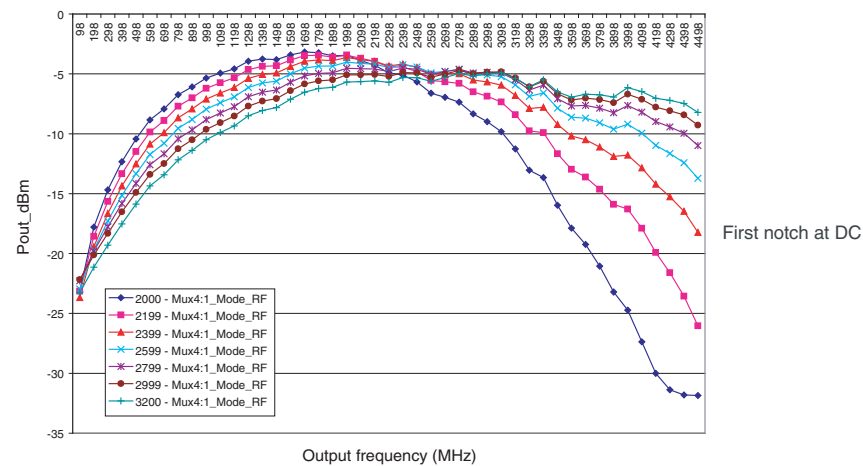
**Figure 7-7.** Available Pout vs Fout from 98 MHz to 4498 MHz and from 2 Gps to 3.2 Gps in NRTZ Mode



**Figure 7-8.** Available Pout vs Fout from 98 MHz to 4498 MHz and from 2 Gps to 3.2 Gps in RTZ Mode



**Figure 7-9.** Available Pout vs Fout from 98 MHz to 4498 MHz and from 2 Gps to 3.2 Gps in RF Mode



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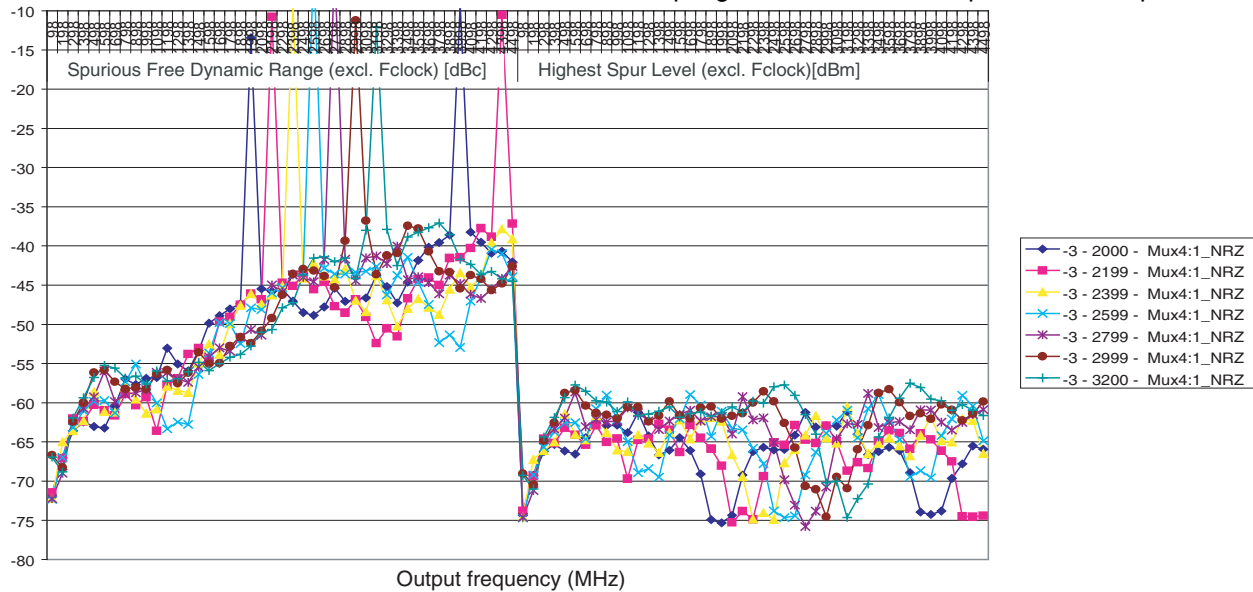
# EV12DS130BZP

## 7.2.2 Single Tone Measurements

The following plots summarize characterization results in MUX4:1 mode, for an Fout sweep from 98 MHz to 4498 MHz (step 100 MHz).

The left side of the plot gives SFDR expressed in dBc and the right side gives HSL (Highest Spur Level excluding Fclock spur) expressed in dBm.

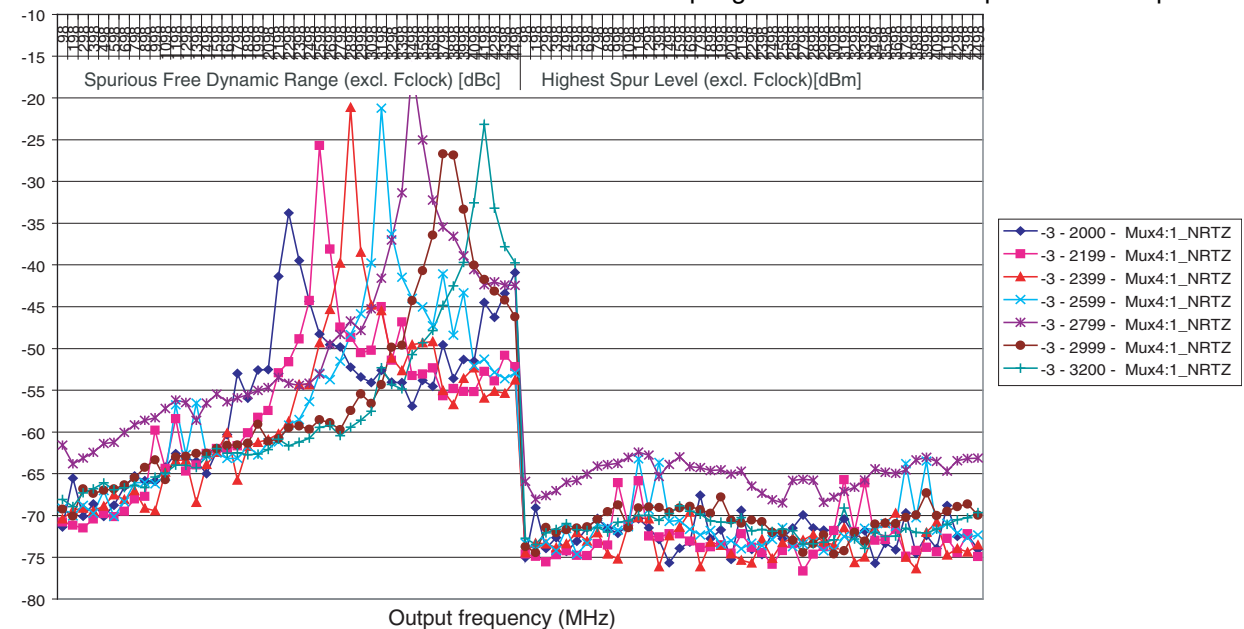
**Figure 7-10.** SFDR and HSL in NRZ mode at –3 dBFS for Sampling Rate from 2000 MSps to 3200 MSps



NRZ mode is only relevant for Fout below 400 MHz.

The spikes in the SFDR are caused by normalization artefacts due to the Sinc(x) null.

**Figure 7-11.** SFDR and HSL in NRTZ mode at –3 dBFS for Sampling Rate from 2000 MSps to 3200 MSps

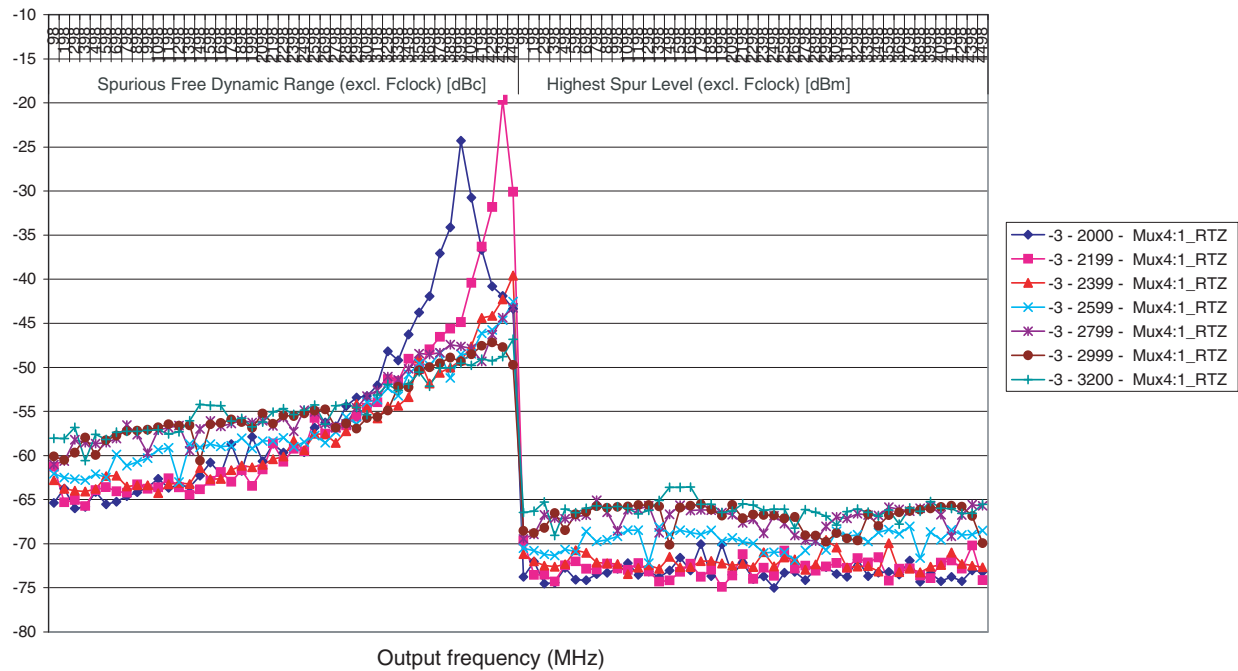


NRTZ mode brings significant improvement regarding NRZ mode. This mode concentrates the benefits of both NRZ mode (high power available) and RTZ mode (extended available dynamic range).

The spikes in the SFDR are caused by normalization artefacts due to the Sinc(x) null.



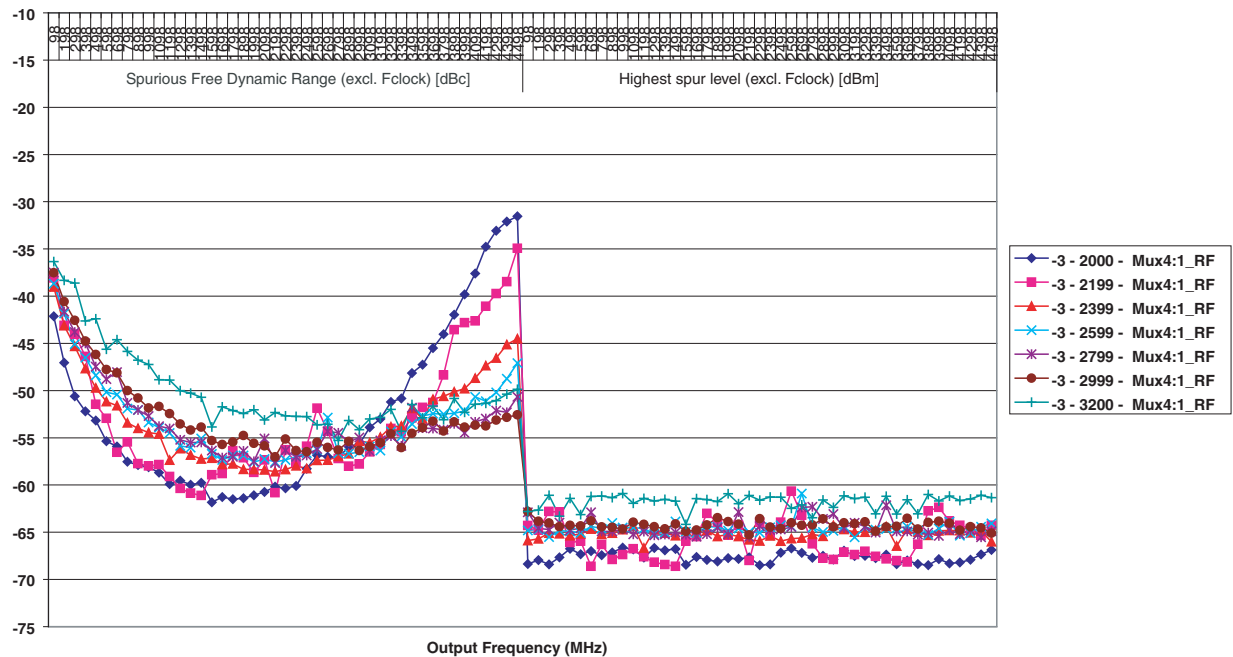
**Figure 7-12.** SFDR and HSL in RTZ Mode at -3 dBFS for Sampling Rate from 2000 MSps to 3200 MSps



RTZ mode allows for operation over the 3 first Nyquist zones.

In first and beginning of second Nyquist zone NRTZ mode is mode relevant. The spikes in the SFDR are caused by normalization artefacts due to the Sinc(x) null.

**Figure 7-13.** SFDR and HSL in RF Mode at -3 dBFS for Sampling Rate from 2000 MSps to 3200 MSps

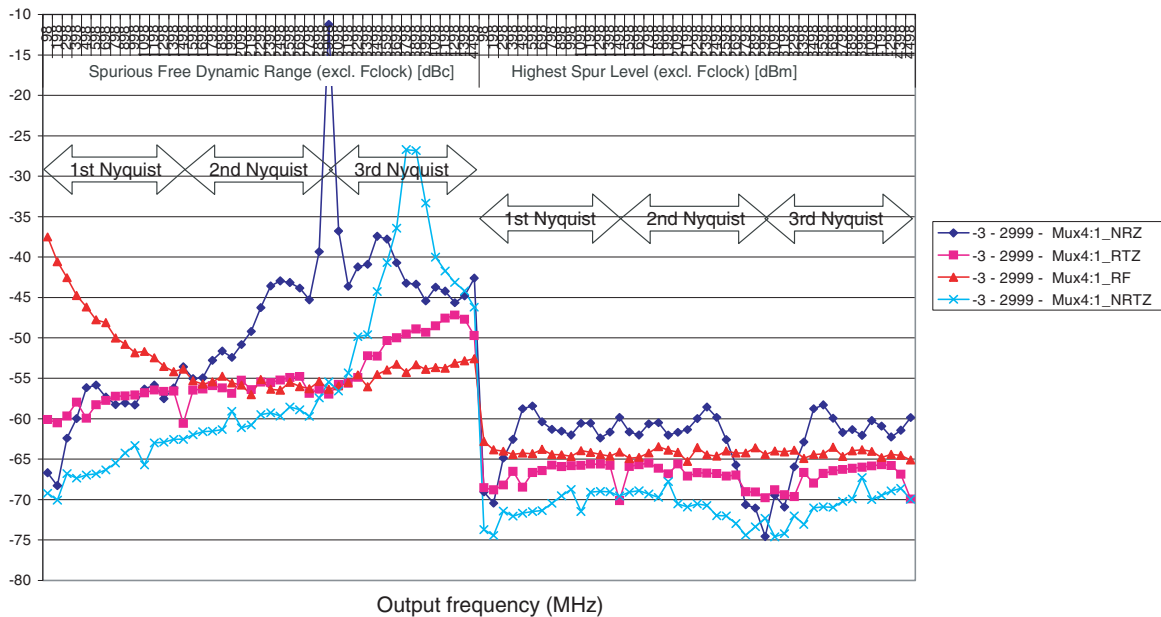


RF mode allows for operation over 3<sup>rd</sup> Nyquist zones. Performances are not sensitive to output level. Performance roll off occurs beyond 3000 MSps.

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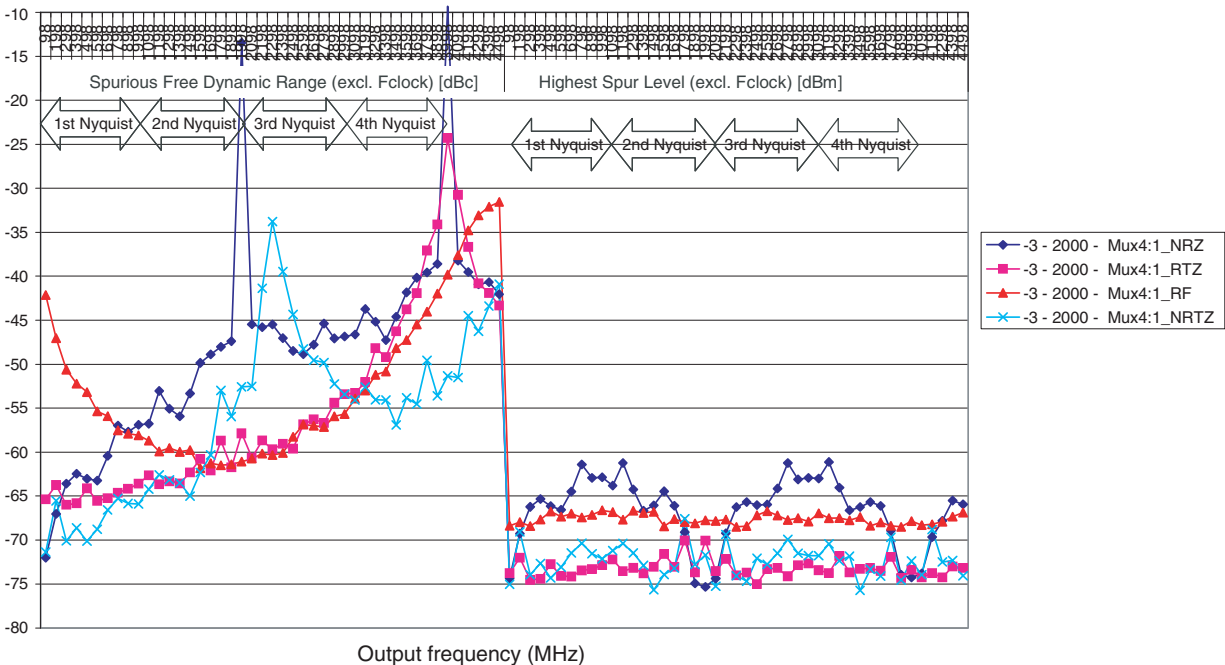
# EV12DS130BZP

**Figure 7-14.** Comparison of the 4 Output Modes at 2999 MSps and at -3 dBFS: SFDR and HSL



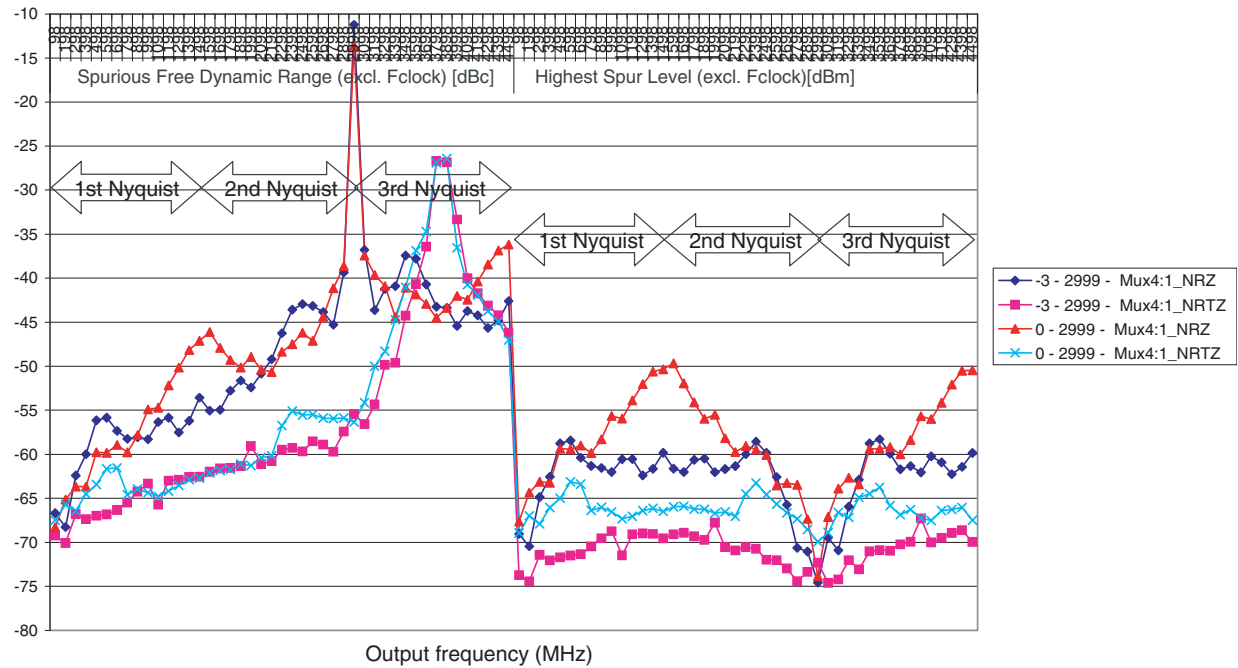
NRZ is interesting only at the very beginning of the first Nyquist zone.  
 NRTZ is relevant over 1<sup>st</sup> 2<sup>nd</sup> and 4<sup>th</sup> Nyquist zones.  
 RTZ is relevant over 2<sup>nd</sup> and 3<sup>rd</sup> Nyquist zones.  
 RF mode displays a good behavior over 2<sup>nd</sup> and 3<sup>rd</sup> Nyquist Zones.  
 The spikes in the SFDR are caused by normalization artefacts due to the Sinc(x) null

**Figure 7-15.** Comparison of the 4 Output Modes at 2000 MSps and -3 dBFS: SFDR and HSL



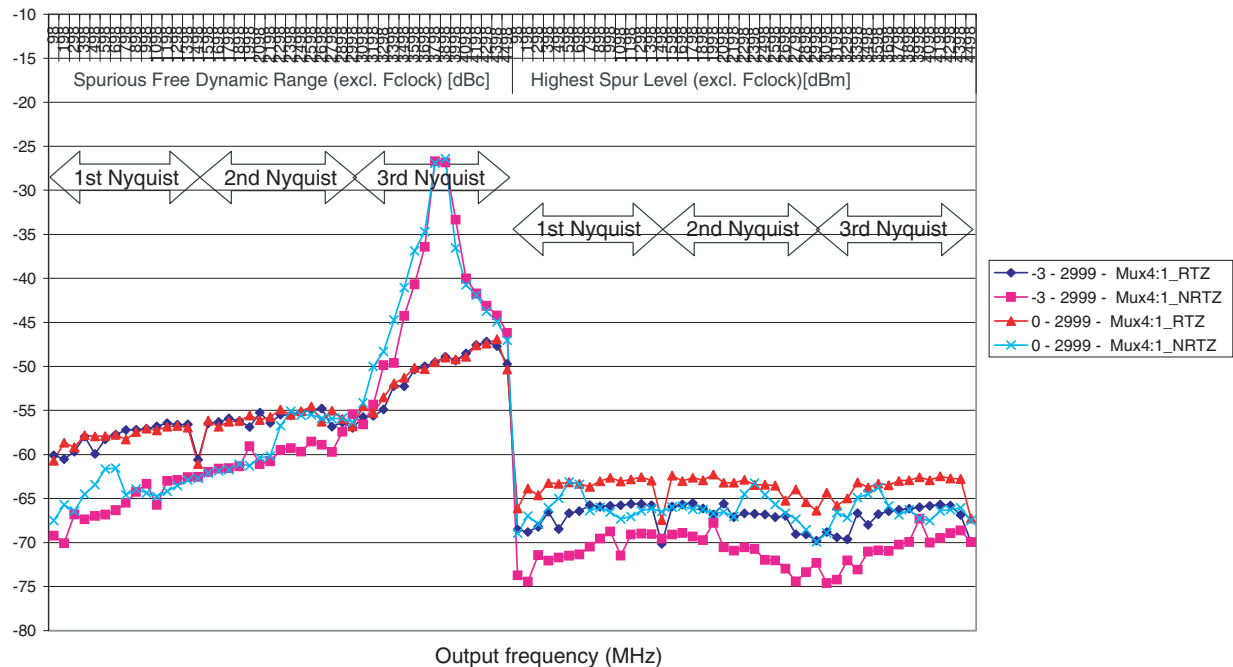
NRTZ is the most relevant over 1<sup>st</sup> Nyquist zone, 1<sup>st</sup> half of 2<sup>nd</sup> Nyquits zone and 4th Nyquist zone.  
 RF mode is the best choice for 2<sup>nd</sup> half of 2<sup>nd</sup> Nyquist Zone and 3<sup>rd</sup> Nyquist zone.  
 RTZ gives relevant performances over the three first Nyquist zones.  
 The spikes in the SFDR are caused by normalization artefacts due to the Sinc(x) null

**Figure 7-16.** Comparison of NRZ and NRTZ Modes at Full Scale and -3 dBFS at 2999 MSps: SFDR and HSL (Excluding Fclock)



NRTZ gives better performances over 1<sup>st</sup> and 2<sup>nd</sup> Nyquist zone, and is much less sensitive to output level.

**Figure 7-17.** Comparison of NRTZ and RTZ Modes at Full Scale and -3 dBFS at 2999 MSps: SFDR and HSL

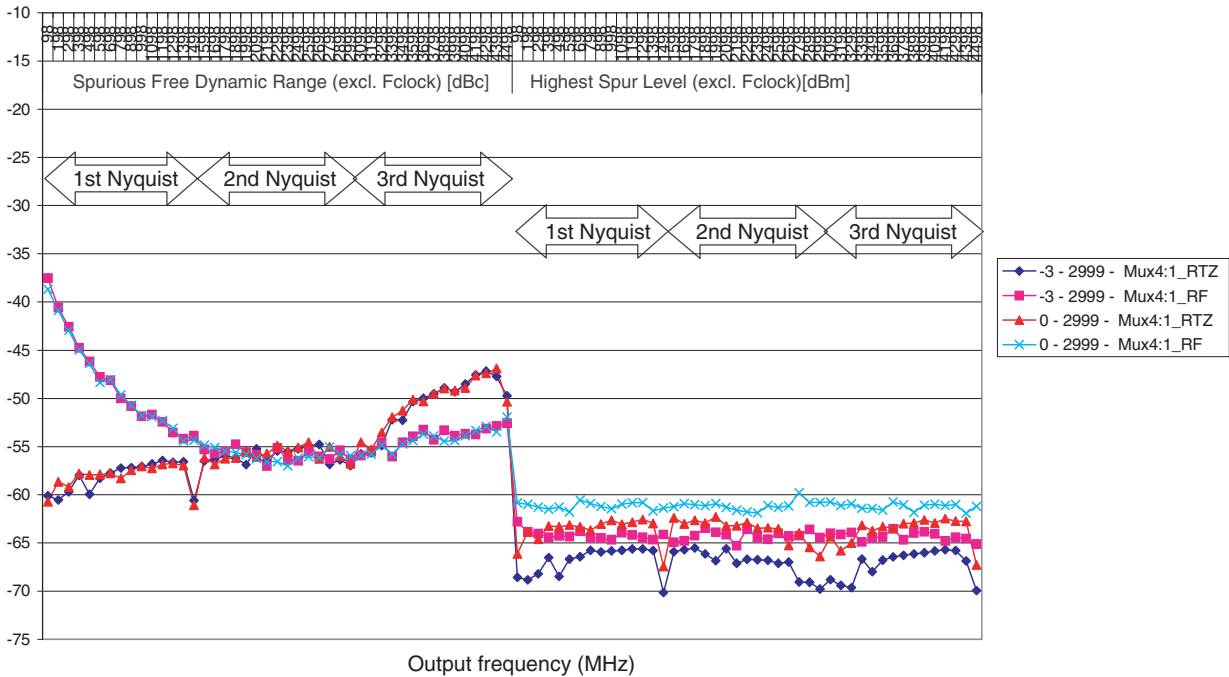


NRTZ is more relevant for 1<sup>st</sup> Nyquist zone and 1<sup>st</sup> half of 2<sup>nd</sup> Nyquist zone. Beyond middle of second Nyquist zone RTZ mode is more relevant.

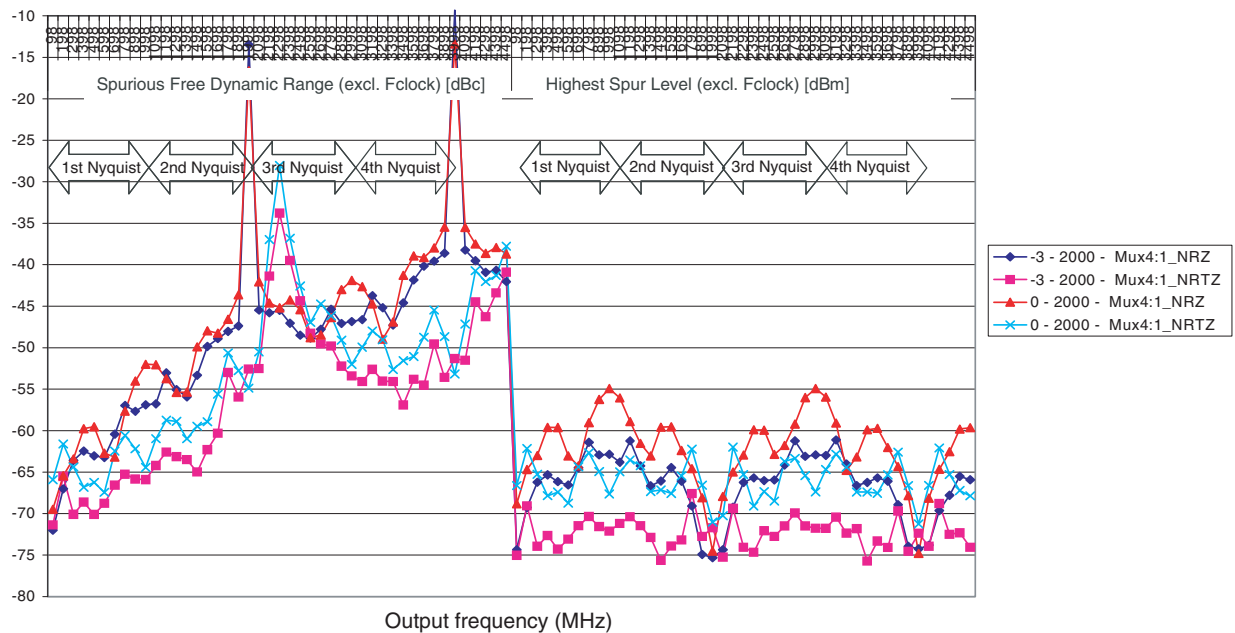
# EV12DS130AZP

# EV12DS130BZP

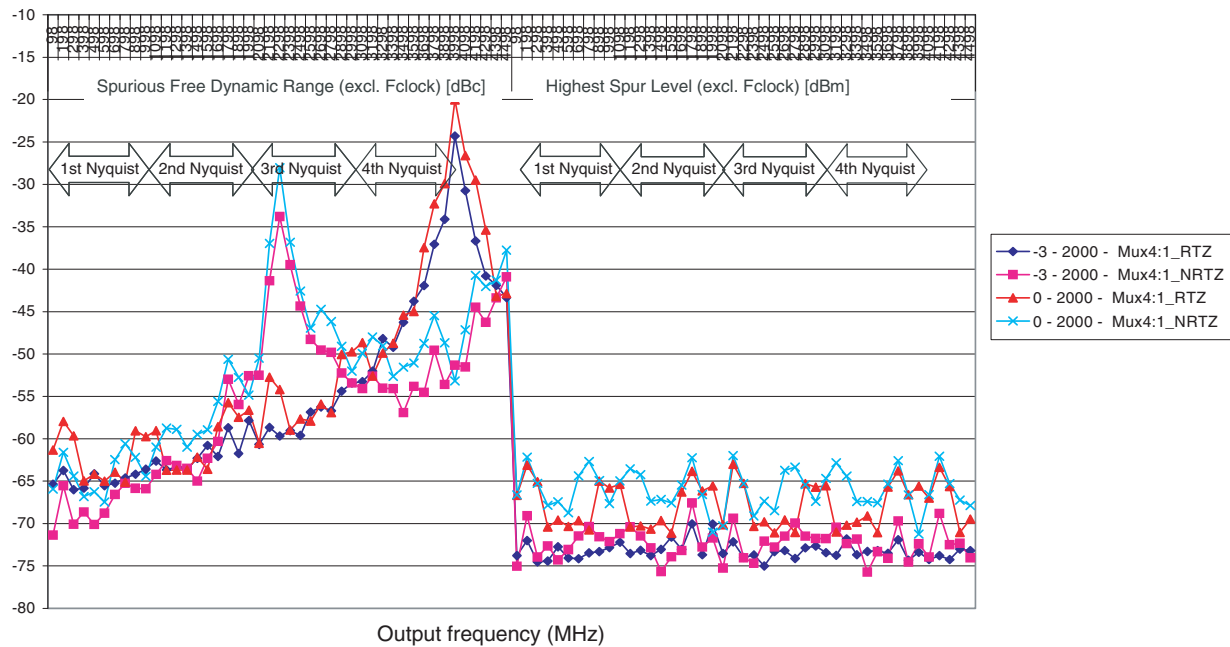
**Figure 7-18.** Comparison of RTZ and RF Modes at Full Scale and -3 dBFS at 2999 MSps: SFDR and HSL



**Figure 7-19.** Comparison of NRZ and NRTZ Modes at Full Scale and -3 dBFS at 2000 MSps: SFDR and HSL (Excluding Fclock)



**Figure 7-20.** Comparison of NTRZ and RTZ Modes at Full Scale and -3 dBFS at 2000 MSps: SFDR and HSL (Excluding Fclock)



NRTZ mode is relevant in 1<sup>st</sup>, 2<sup>nd</sup> Nyquist zones and is still usable over 4<sup>th</sup> Nyquist zone with SFDR in excess of 50 dBc.

### 7.2.3 Single tone measurements: typical spectra at 3GspS

The following figures show typical SFDR spectra obtained for the four DAC modes on an EV12DS130A/B device.

Conditions: typical power supplies, ambient temperature, MUX4:1, Fs = 3 GspS.

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Figure 7-21. Typical SFDR spectrum in NRZ mode. Fout = 100MHz (1st Nyquist), MUX4:1, Fs = 3Gsps. SFDR = 67dBc

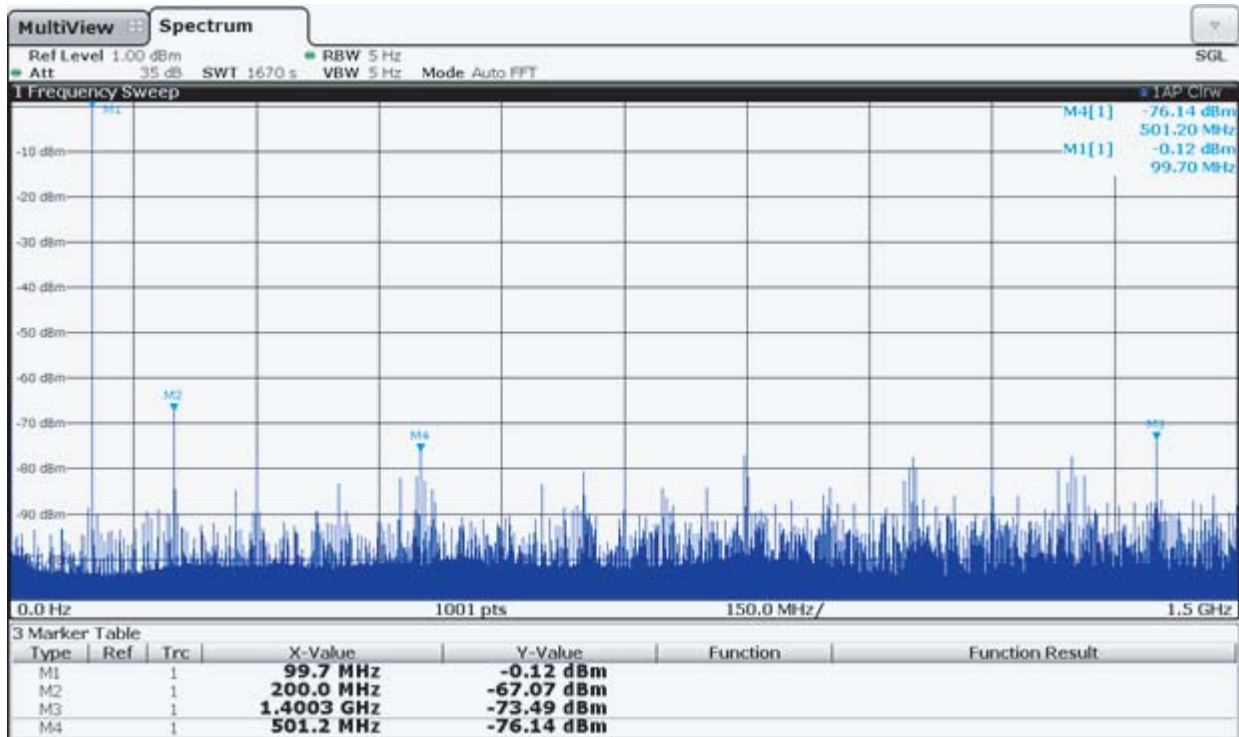
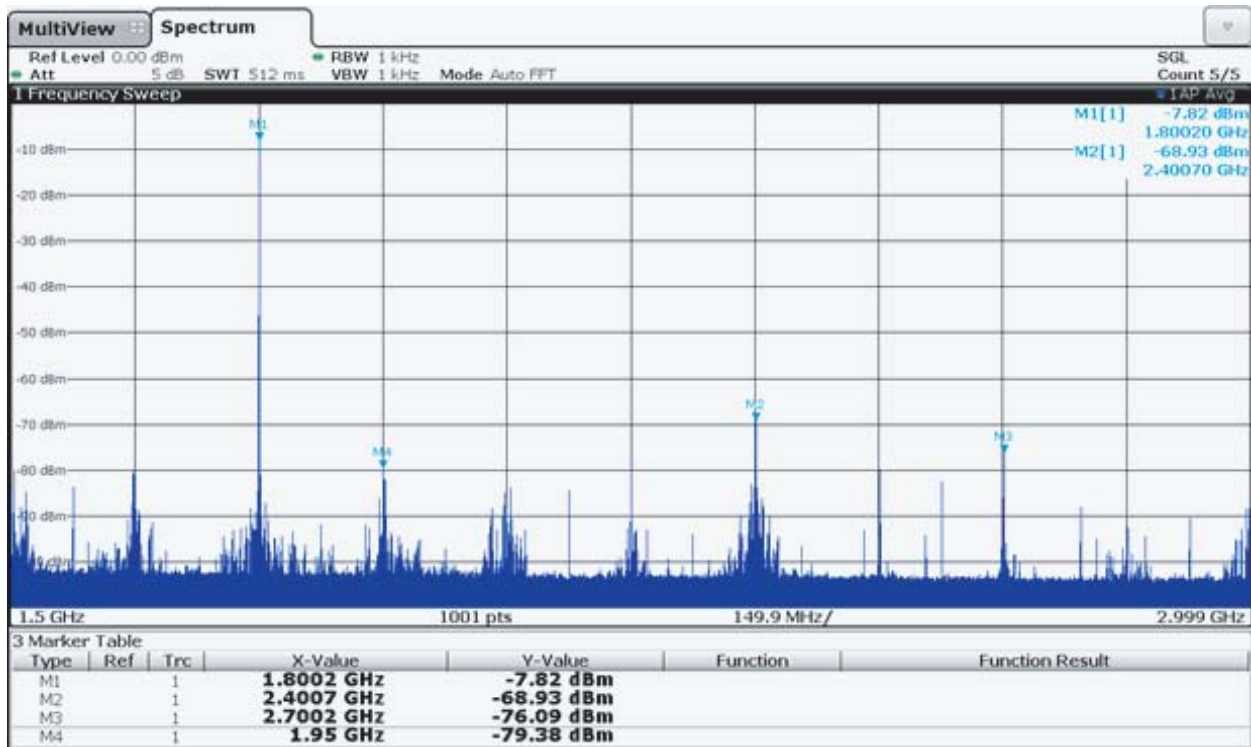
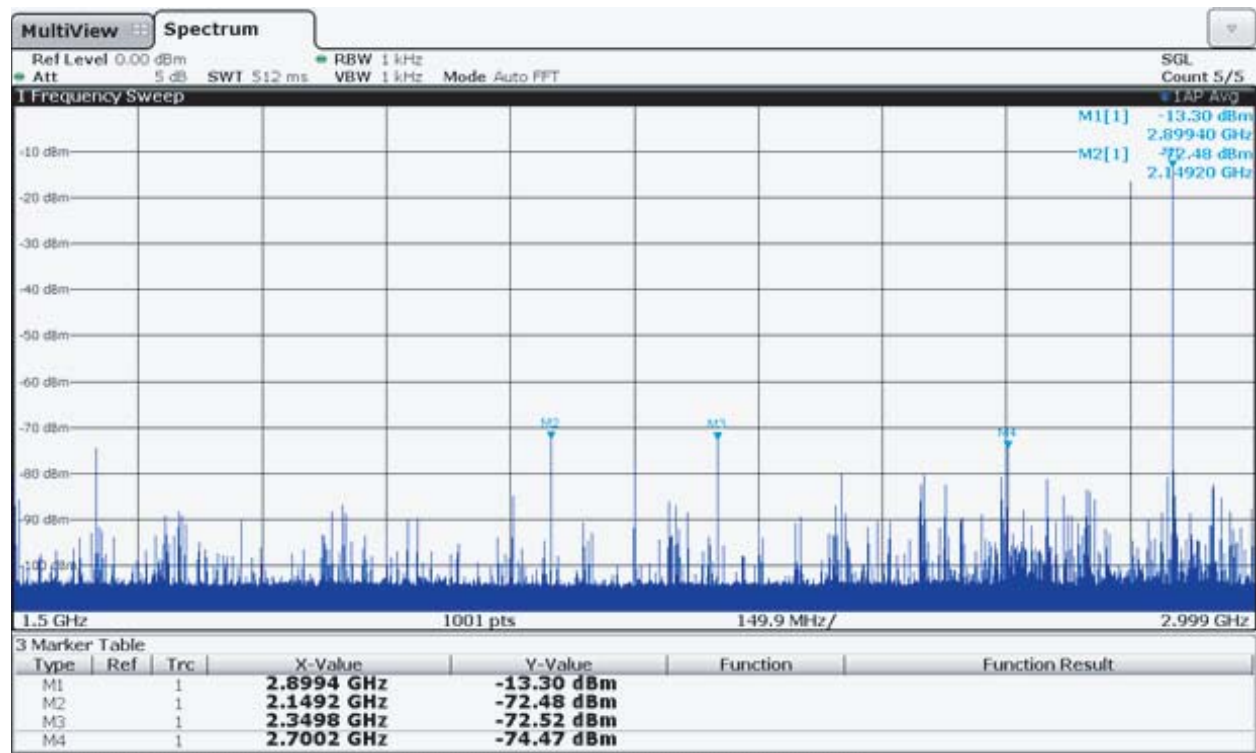


Figure 7-22. Typical SFDR spectrum in NRTZ mode. Fout = 1800MHz (2nd Nyquist), MUX4:1, Fs = 3Gsps. SFDR = 61dBc

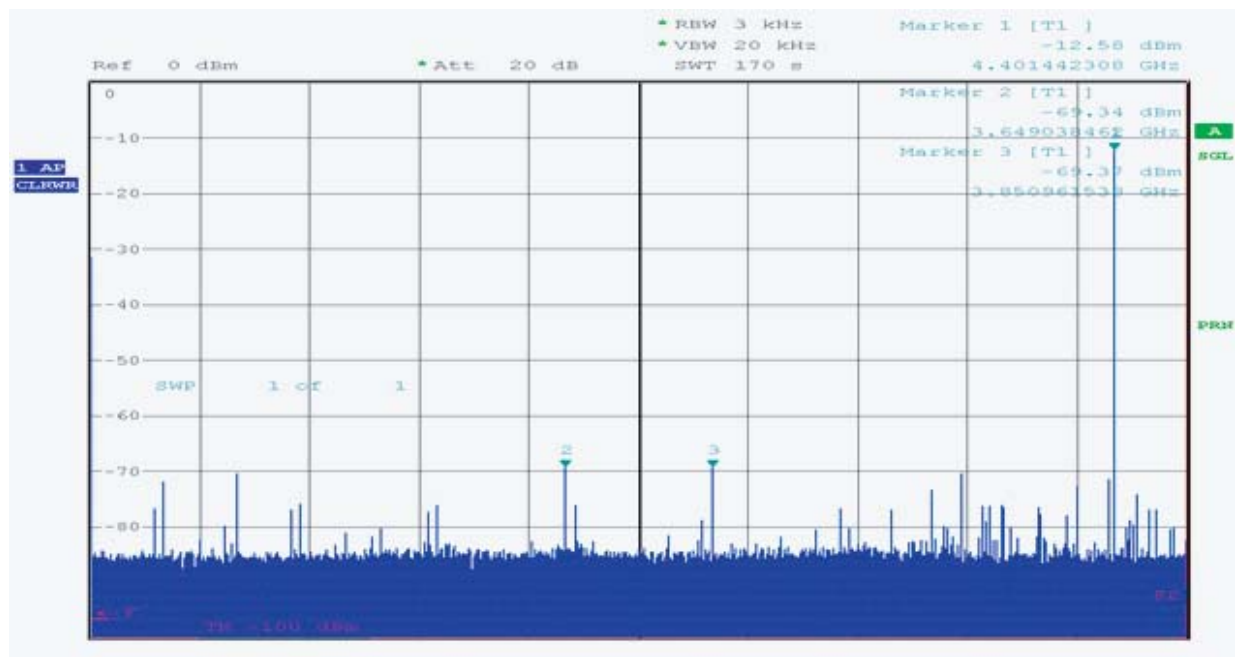




**Figure 7-23.** Typical SFDR spectrum in RTZ mode. Fout = 2900MHz (2nd Nyquist), MUX4:1, Fs = 3Gsp/s. SFDR = 59dBc.



**Figure 7-24.** Typical SFDR spectrum in RF mode. Fout = 4400MHz (3rd Nyquist), MUX4:1, Fs = 3Gsp/s. SFDR = 56 dBc



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# EV12DS130BZP

## 7.2.4 Multi Tone Measurements

A five tones pattern (400 MHz, 500 MHz, 600 MHz, 700 MHz and 800 MHz) is applied to the DAC operating at 3 Gps and results are observed in the 2<sup>nd</sup>, 3<sup>rd</sup>, 4<sup>th</sup> and 5<sup>th</sup> Nyquist zones.

Results are given in the most relevant mode considering the Nyquist zone observed.

**Figure 7-25.** Observation of the 2<sup>nd</sup> Nyquist Zone (Tones are pushed from 2.2 GHz to 2.6 GHz): NRTZ, RF and RTZ Modes

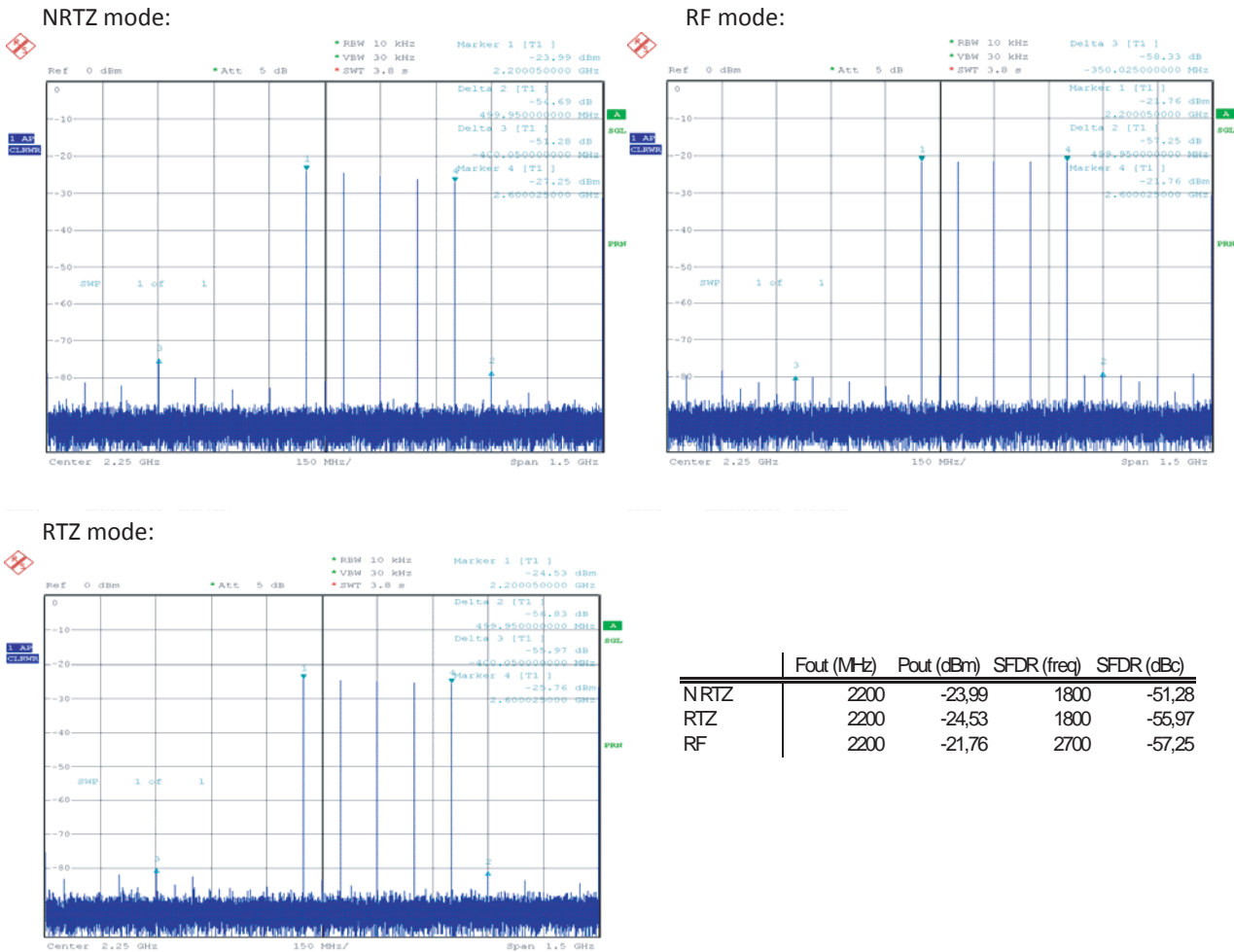
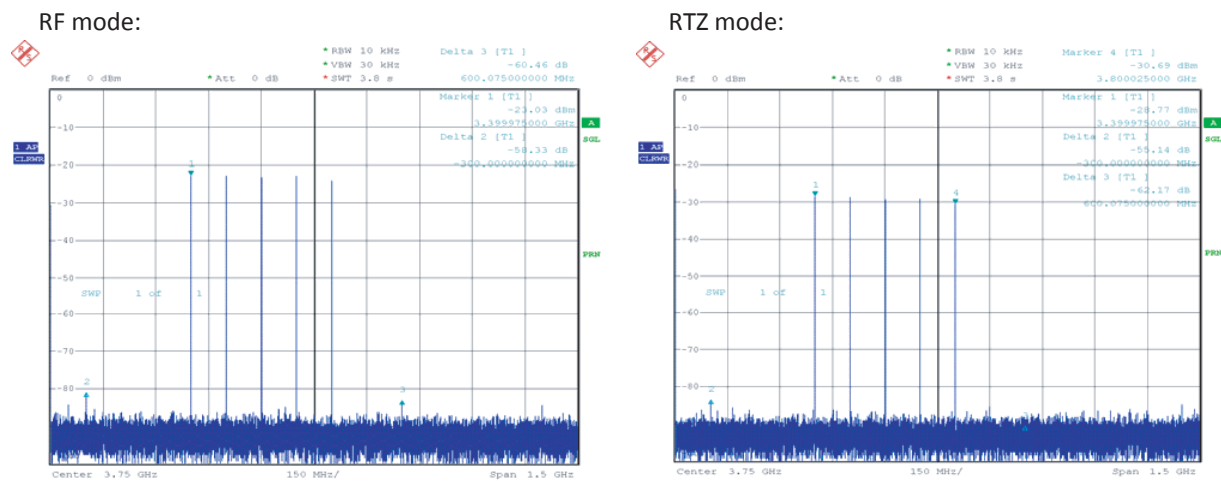




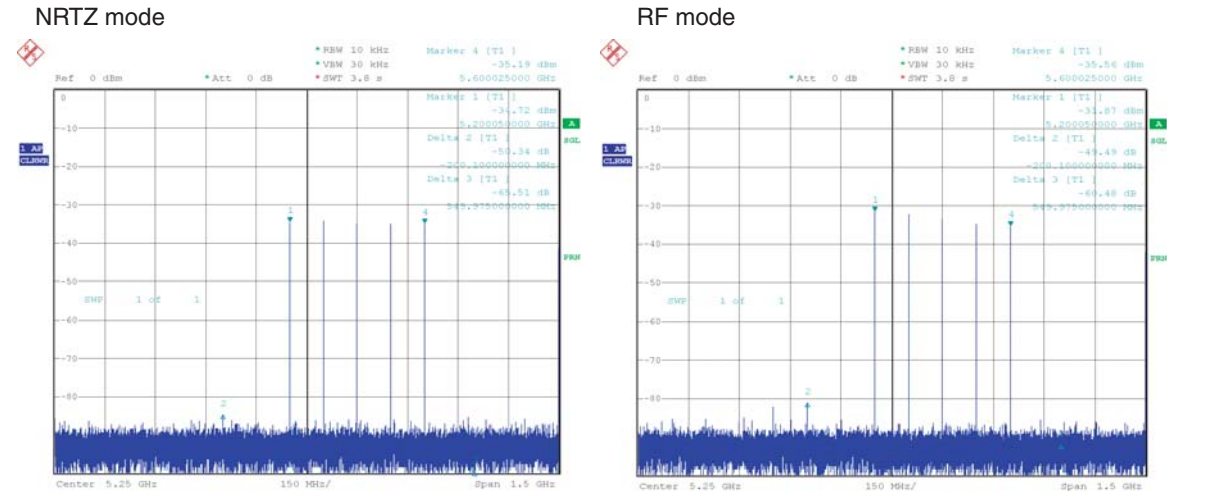
Figure 7-26. Observation of the 3<sup>rd</sup> Nyquist Zone (Tones are pushed from 3.4GHz to 3.8GHz): RF and RTZ Modes



	Fout (MHz)	Pout (dBm)	SFDR (freq)	SFDR (dBc)
NRTZ	3400	-39.43	4000	-44.48
RTZ	3400	-28.77	3100	-55.14
RF	3400	-23.03	3100	-58.33

NRTZ performances are degraded because of the sinc attenuation (first notch in the first half of the 3<sup>rd</sup> Nyquist zone).

Figure 7-27. Observation of the 4<sup>th</sup> Nyquist Zone (Tones are pushed from 5.2 GHz to 5.6 GHz): NRTZ and RF Modes



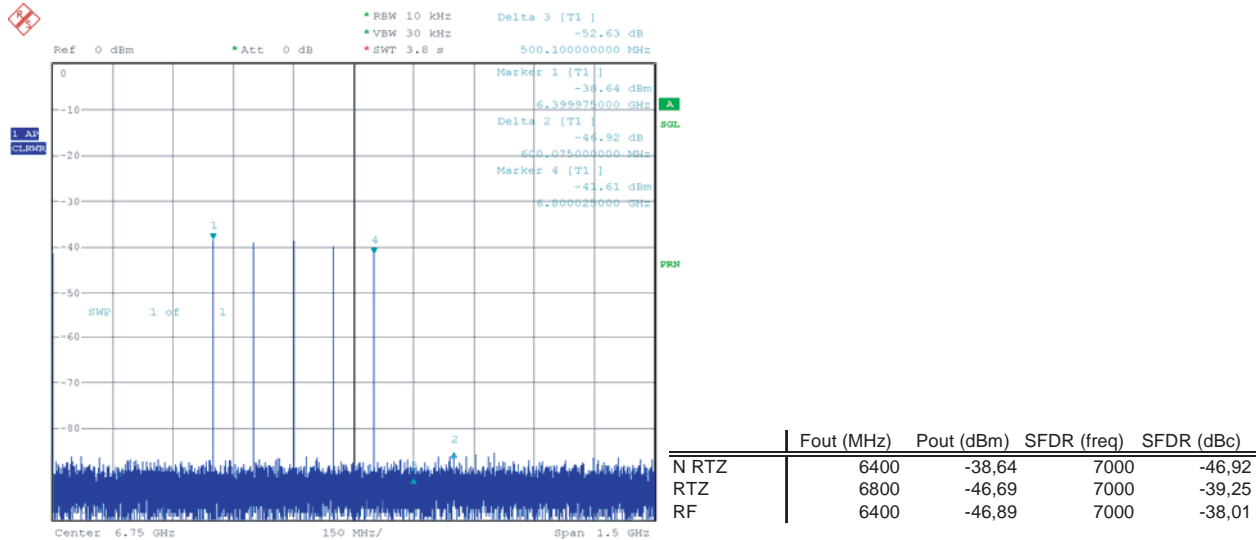
	Fout (MHz)	Pout (dBm)	SFDR (freq)	SFDR (dBc)
NRTZ	5200	-34.72	5000	-50.34
RTZ	5200	-40.37	4700	-45
RF	5200	-31.87	4700	-49.49

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RTZ mode is degraded because of the sinc attenuation (first notch at the end of the 4<sup>th</sup> Nyquist zone).  
RF mode offers significantly more power than RTZ mode, this is why we still have acceptable performances.

NRTZ operation is possible because the 4<sup>th</sup> Nyquist zone is fully included in the secondary spectral lobe.

Figure 7-28. Observation of the 5<sup>th</sup> Nyquist Zone (Tones are pushed from 6.4 GHz to 6.8 GHz): NRTZ Mode



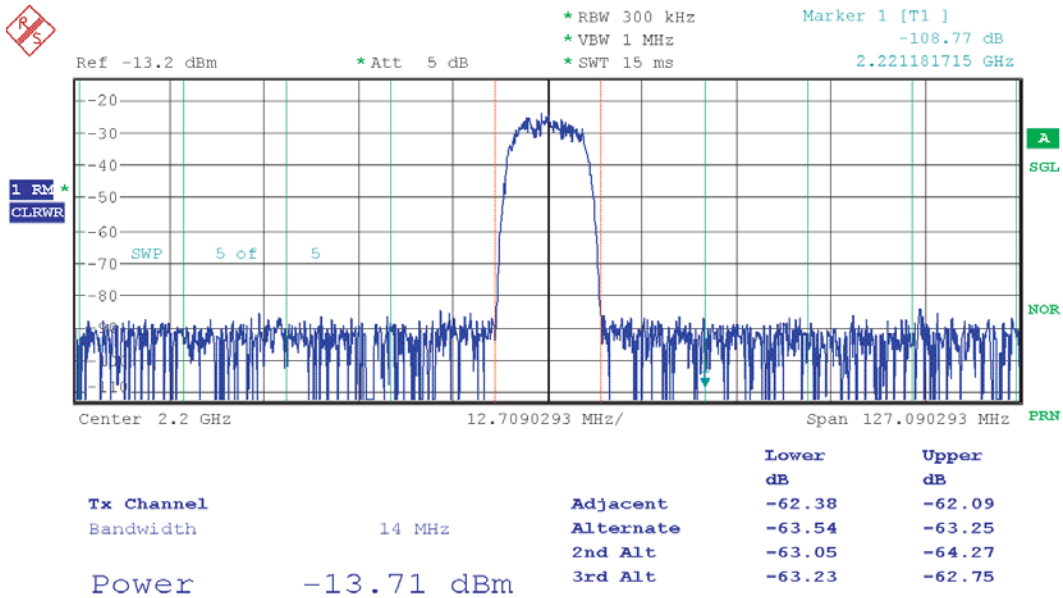
NRTZ mode is still usable in the 5<sup>th</sup> Nyquist zone (SFDR in excess of 46 dB).

7.2.5 Direct Microwave Synthesis Capability Measurements: ACPR

Measurements given hereafter are performed on the DAC at 3 Gsps with a 10 MHz wide QPSK pattern centered on 800 MHz.

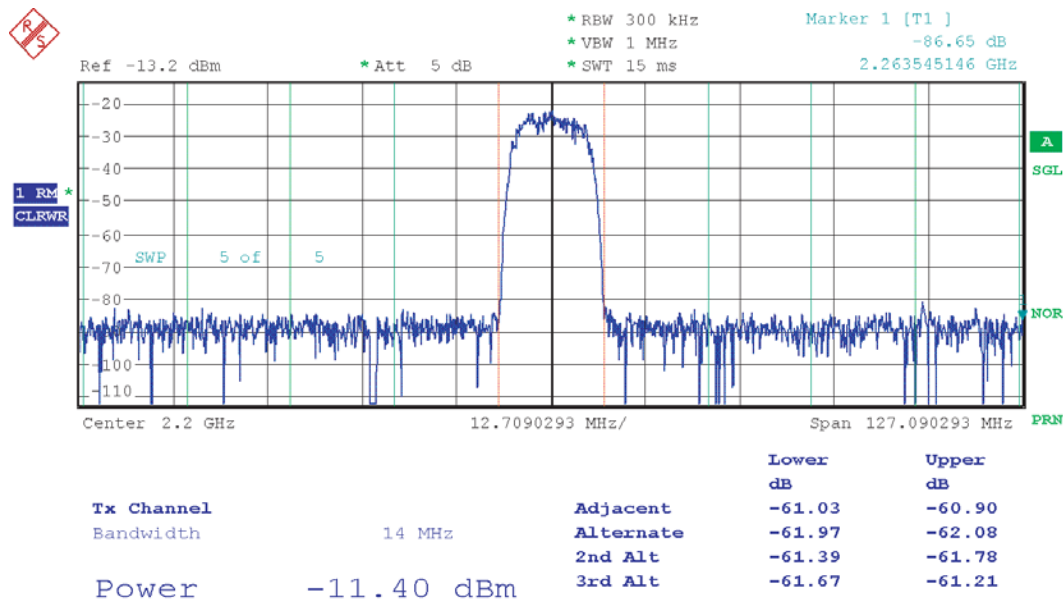
Results are observed in 2<sup>nd</sup>, 3<sup>rd</sup>, 4<sup>th</sup> and 5<sup>th</sup> Nyquist zones and are given only for the most relevant modes (that is RF and/or NRTZ modes).

Figure 7-29. NRTZ Mode, 2<sup>nd</sup> Nyquist: Center Frequency is pushed to 3 GHz – 800 MHz = 2.2 GHz



ACPR is in excess of 62 dB. DMWS capability is proven for second Nyquist in NRTZ mode.

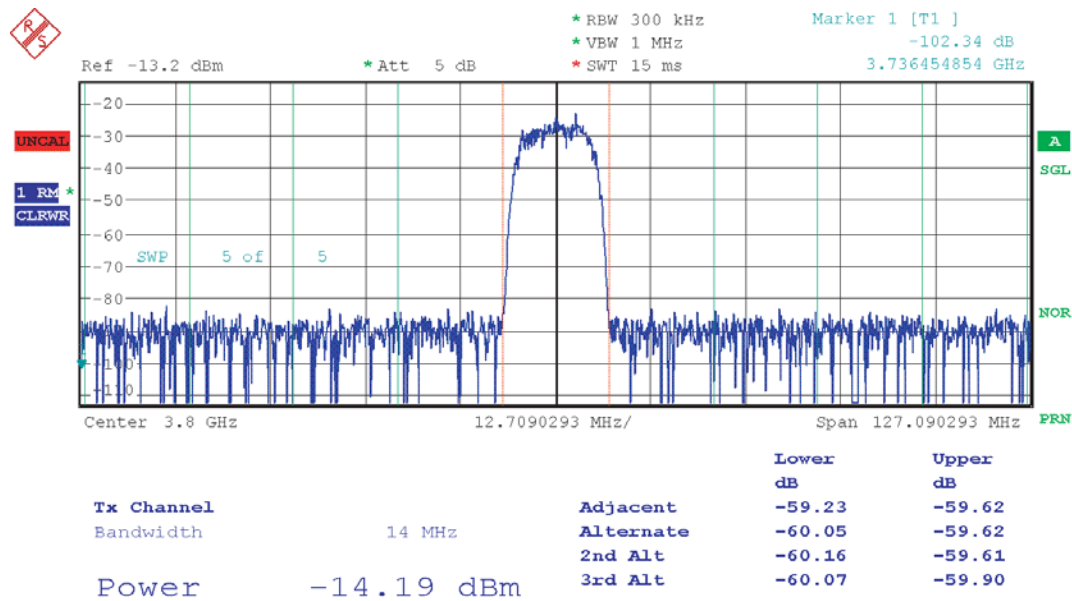
Figure 7-30. RF Mode, 2<sup>nd</sup> Nyquist: Center Frequency is pushed to 3 GHz – 800 MHz = 2.2 GHz



ACPR is in excess of 60 dB. DMWS capability is proven for the second Nyquist zone in RF mode with slightly reduced dynamic range regarding NRTZ mode but with increased output power.

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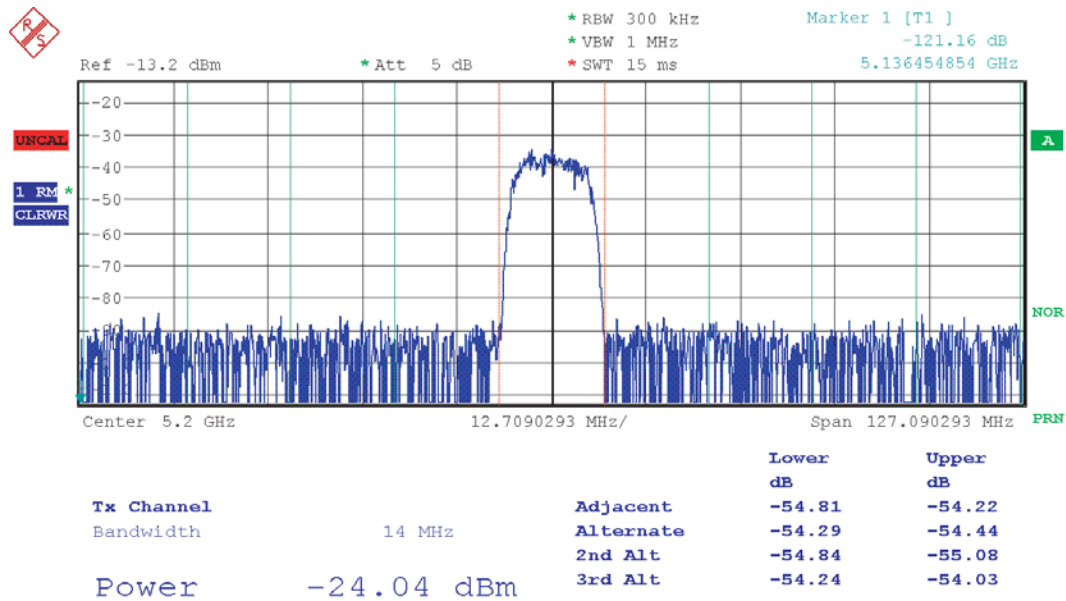
Figure 7-31. RF Mode, 3<sup>rd</sup> Nyquist Zone: Center Frequency is pushed to 3 GHz+ 800 MHz = 3.8 GHz



ACPR is in excess of 59 dB. DMWS capability is proven for the third Nyquist zone in RF mode.

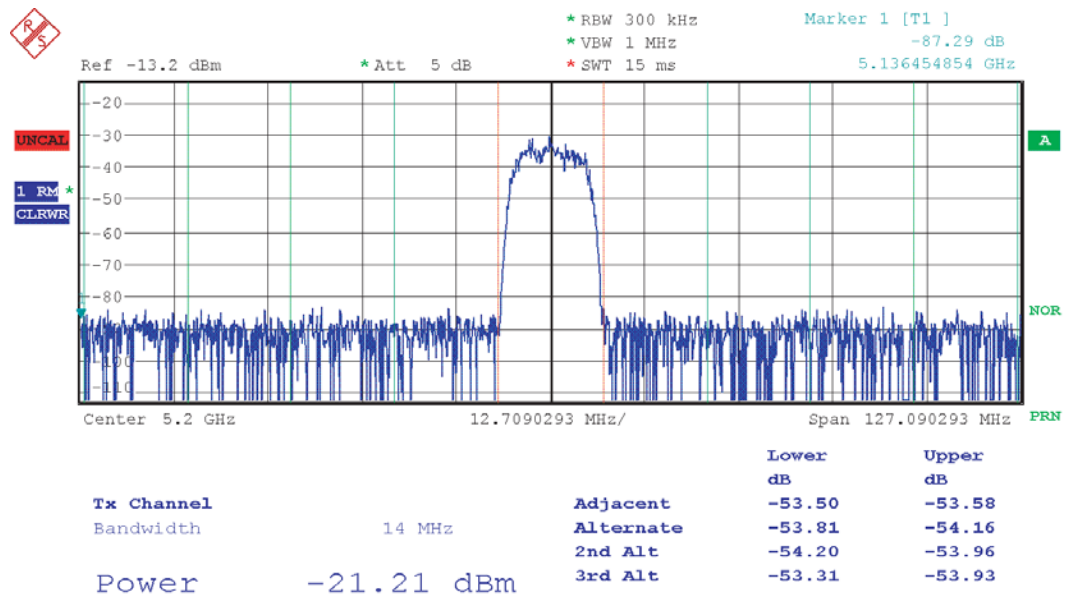
Note: due to the notch of available Pout near the middle of the third Nyquist zone, the NRTZ mode is not relevant for DMWS in the third Nyquist zone.

Figure 7-32. NRTZ Mode, 4<sup>th</sup> Nyquist Zone: Center Frequency is pushed to 6 GHz – 800 MHz = 5.2 GHz



ACPR is in excess of 54 dB. DMWS capability is proven for the fourth Nyquist zone in NRTZ mode.

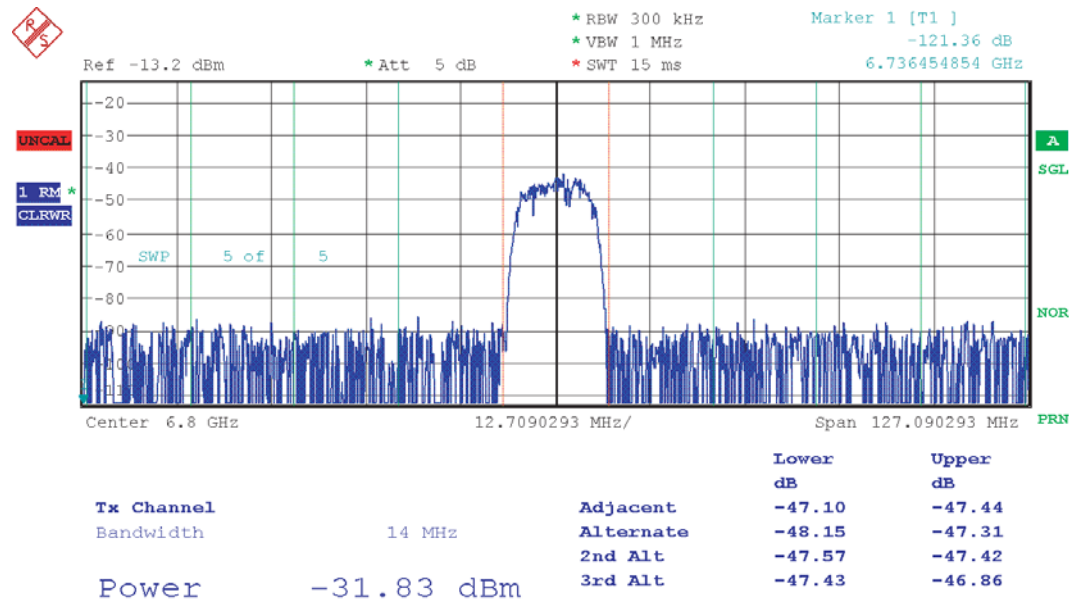
Figure 7-33. RF Mode, 4<sup>th</sup> Nyquist Zone: Center Frequency is pushed to 6 GHz – 800 MHz = 5.2 GHz



ACPR is in excess of 53 dB. DMWS capability is proven for the fourth Nyquist zone in RF mode.

Note due to a notch of available Pout near the end of the 4<sup>th</sup> Nyquist zone in RF output mode, for DMWS beyond middle of 4<sup>th</sup> Nyquist zone it is recommended to use the NRTZ output mode instead of the RF output mode.

Figure 7-34. NRTZ Mode, 5<sup>th</sup> Nyquist Zone: Center Frequency is pushed to 6 GHz + 800 MHz = 6.8 GHz



ACPR is still in excess of 47 dB. DMWS capability is proven for the fifth Nyquist zone in NRTZ mode with reduced available dynamic range.

# EV12DS130AZP

# EV12DS130BZP

## 7.2.6 DOCSIS v3.0 Capability Measurements

Measurements hereafter have been carried out on a soldered device EV12DS130A/B, in NRTZ mode at 3 GSps.

Note: Results illustrated hereafter (spectrum and zoom on notch) come from measurement on a EV12DS130A/B device (CI-CGA255 package). Measurements have been carried out using the ACP treatment of the spectrum analyzer Rhode & Schwarz FSU8, in RMS detection mode.

Figure 7-35. ACPR 1 Channel Centered on 300 MHz, Output Mode NRTZ

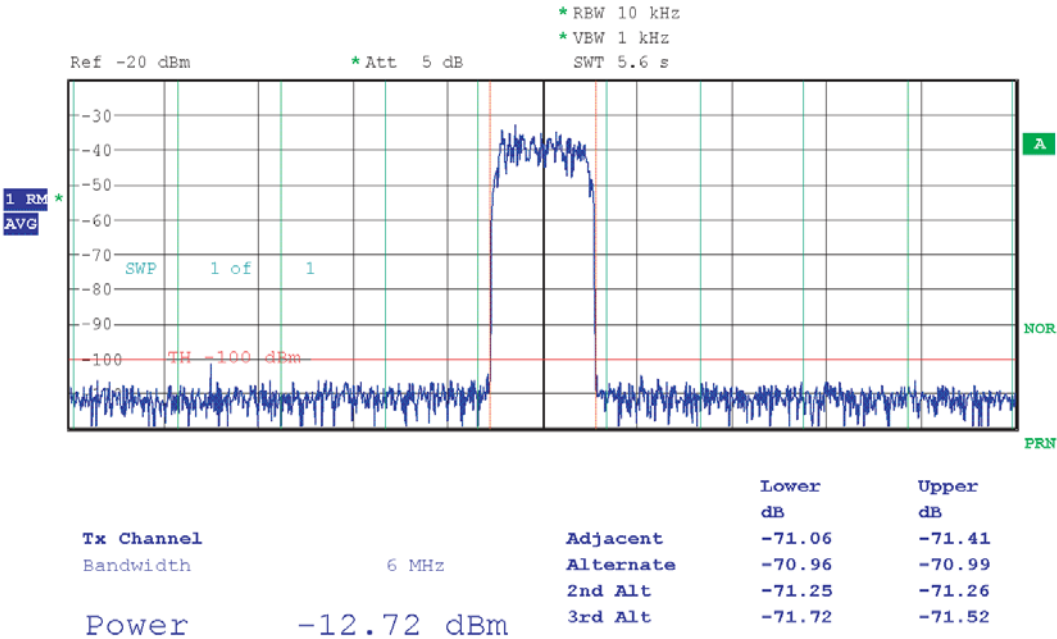


Figure 7-36. ACPR 1 Channel Centered on 900 MHz, Output Mode NRTZ

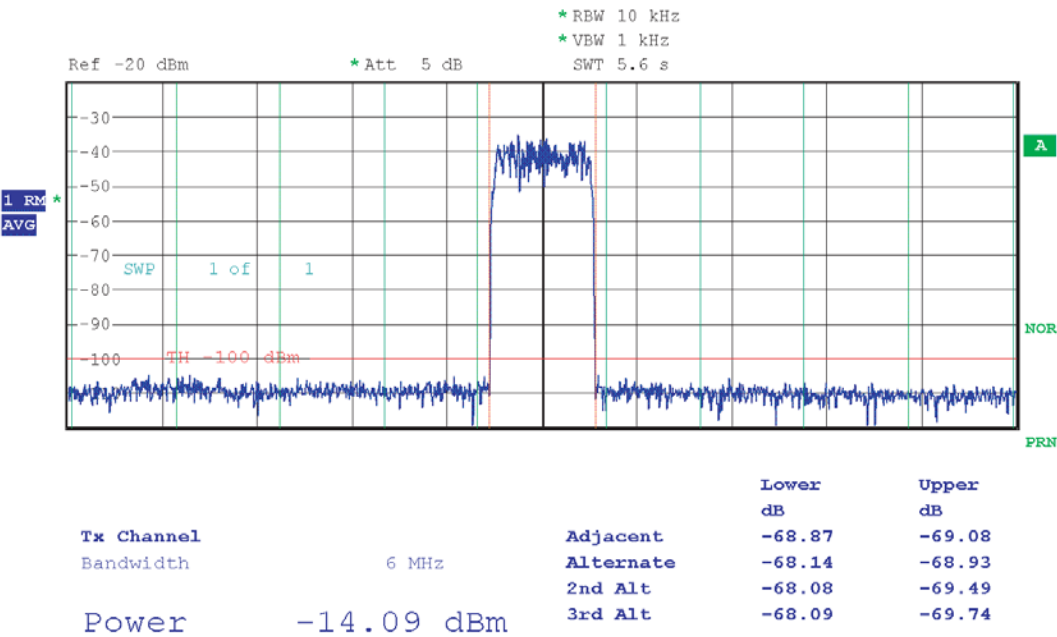


Figure 7-37. ACPR 1 channel centered on 300 MHz, Output Mode NRTZ

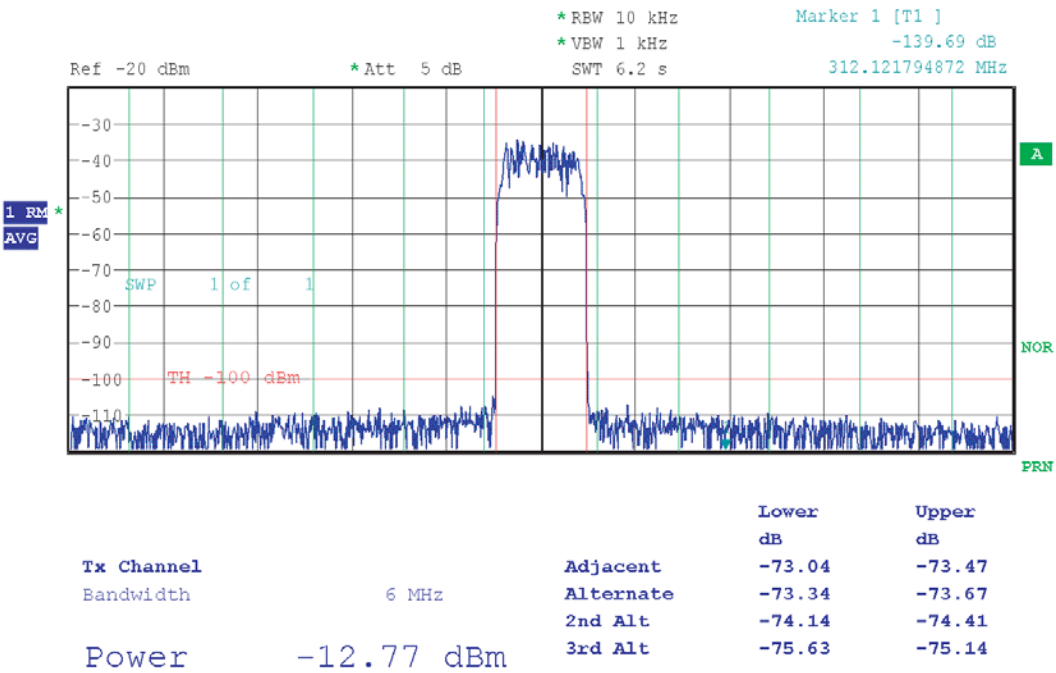
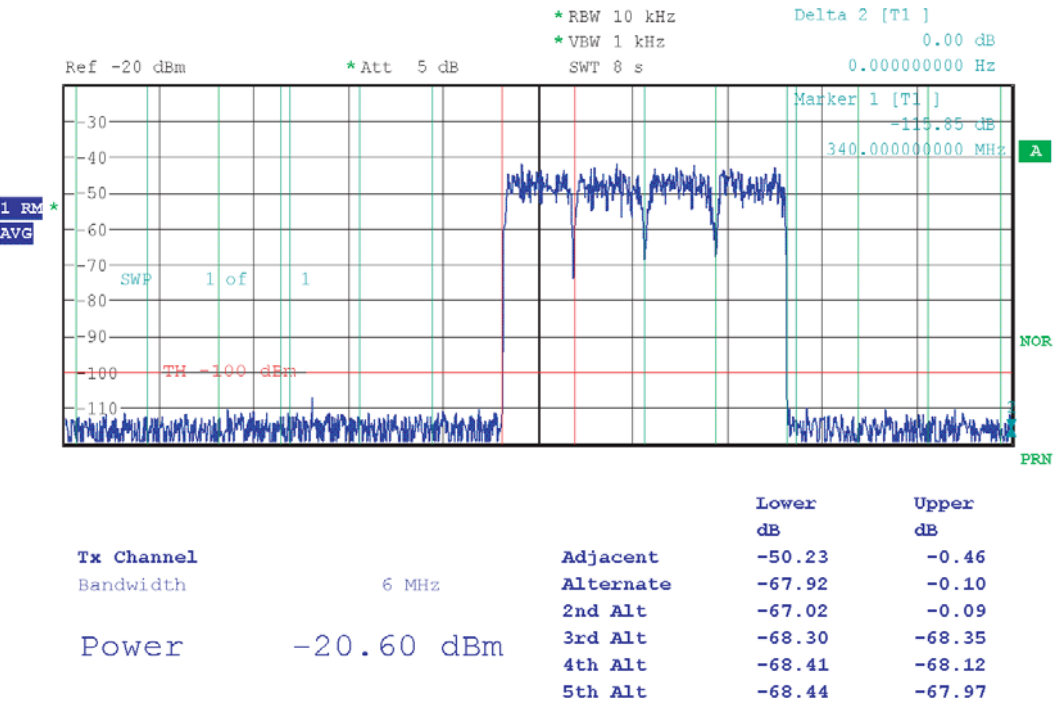


Figure 7-38. ACPR 4 Channels Centered on 300 MHz, Output Mode NRTZ





EV12DS130AZP  
EV12DS130BZP

Figure 7-39. ACPR 1 Channel Centered on 900 MHz, Output Mode NRTZ

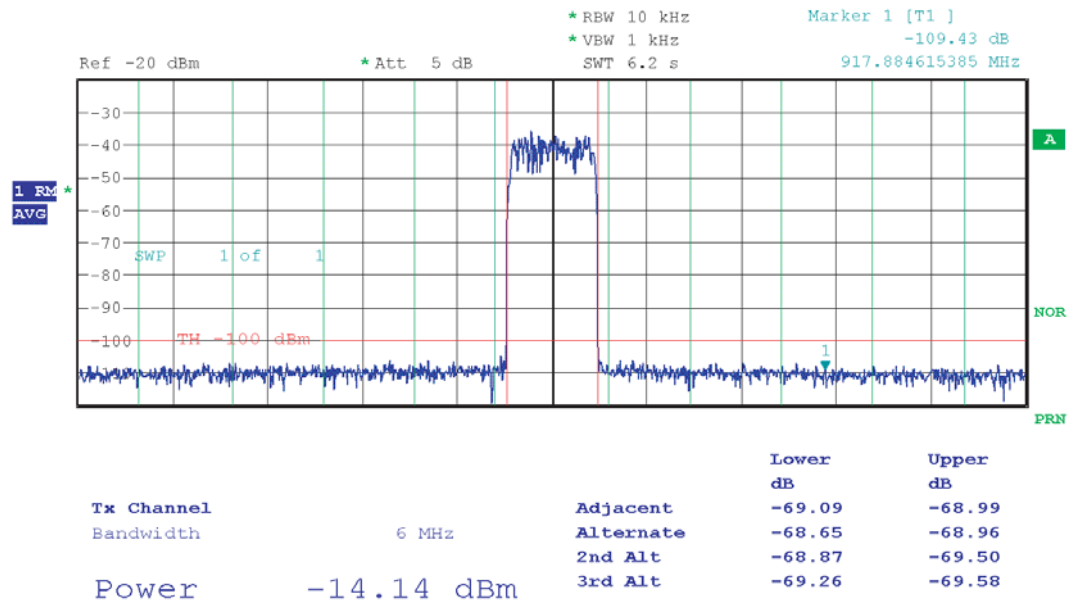
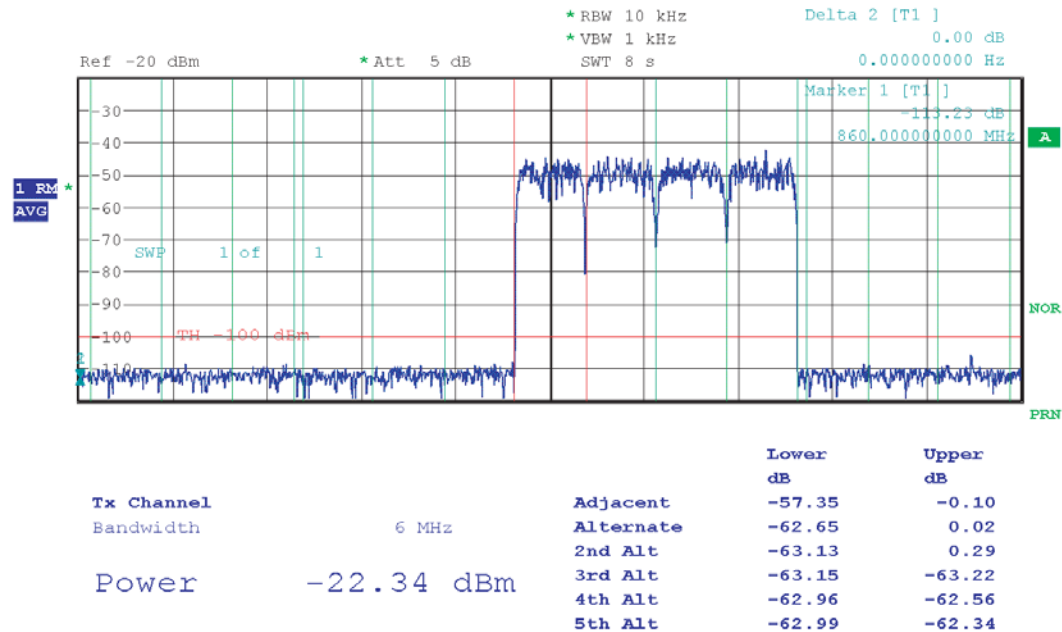


Figure 7-40. ACPR 4 Channels Centered on 900 MHz, Output Mode NRTZ





7.2.7 NPR Performance

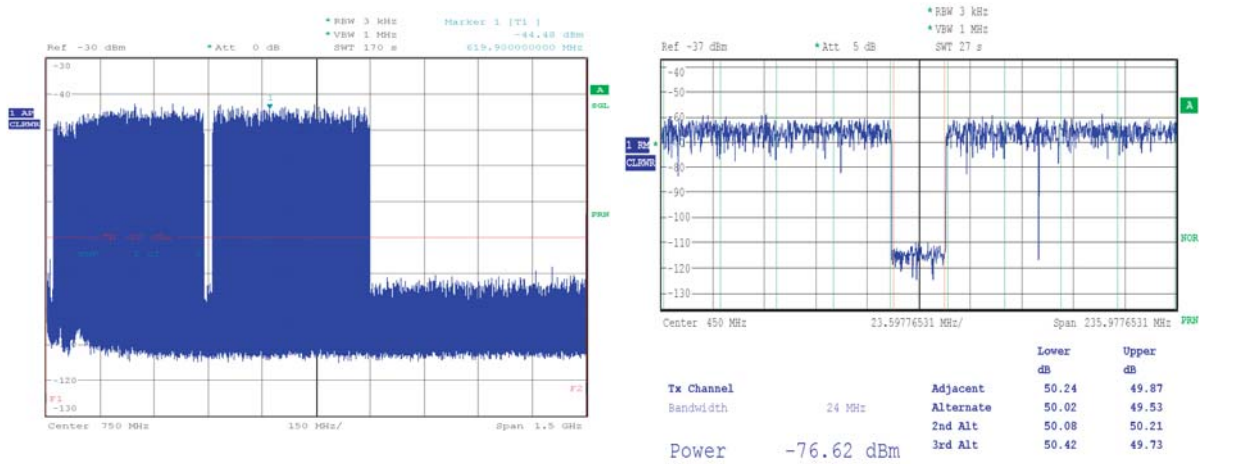
NPR measurements have been carried out at optimum loading factor (LF) for a 12 bit DAC, that is -14 dBFS, with the DAC operating at 3 Gsps.

SNR can be computed from SNR measurement with the formula:  $SNR_{[dB]} = NPR_{[dB]} + ILF_{[dB]} - 3$ .

ENOB can be computed with the formula:  $ENOB = (SNR_{[dB]} - 1.76) / 6.02$ .

Note: Results illustrated hereafter (spectrum and zoom on notch) come from measurement on a EV12DS130A/B device (CI-CGA255 package). Measurements have been carried out using the ACP treatment of the spectrum analyzer Rhode & Schwarz FSU8, in RMS detection mode.

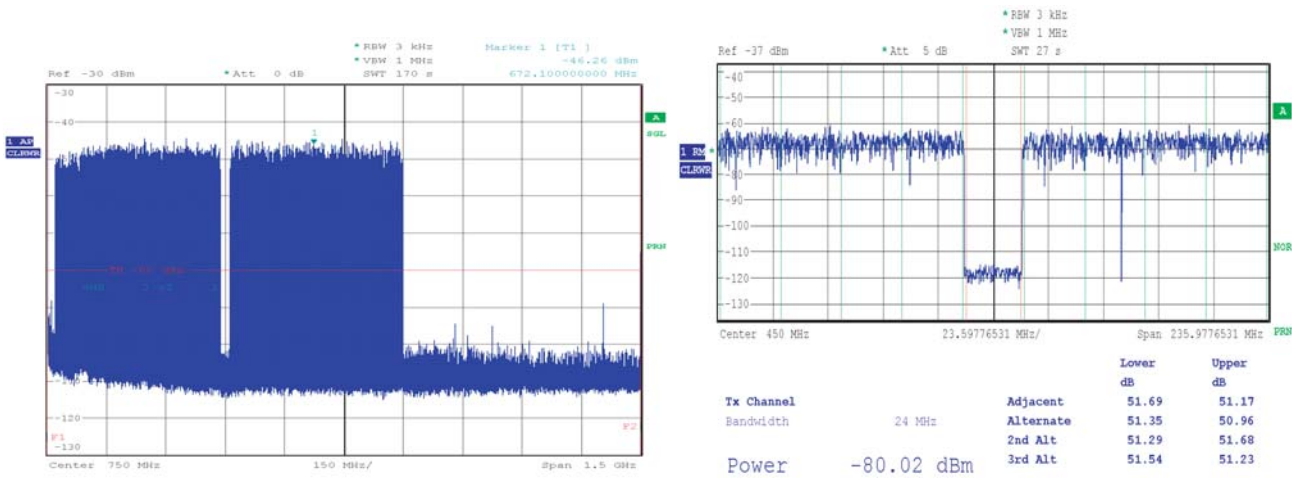
Figure 7-41. NPR in First Nyquist Zone, 20 MHz to 900 MHz Noise Pattern with a 25 MHz Notch Centered on 450 MHz, NRZ mode



Measured average NPR: 50.02 dB, therefore SNR = 61.02 dB and ENOB = 9.84 bit

Effects at low frequency are due to balun and pattern.

Figure 7-42. NPR in First Nyquist Zone, 20 MHz to 900 MHz Noise Pattern with a 25 MHz Notch Centered on 450 MHz, NRTZ Mode

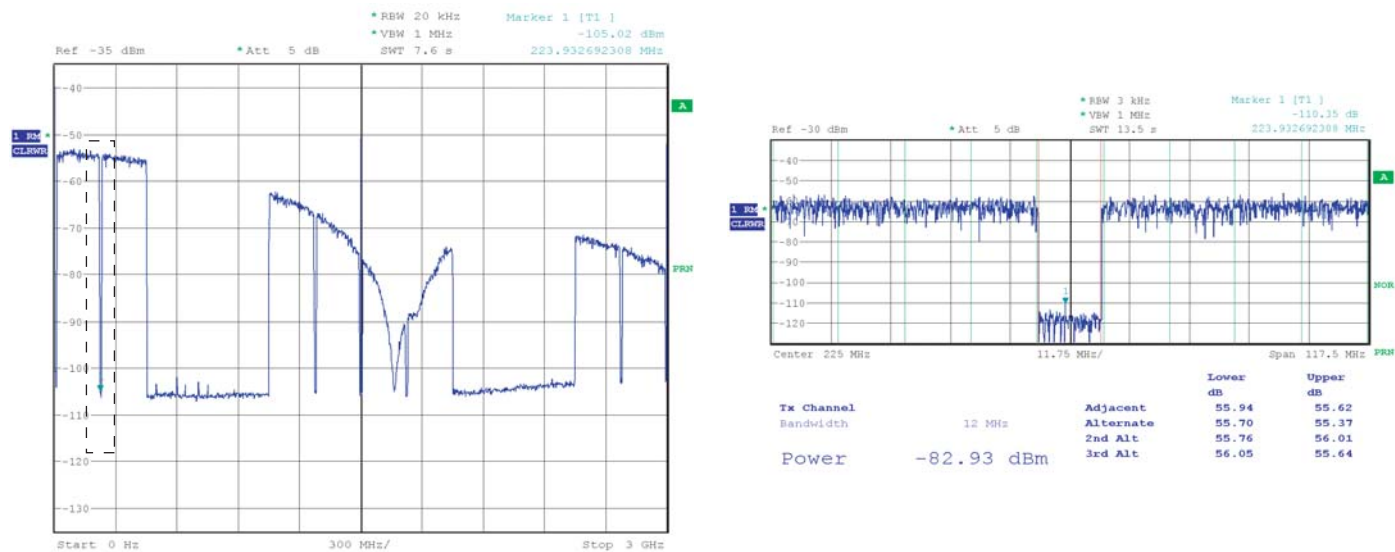


Measured average NPR: 51.36 dB, therefore SNR = 62.36 dB and ENOB = 10.07 bit.

Effects at low frequency are due to balun and pattern.

EV12DS130AZP  
EV12DS130BZP

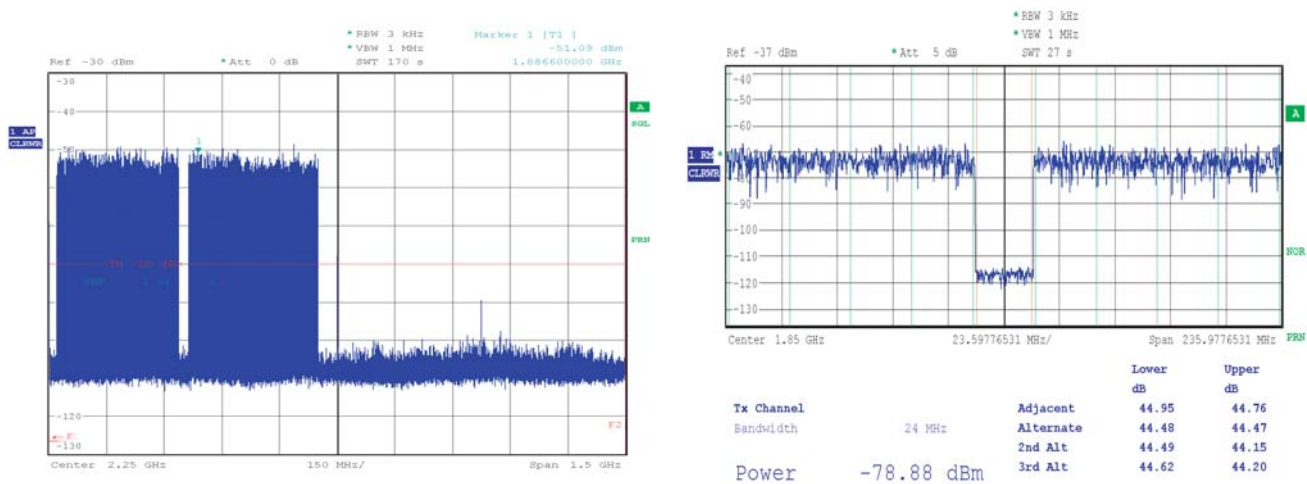
Figure 7-43. NPR in First Nyquist Zone, 10 MHz to 450 MHz Noise Pattern with a 12.5 MHz Notch centered on 225 MHz, NRTZ Mode at Fs = 1.5 Gsps



Measured average NPR: 55.7 dB, therefore SNR = 66.7 dB and ENOB = 10.8 bit.

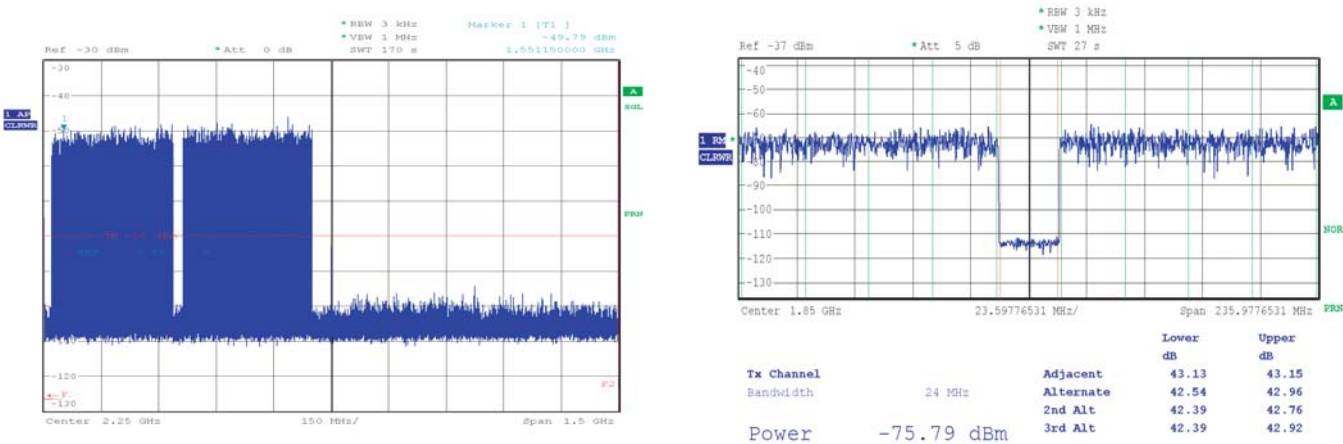
Effects at low frequency are due to balun and pattern.

Figure 7-44. NPR in second Nyquist Zone, 1520 MHz to 2200 MHz Noise Pattern with a 25 MHz Notch centered on 1850 MHz, RTZ mode



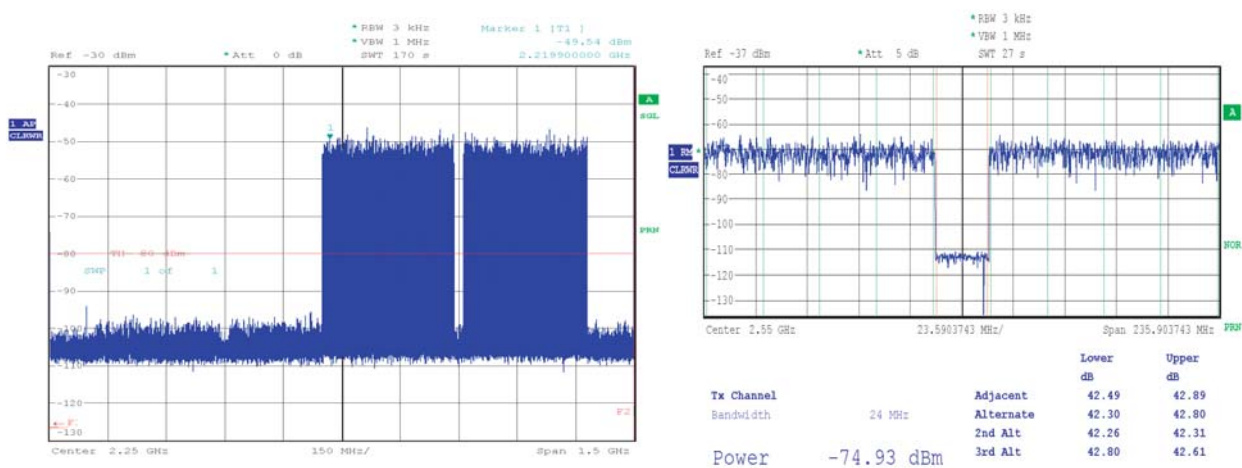
Measured average NPR: 44.6 dB, therefore SNR = 55.6 dB and ENOB = 8.94 bit

**Figure 7-45.** NPR in second Nyquist Zone, 1520 MHz to 2200 MHz noise pattern with a 25 MHz notch centered on 1850 MHz, RF Mode



Measured average NPR: 42.78 dB, therefore SNR = 53.78 dB and ENOB = 8.64 bit

**Figure 7-46.** NPR in second Nyquist Zone, 2200 MHz to 2880 MHz Noise Pattern with a 25 MHz Notch centered on 2550 MHz, RF Mode

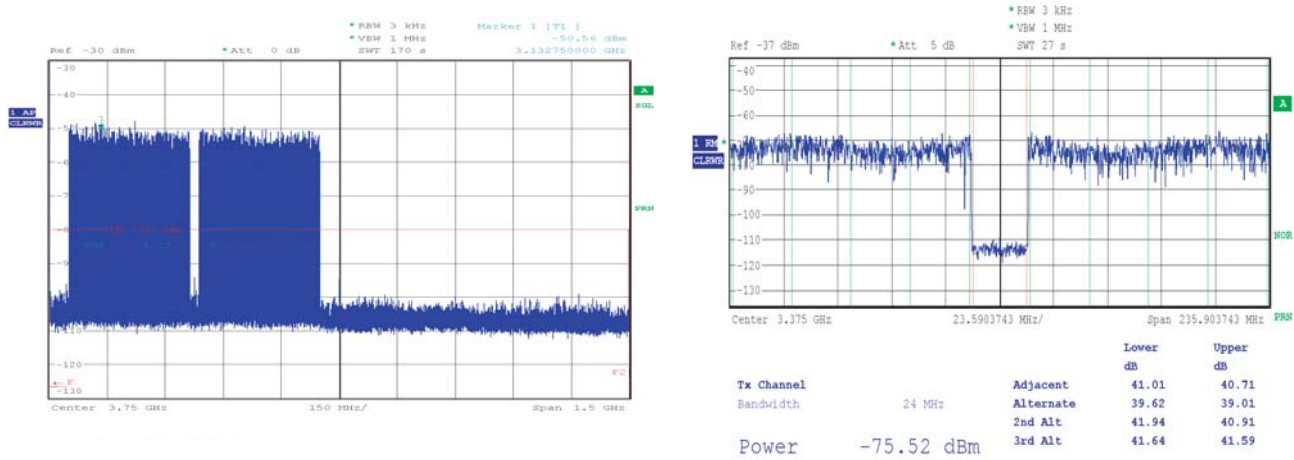


Measured average NPR: 42.56 dB, therefore SNR = 53.56 dB and ENOB = 8.6 bit.

# EV12DS130AZP

# EV12DS130BZP

Figure 7-47. NPR in Third Nyquist Zone, 3050 MHz to 3700 MHz Noise Pattern with a 25 MHz Notch Centered on 3375 MHz, RF Mode

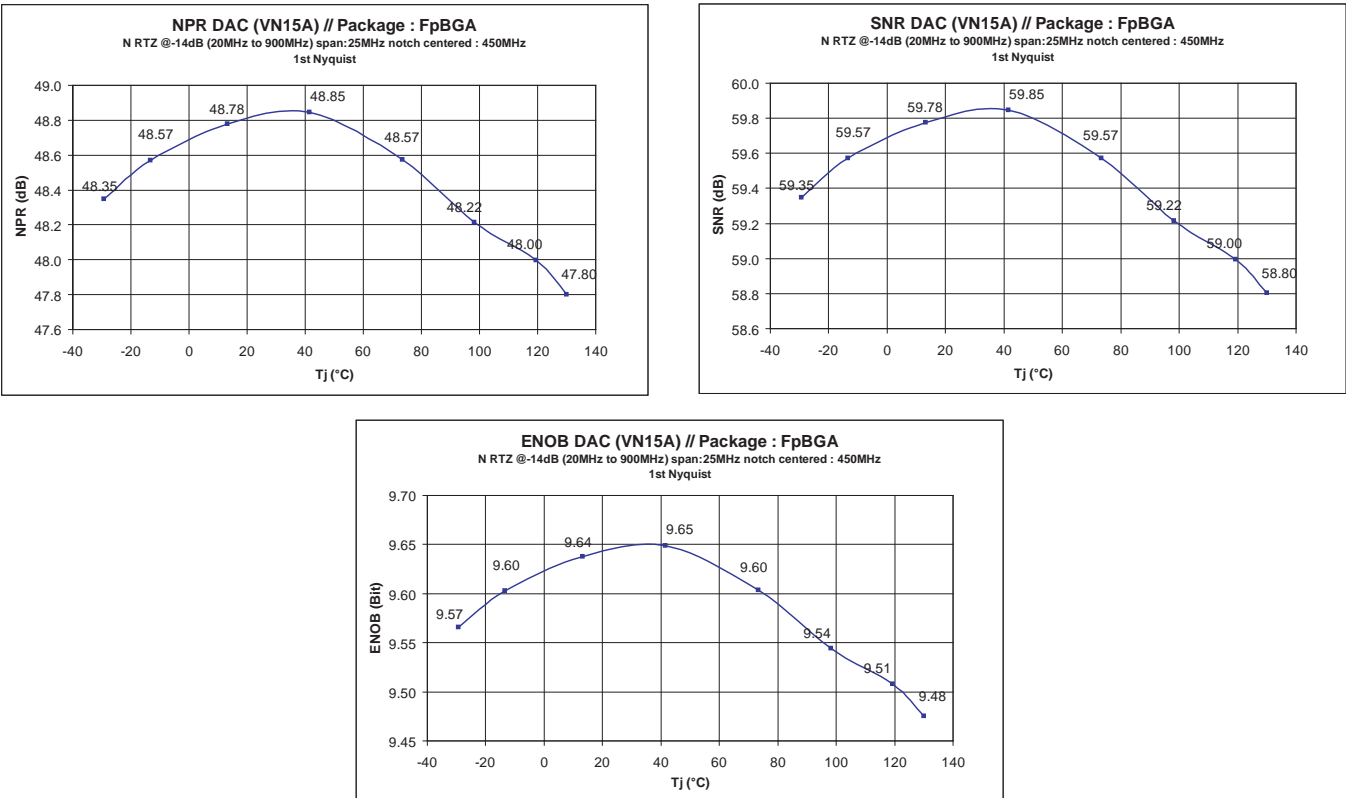


Measured average NPR: 40.08 dB, therefore SNR = 51.08 dB and ENOB = 8.19 bit

The following figures reflect the stability of NPR in first Nyquist in NRTZ mode (and therefore SNR and ENOB) versus temperature.

Measurements have been carried out at nominal power supply on an EV12DS130A/B, at 3 Gsps, with the FSU8 spectrum analyzer in RMS detection mode.

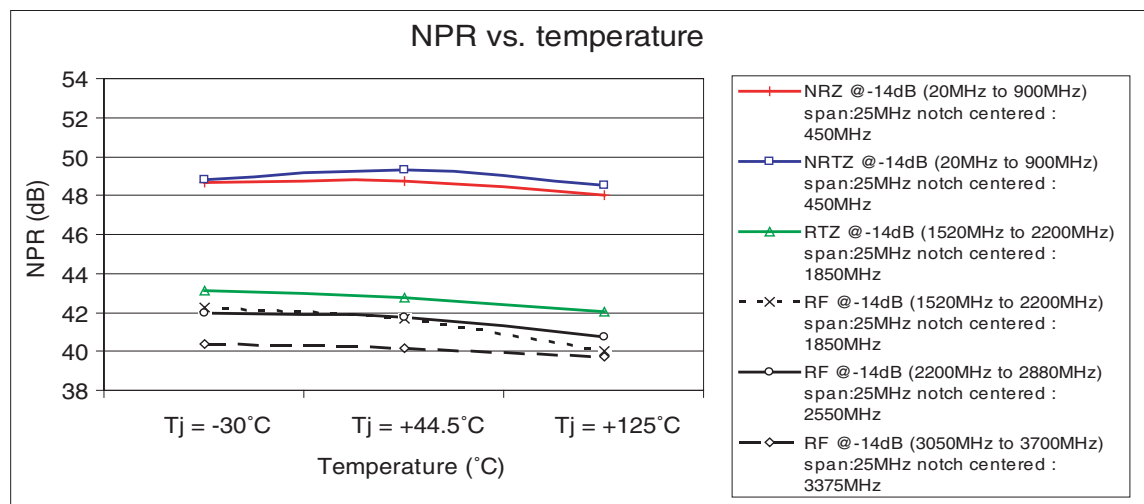
Figure 7-48. Drift of NPR and Associated SNR and ENOB in First Nyquist in NRTZ Mode from  $T_j = -30^{\circ}\text{C}$  to  $T_j = 125^{\circ}\text{C}$



Optimum is at  $T_j = 40^{\circ}\text{C}$ , degradation over temp is within 1 dB (or 0.15 effective bit).

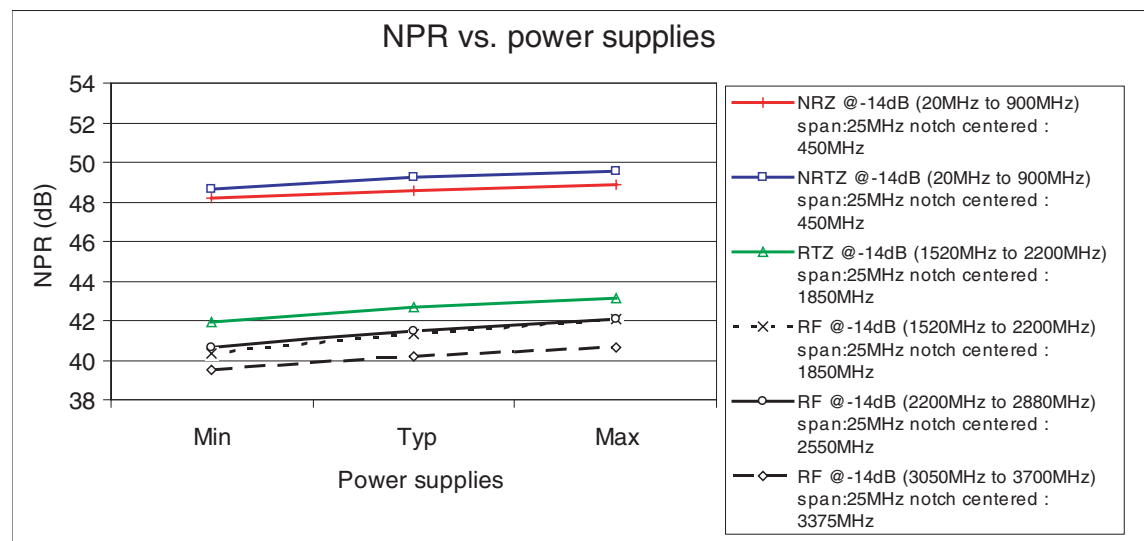
Measurements hereafter have been carried out on an EV12AS130AGS device at 3 Gsps, with the FSU8 spectrum analyzer in RMS detection mode.

**Figure 7-49.** Drift of NPR vs temperature in the 4 Output Modes at Nominal Supply



Conclusion: performances are stable in the four output modes against temperature.

**Figure 7-50.** NPR vs Power Supply Level in the 4 Output Modes at Room Temperature



Conditions: Typical, excepted: power supplies

Min:  $V_{CCA} = 4.75V // V_{CCA3} = V_{CCD} = 3.15V$

Typ:  $V_{CCA} = 5.0V // V_{CCA3} = V_{CCD} = 3.3V$

Max:  $V_{CCA} = 5.25V // V_{CCA3} = V_{CCD} = 3.45V$ .

Conclusion: performances are fairly stable against power supply.

Note: NPR performance at lower clock frequencies is affected by power up sequence. See application note 1087 for further details.

# EV12DS130AZP

# EV12DS130BZP

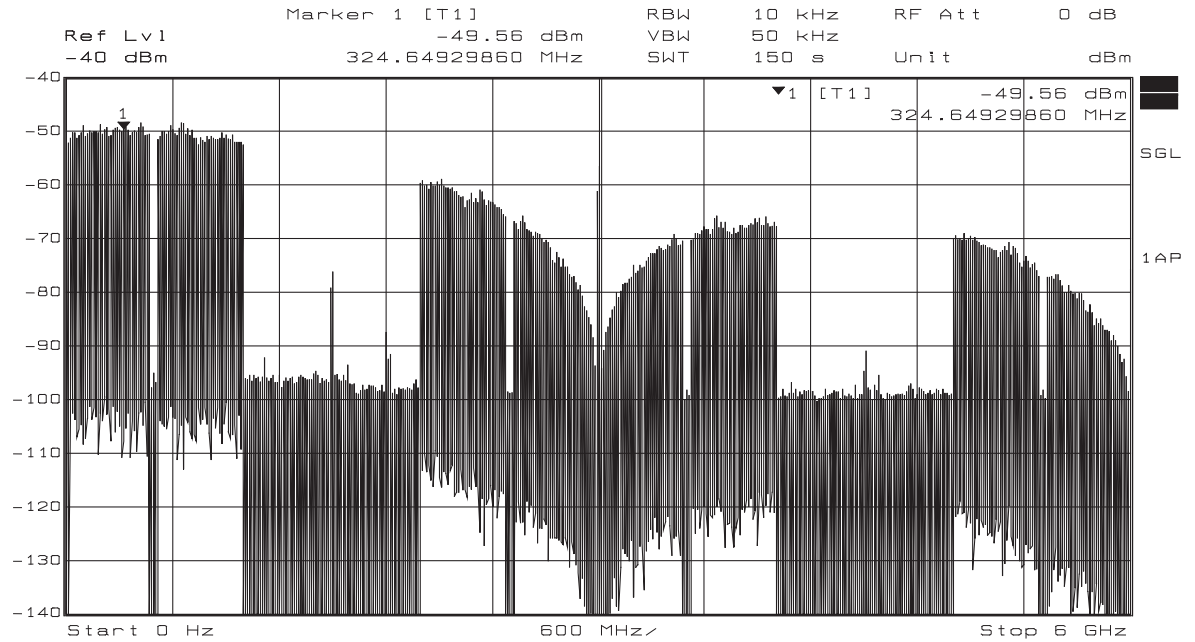
## 7.2.8 Spectrum over 4 Nyquist Zones in the Four Output Modes

Observation of a 1GHz broadband pattern with a 25 MHz notch centered on 500 MHz spectrum over 4 Nyquist zones at 3 Gsps (that is from DC to 6 GHz), measurements performed on an EV12DS130A/B device (CI-CGA 255 package, with an overall 6 GHz bandwidth limitation).

By periodisation of a sampled system each tone  $F_i$  of the pattern in the 1<sup>st</sup> Nyquist zone is duplicated as follows:

- 2<sup>nd</sup> Nyquist Zone: tone at  $F_{\text{clock}} - F_i$
- 3<sup>rd</sup> Nyquist Zone: tone at  $F_{\text{clock}} + F_i$
- 4<sup>th</sup> Nyquist Zone: tone at  $2 \cdot F_{\text{clock}} - F_i$

**Figure 7-51.** Spectrum over 4 Nyquist Zones at 3 Gsps in NRZ Output Mode



First Zero of the sinc() function is at  $F_{\text{clock}}$ .



Figure 7-52. Spectrum over 4 Nyquist Zones at 3 Gps in NRTZ Output Mode

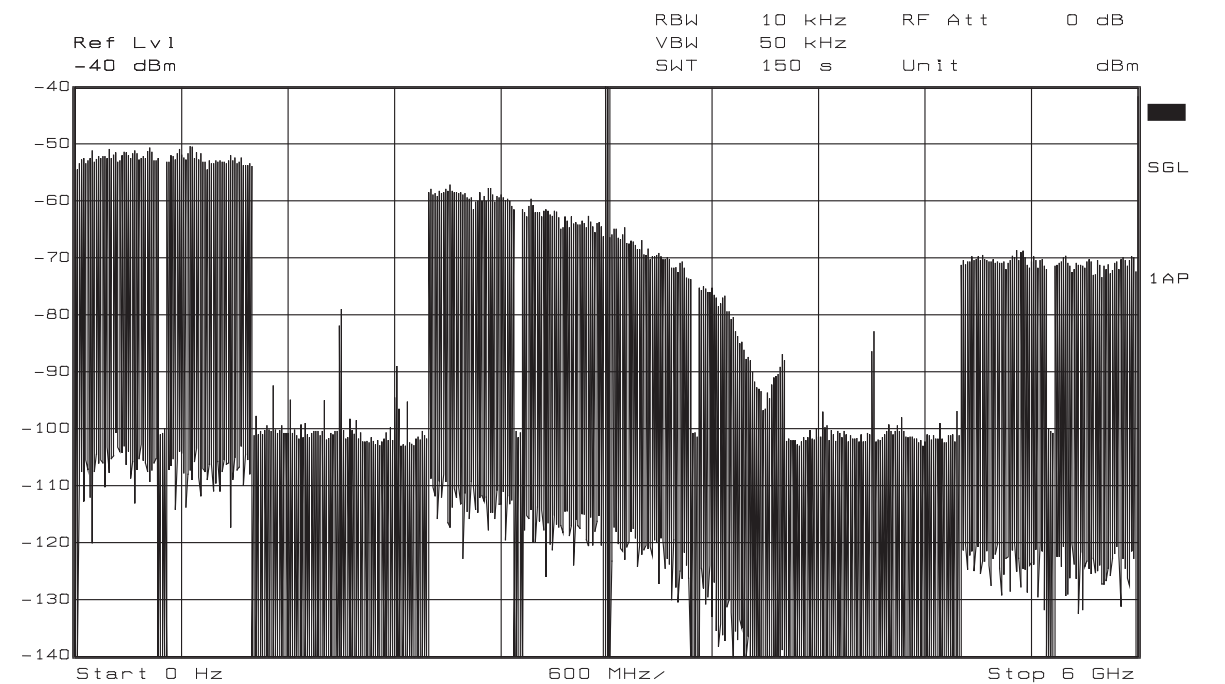
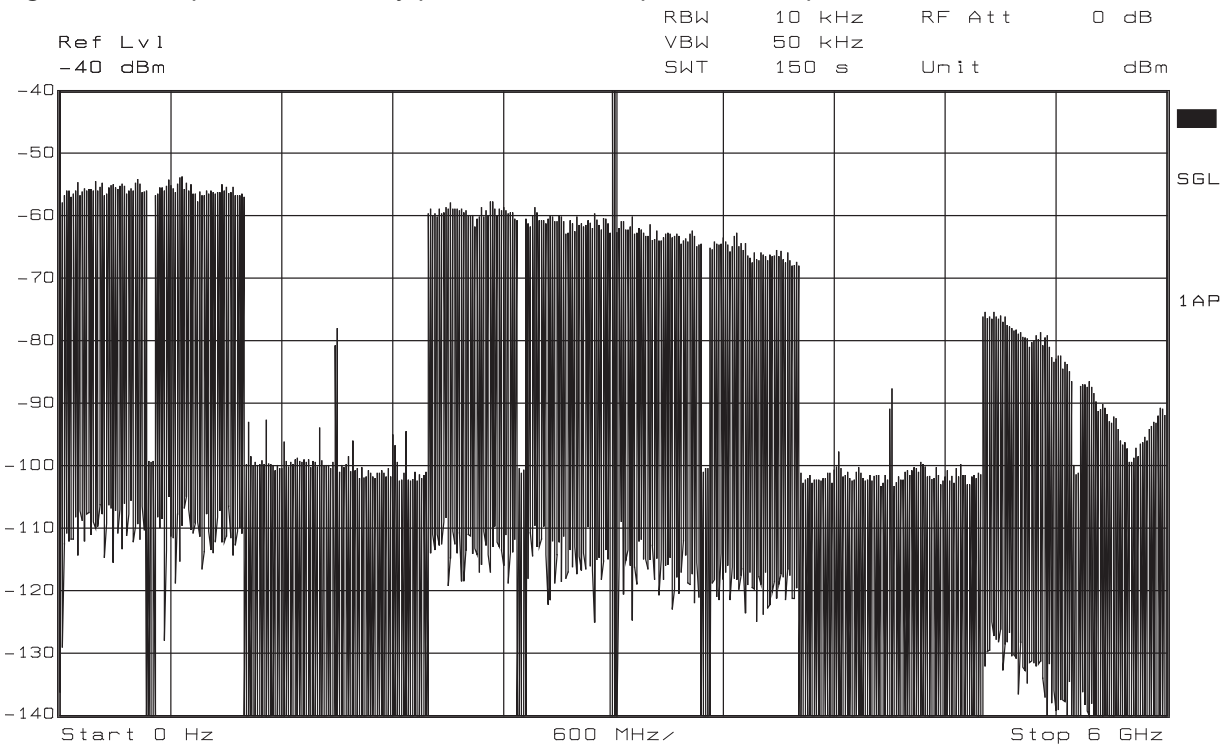


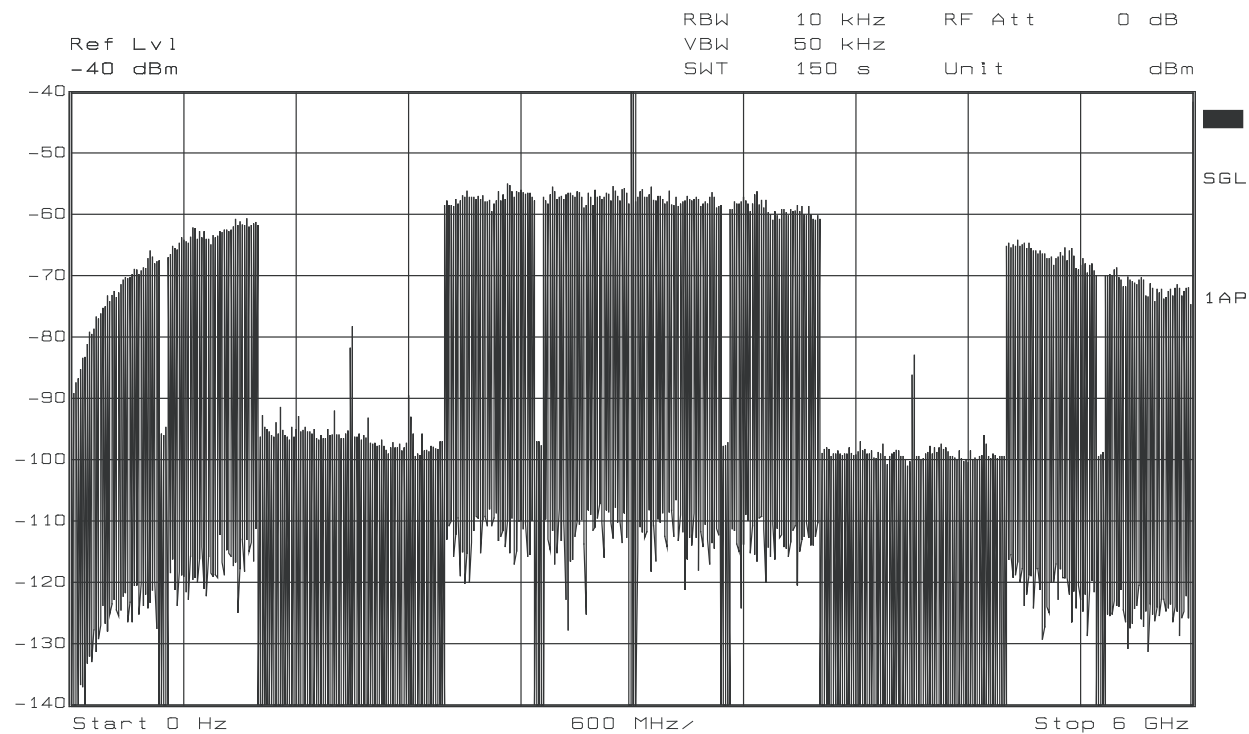
Figure 7-53. Spectrum over 4 Nyquist Zones at 3 Gps in RTZ Output Mode



First Zero of the sinc() function is slightly before  $2 \cdot F_{\text{clock}}$  which indicates that the duty cycle of RTZ function is a little bit more than 50%, this is due to the balun which introduced some phase error beyond the 180 degrees between CLK and CLKN thus creating a duty cycle on the clock actually seen by the DAC.

EV12DS130AZP  
EV12DS130BZP

Figure 7-54. Spectrum over 4 Nyquist Zones at 3 Gsps in RF Output Mode



Measurements are showing a pretty good fit with theory, see [Section 5.3 on page 17](#).



## 8. Application Information

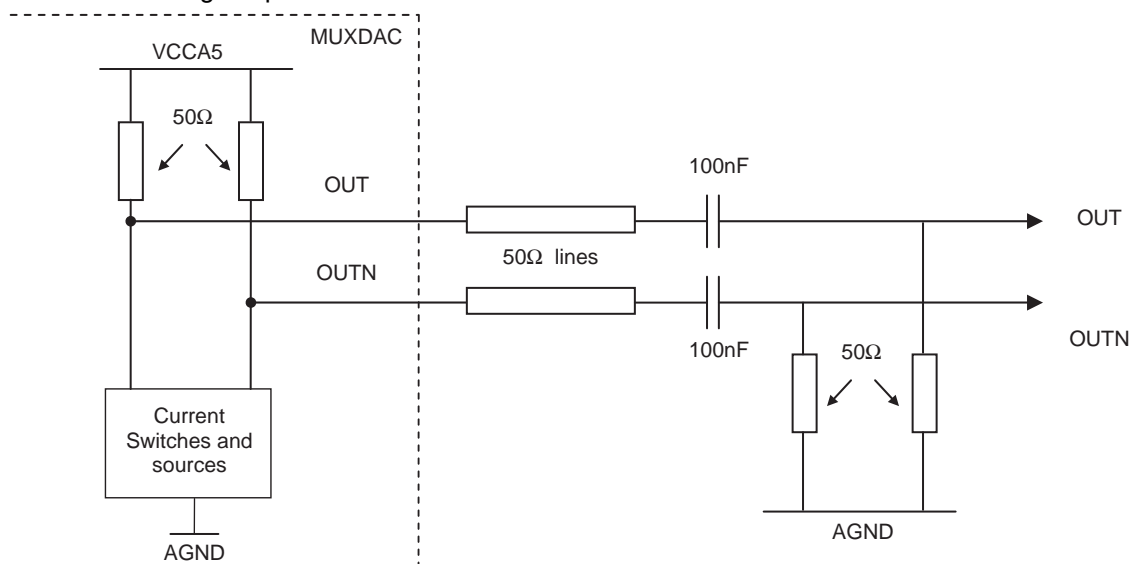
For further details, please refer to application note 1087.

### 8.1 Analog Output (OUT/OUTN)

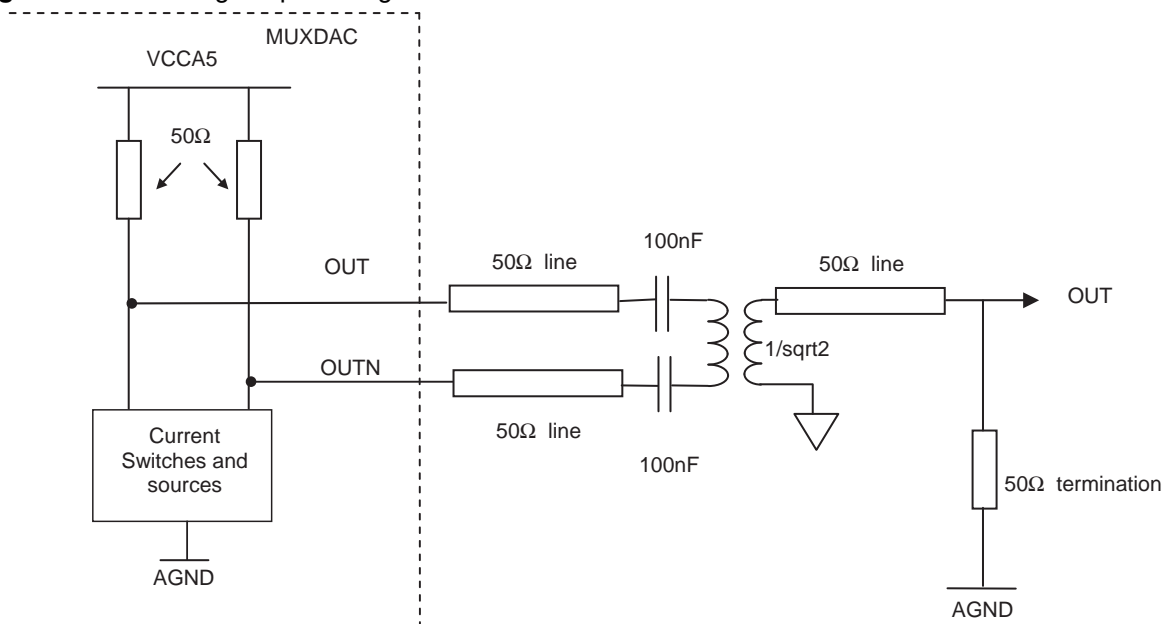
The analog output should be used in differential way as described in the figures below.

If the application requires a single-ended analog output, then a balun is necessary to generate a single-ended signal from the differential output of the DAC.

**Figure 8-1.** Analog Output Differential Termination



**Figure 8-2.** Analog Output Using a 1/√2 Balun

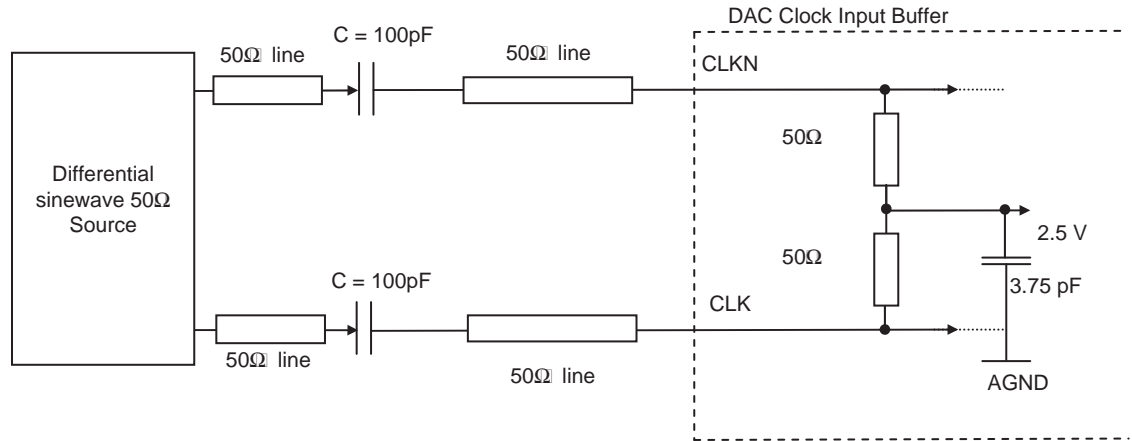


**Note:** The AC coupling capacitors should be chosen as broadband capacitors with a value depending on the application.

## 8.2 Clock Input (CLK/CLKN)

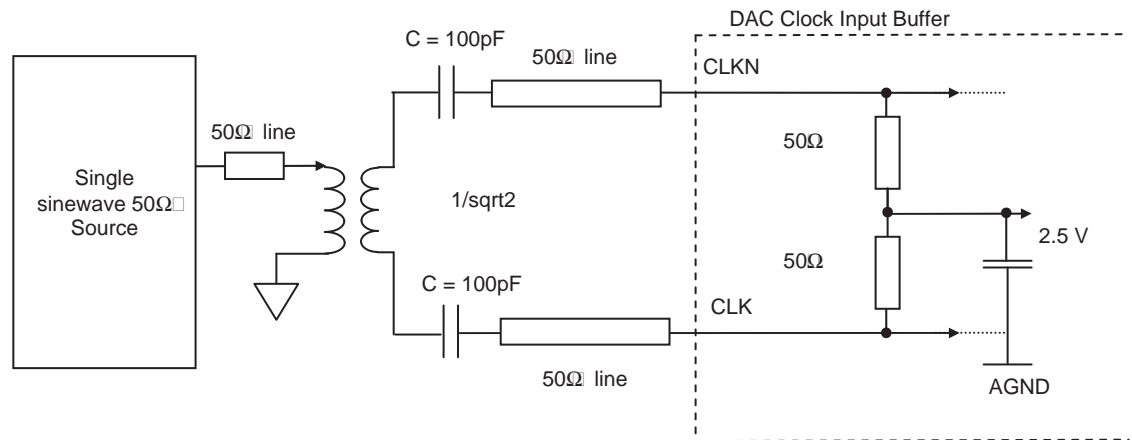
The DAC input clock (sampling clock) should be entered in differential mode as described in [Figure 5-9](#).

**Figure 8-3.** Clock Input Differential Termination



Note: The buffer is internally pre-polarized to 2.5V (buffer between  $V_{CC5}$  and AGND).

**Figure 8-4.** Clock Input Differential with Balun

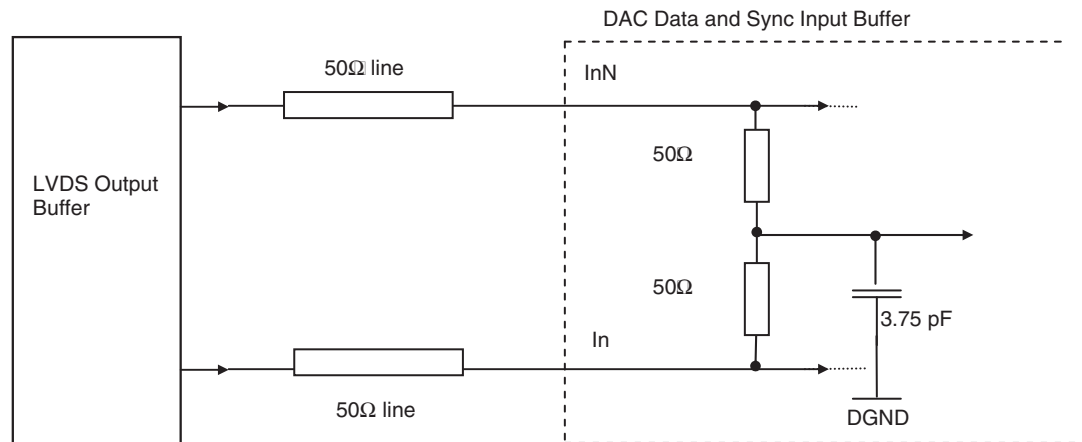


Note: The AC coupling capacitors should be chosen as broadband capacitors with a value depending on the application.

### 8.3 Digital Data, SYNC and IDC Inputs

LVDS buffers are used for the digital input data, the reset signal (active high) and IDC signal. They are all internally terminated by  $2 \times 50\Omega$  to ground via a 3.75 pF capacitor.

**Figure 8-5.** Digital Data, Reset and IDC Input Differential Termination



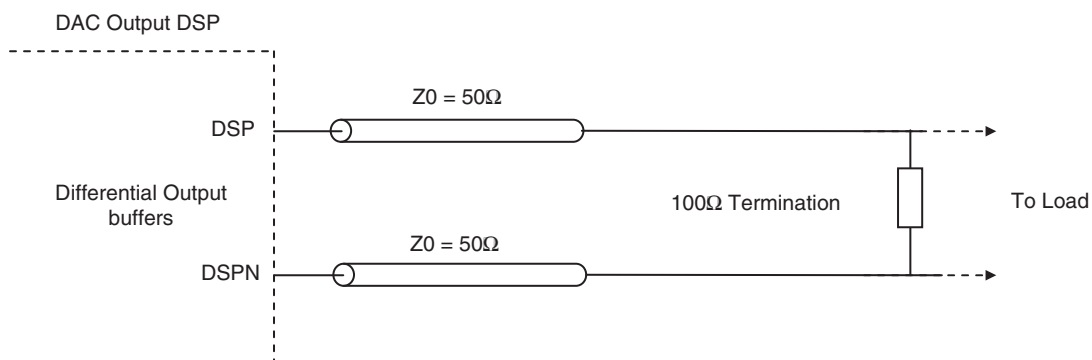
- Notes:
1. In the case when only two ports are used (2:1 MUX ratio), then the unused data should be left open (no connect).
  2. Data and IDC signals should be routed on board with the same layout rules and the same length than the data.
  3. In case SYNC is not used, it is necessary to bias the SYNC to 1.1V and SYNCN to 1.4V on EV12DS130A.

### 8.4 DSP Clock

The DSP, DSPN output clock signals are LVDS compatible.

They have to be terminated via a differential 100Ω termination as described in [Figure 5-11](#).

**Figure 8-6.** DSP Output Differential Termination



# EV12DS130AZP

# EV12DS130BZP

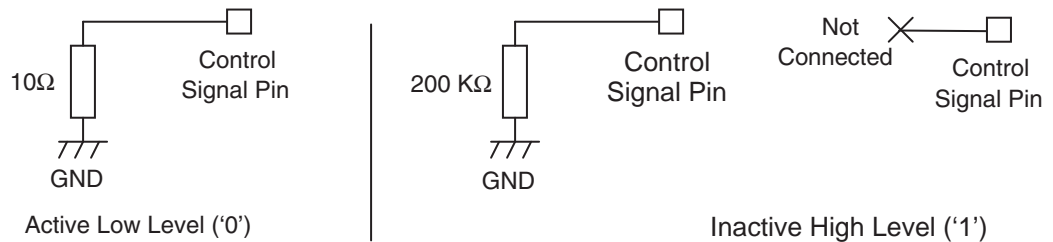
## 8.5 Control Signal Settings

The MUX, MODE, PSS and OCDS control signals use the same static input buffer.

Logic "1" = 200 K $\Omega$  to Ground, or tied to  $V_{CCD} = 3.3V$  or left open

Logic "0" = 10 $\Omega$  to Ground or Grounded

**Figure 8-7.** Control Signal Settings



The control signal can be driven by FPGA.

**Figure 8-8.** Control Signal Settings with FPGA



Logic "1" >  $V_{IH}$  or  $V_{CCD} = 3.3V$

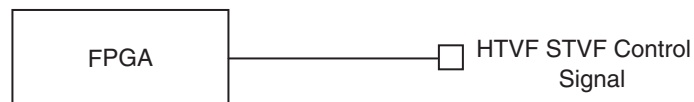
Logic "0" <  $V_{IL}$  or 0V

## 8.6 HTVF and STVF Control Signal

The HTVF and STVF control signals is a 3.3V CMOS output buffer.

These signals could be acquired by FPGA.

**Figure 8-9.** Control Signal Settings with FPGA



In order to modify the  $V_{OL}/V_{OH}$  value, pull up and pull down resistances could be used, or a potential divider.

## 8.7 GA Function Signal

This function allows adjustment of the internal gain of the DAC.

The gain of the DAC can be tuned with applied analog voltage from 0 to  $V_{CCA3}$

This analog input signal could be generated by a DAC controlled by FPGA or microcontroller.

**Figure 8-10.** Control Signal Settings with GA



## 8.8 Power Supplies Decoupling and Bypassing

The DAC requires 3 distinct power supplies:

$V_{CCA5} = 5.0V$  (for the analog core)

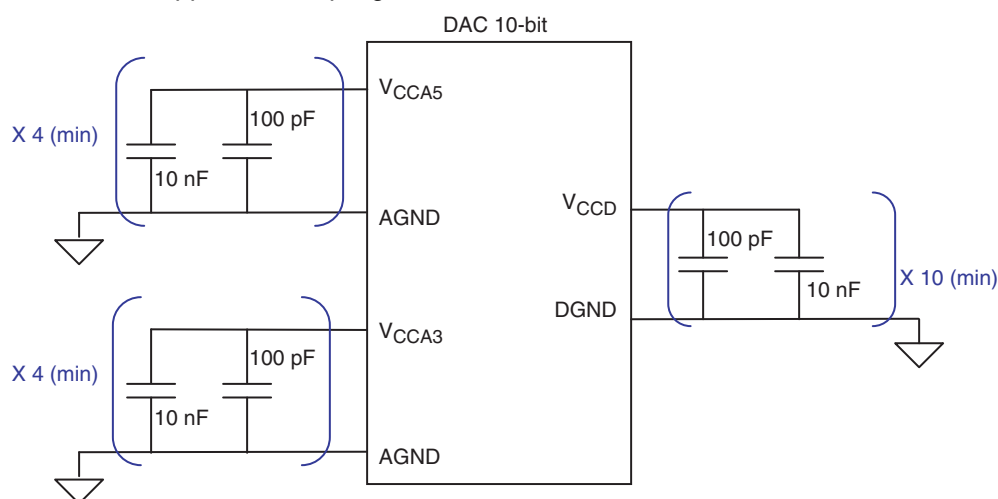
$V_{CCA3} = 3.3V$  (for the analog part)

$V_{CCD} = 3.3V$  (for the digital part)

It is recommended to decouple all power supplies to ground as close as possible to the device balls with 100 pF in parallel to 10nF capacitors. The minimum number of decoupling pairs of capacitors can be calculated as the minimum number of groups of neighboring pins.

4 pairs of 100pF in parallel to 10 nF capacitors are required for the decoupling of  $V_{CCA5}$ . 4 pairs for the  $V_{CCA3}$  is the minimum required and finally, 10 pairs are necessary for  $V_{CCD}$ .

**Figure 8-11.** Power Supplies Decoupling Scheme



Each power supply has to be bypassed as close as possible to its source or access by 100 nF in parallel to 22  $\mu F$  capacitors (value depending of DC/DC regulators).

Analog and digital ground plane should be merged.

### 8.9 Power Up Sequencing

For EV12DS130B there is no forbidden power-up sequence, nor power supplies dependency requirement.

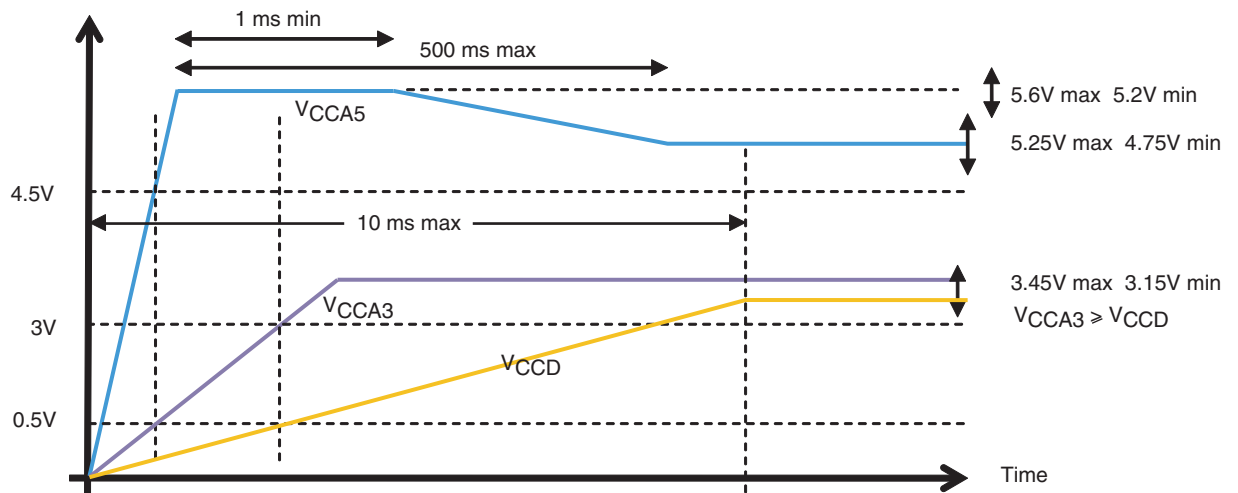
For EV12DS130A the following instructions must be implemented:

Power-up sequence:

It is necessary to raise  $V_{CCA5}$  power supply within the range 5.20V up to a recommended maximum of 5.60V during at least 1ms at power up. Then the supply voltage has to settle within 500 ms to a steady nominal supply voltage within a range of 4.75V up to 5.25V.

A power-up sequence on  $V_{CCA5}$  that does not comply with the above recommendation will not compromise the functional operation of the device. Only the noise floor will be affected.

**Figure 8-12.** Power-up Sequence



The rise time for any of the power supplies ( $V_{CCA5}$ ,  $V_{CCA3}$  and  $V_{CCD}$ ) shall be  $\leq 10$  ms.

At power-up a SYNC pulse is internally and automatically generated when the following sequence is satisfied:  $V_{CCD}$ ,  $V_{CCA3}$  and  $V_{CCA5}$ . To cancel the SYNC pulse at power-up, it is necessary to apply the sequence:  $V_{CCA5}$ ,  $V_{CCA3}$ ,  $V_{CCD}$ . ( $V_{CCA3}$  can not reach 0.5V until  $V_{CCA5}$  is greater than 4.5V.  $V_{CCD}$  can not reach 0.5V until  $V_{CCA3}$  is greater than 3.0V). Any other sequence may not have a deterministic SYNC behaviour. See erratasheet (ref 1125) for specific condition of use relative to the SYNC operation.

Relationship between power supplies:

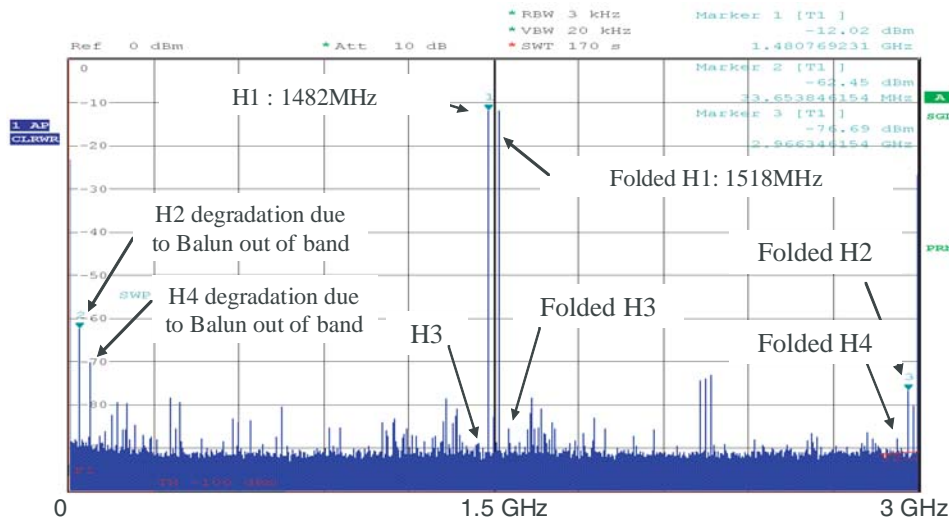
Within the applicable power supplies range, the following relationship shall always be satisfied  $V_{CCA3} \geq V_{CCD}$ , taking into account AGND and DGND planes are merged and power supplies accuracy.

## 8.10 Balun Influence

It is important to know that balun characteristic may influence significantly DAC output spectral response. Especially harmonic distortion can dramatically be degraded when part of the band of interest lies out of the specified domain of the balun.

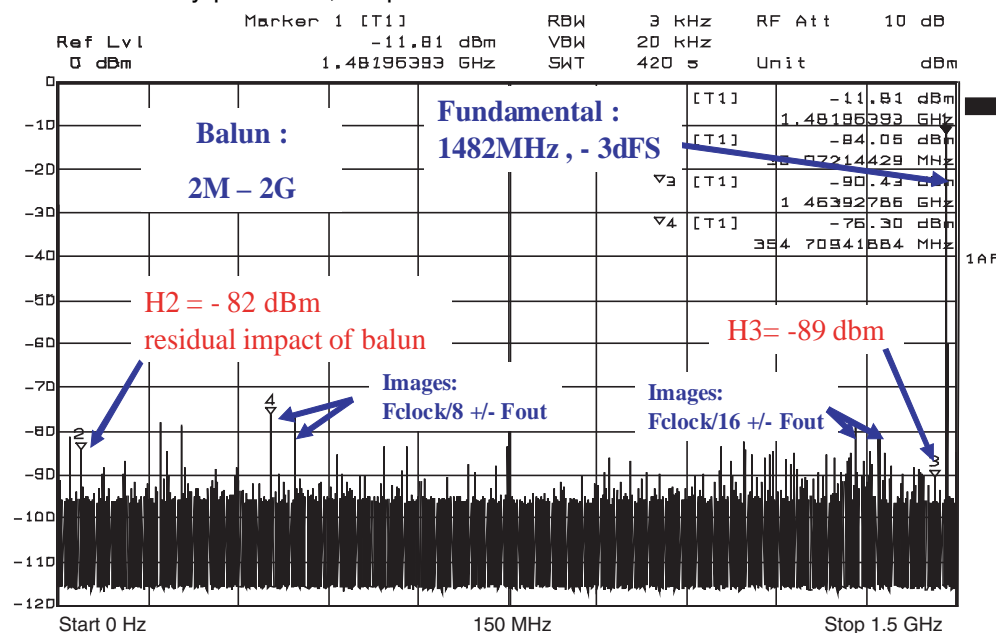
As depicted in the following figure an inappropriate balun choice can result in a strong increase in harmonic peaks amplitude, thus degrading performances. The balun used in this measurement covers only the 500MHz to 7GHz band so that the DC to 500MHz region of the first nyquist zone is distorted.

**Figure 8-13.** Observation of the 1<sup>st</sup> and 2<sup>nd</sup> nyquist zones in output mode RTZ with 0.5 GHz-7 GHz Balun



On the opposite, when appropriate balun is used the real device response is measured

**Figure 8-14.** Spectrum of the 1<sup>st</sup> Nyquist Zone, Output Mode RTZ with a 2 MHz to 2GHz Bandwidth Balun

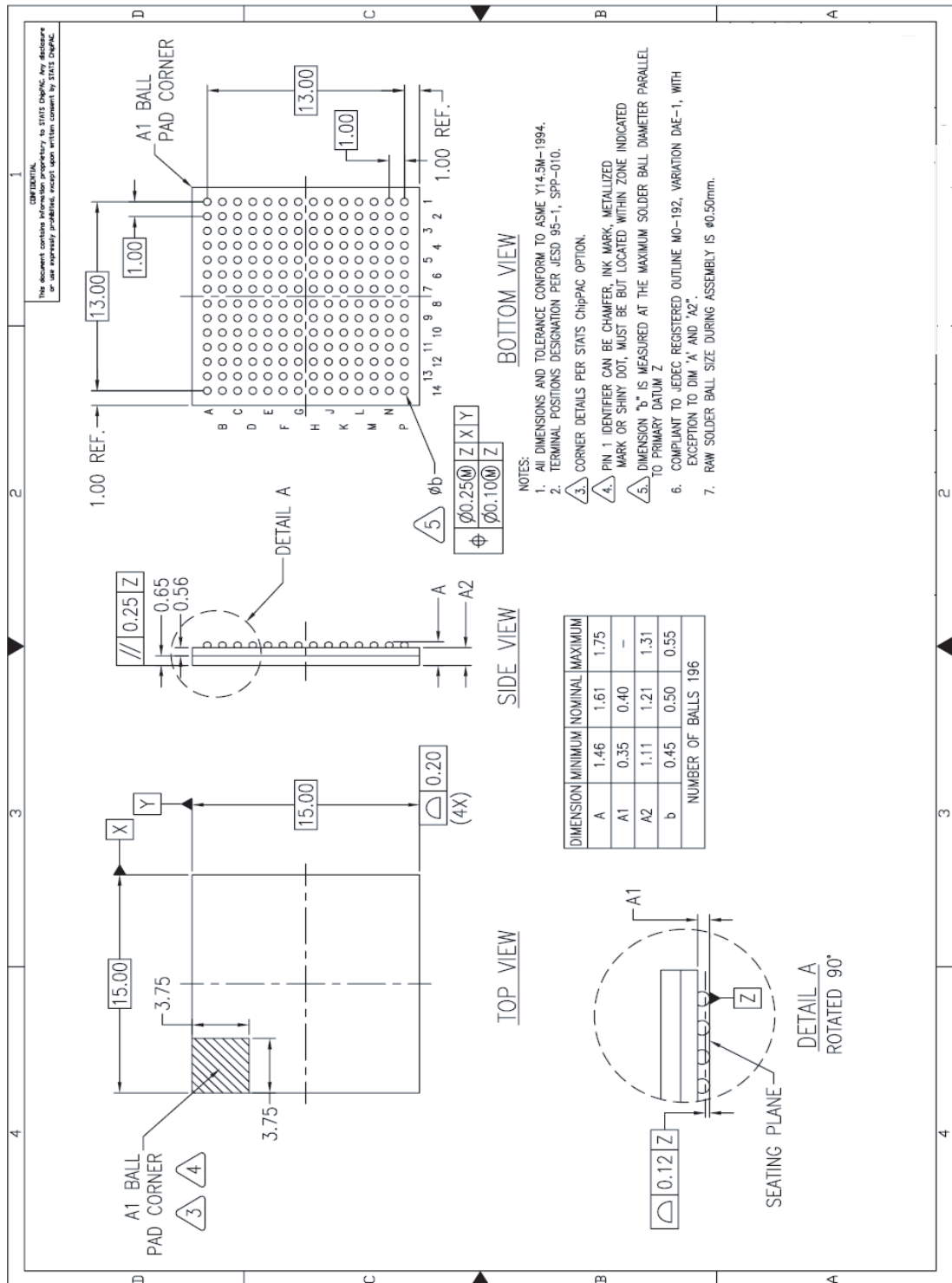


As a consequence, one must be aware that optimum performances can only be reached when using a balun optimal for the band of interest of the application. We specifically recommend selecting a balun which frequency domain covers the whole band of interest (for instance one whole Nyquist zone).

**EV12DS130AZP**  
**EV12DS130BZP**

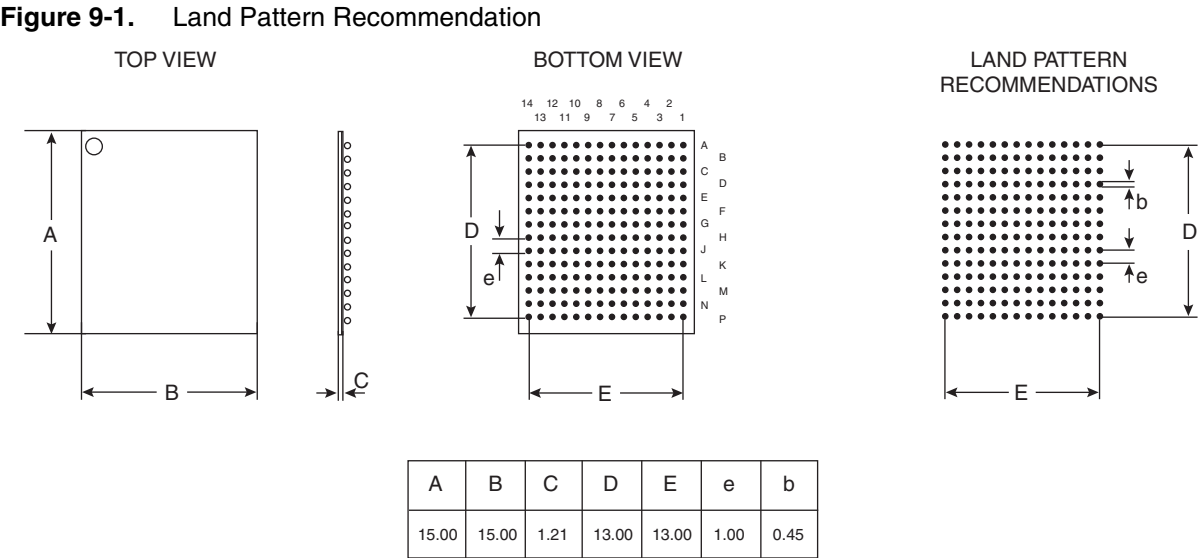
## 9. Package Information

## 9.1 fpBGA 196 Outline





9.2 Land Pattern Recommendation



10. Thermal Characteristics fpBGA196

10.1 Thermal Resistance

Assumptions:

- Still air
- Pure conduction
- No radiation
- Heating zone = 5% of die surface
- Rth Junction – bottom of Balls = 13.3°C/W
- Rth Junction – board (JEDEC JESD-51-8) = 17.8°C/W
- Rth Junction – top of case = 14.5°C/W

Assumptions:

- Heating zone = 5% of die surface
- Still air, JEDEC condition
- Rth Junction – ambient (JEDEC) = 32°C/W

11. Differences between EV12DS130A and EV12DS130B

EV12DS130A and EV12DS130B exhibit the same dynamic performances.

EV12DS130B requires no specific dependency between power supplies nor power up sequences while the EV12DS130A does require specific power up sequences as described in [Section 8.9 on page 70](#).

Maximum supported sampling frequency with DSP clock feature for EV12DS130B is 2.1GHz due to internal jitter. It is however possible to benefit from the EV12DS130B DAC performances up to 3GHz if specific system architecture is implemented. Please refer to application AN1141 for further information.

No SYNC timing constraints (other than T1 T2) are required on EV12DS130B.

# EV12DS130AZP

# EV12DS130BZP

As a summary

When using EV12DS130A, please ensure your system fulfills those specific recommendations

- Power Up Sequence (See [Section 8.9 on page 70](#))
- Power supplies dependency (see [Section 8.9 on page 70](#))
- SYNC pin have to be driven in any case
- Please refer to errata sheet 1125

When using EV12DS130B, please ensure your system fulfills those specific recommendations

- In case sampling frequency is above 2.1 Gsps, please read the AN1141 "Using EV1xDS130B at sampling rate higher than 2.1GSps"

Please refer to application note AN1140 "Replacing EV1xDS130A with EV1xDS130B" for further details

## 12. Ordering Information

Please refer to datasheet details and application notes before ordering.

**Table 12-1.** Ordering Information

Part Number	Package	Lead Finish	Temperature Range	Screening Level	Comments
<b>EV12DS130A</b>					
EVX12DS130AZPY	fpBGA196 RoHS	SAC 305	Ambient	Prototype	
EV12DS130ACZPY	fpBGA196 RoHS	SAC 305	0°C < Tc, Tj < 90°C	Commercial « C » Grade	
EV12DS130AVZPY	fpBGA196 RoHS	SAC 305	–40°C < Tc, Tj < 110°C	Industrial « V » Grade	
EV12DS130AZPY-EB	fpBGA196 RoHS	NA	Ambient	Prototype	Evaluation board
EVX12DS130AZP	fpBGA196	SnPb 63/37	Ambient	Prototype	Contact sales for availability
EV12DS130AVZP	fpBGA196	SnPb 63/37	–40°C < Tc, Tj < 110°C	Industrial « V » Grade	Contact sales for availability
<b>EV12DS130B</b>					
EVX12DS130BZPY	fpBGA196 RoHS	SAC 305	Ambient	Prototype	
EV12DS130BCZPY	fpBGA196 RoHS	SAC 305	0°C < Tc, Tj < 90°C	Commercial « C » Grade	
EV12DS130BVZPY	fpBGA196 RoHS	SAC 305	–40°C < Tc, Tj < 110°C	Industrial « V » Grade	
EV12DS130BZPY-EB	fpBGA196 RoHS	NA	Ambient	Prototype	Evaluation board
EV12DS130BVZP	fpBGA196	SnPb 63/37	–40°C < Tc, Tj < 110°C	Industrial « V » Grade	Contact sales for availability

## 13. Revision History

This table provides revision history for this document.

**Table 13-1.** Revision History

Rev. No	Date	Substantive Change(s)
1077H	December 2014	Table 6-1 on page 28: $V_{CCD}$ pin F10 added Section 5.5 on page 24: OCDS [10] not allowed
1077G	November 2014	Figure 1-1 on page 2: Typo error
1077F	October 2014	Introduction and description of EV12DS130B New Section 11. "Differences between EV12DS130A and EV12DS130B" on page 73 Table 3-9, "Coding Table (Theoretical values)," on page 14: typo error on lines (RTZ) and (NRTZ) Section 5.1 "DSP Output Clock" on page 17 updated Section 5.3 "MODE Function" on page 17: equations updated Section 5.4 "PSS (Phase Shift Select Function)" on page 22 updated Section 5.8 "Synchronization functions for multi-DAC operation" on page 26 updated Figure 7-5 on page 38 updated Figure 7-13 on page 41 updated New Section 7.2.3 "Single tone measurements: typical spectra at 3Gsps" on page 45 New Section 8.10 "Balun Influence" on page 71 Table 12-1, "Ordering Information," on page 74 added column Lead Finish and added part number EV12DS130AVZP and all EV12DS130B part numbers
1077E	December 2013	Table 3-3, "Electrical Characteristics," on page 5: typo error on note 7: $V_{CCA3} \geq V_{CCD}$
1077D	December 2013	Table 3-2, "Recommended Conditions of Use," on page 4: typo error on note 2: $V_{CCA3} \geq V_{CCD}$
1077C	November 2013	Typo errors corrections OCDS restrictions to OCDS1 & 2 HTVF STVF flag application clarifications Power sequencing modification, relative to SYNC operation
1077B	July 2012	Typo errors corrections Absolute max rating clarifications Addition of pin equivalent schematic description Power up sequencing recommendation
1077A	February 2012	Initial revision

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